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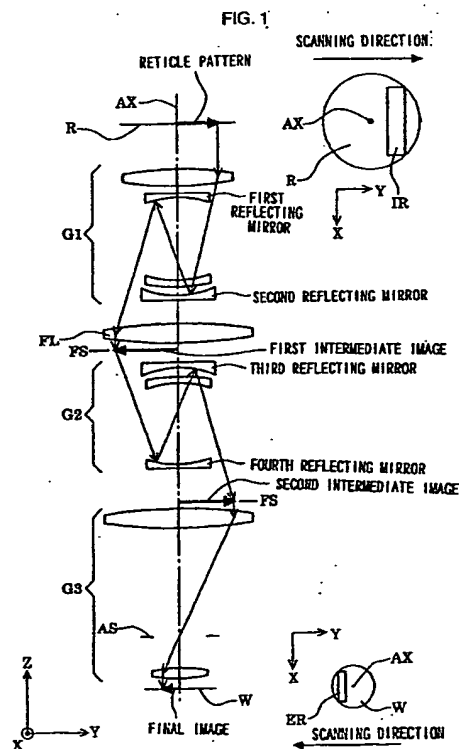
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(54) **CATADIOPTRIC SYSTEM AND EXPOSURE DEVICE HAVING THIS SYSTEM**

(57) A catadioptric system includes: a first image forming optical system that includes at least two reflecting mirrors and forms a first intermediate image of a first plane with light originating from the first plane; a second image forming optical system that includes at least two reflecting mirrors and forms a second intermediate image of the first plane with light having traveled via the first image forming optical system; and a refractive type of third image forming optical system that forms a final image of the first plane onto a second plane with light having traveled via the second image forming optical system, and optical members constituting the first image forming optical system, the second image forming optical system and the third image forming optical system are all disposed along a single linear optical axis.



Description

[0001] The disclosures of the following priority applications are herein incorporated by reference: Japanese Patent Application No. 2000-322068 filed October 23, 2000; Japanese Patent Application No. 2001-003200 filed January 11, 2001; and Japanese Patent Application No. 2001-309516 filed October 5, 2001.

TECHNICAL FIELD

[0002] The present invention relates to a catadioptric system and an exposure apparatus having this catadioptric system and, more specifically, it relates to a high resolution catadioptric type projection optical system ideal in an application in an exposure apparatus which is employed when manufacturing semiconductor elements or the like through a photolithography process.

BACKGROUND ART

[0003] As further miniaturization is pursued with increasing vigor in the field of semiconductor production and semiconductor chip substrate production today, the projection optical system in an exposure apparatus that prints patterns needs to achieve higher resolution. The wavelength of the exposure light must be reduced and the NA (numerical aperture at the projection optical system) must be increased to raise the resolution. However, since light absorption becomes a factor that needs to be taken into consideration, only limited types of optical glass can be utilized in practical application in conjunction with exposure light with small wavelengths. For instance, if the wavelength is 180nm or less, only fluor can be utilized as glass material in practical application.

[0004] In such a situation, if the projection optical system is constituted by using refractive optical members (lenses, plane parallel plates, etc.) alone, it is impossible to correct any chromatic aberration with the refractive projection optical system. In other words, it is extremely difficult to constitute a projection optical system achieving the required resolution with refractive optical members alone. In response, attempts have been made to constitute a projection optical system with reflective optical members, i.e., reflecting mirrors, alone.

[0005] However, the reflective projection optical system achieved by using reflective optical members alone is bound to become large. In addition, aspherical reflecting surfaces must be formed. It is to be noted that it is extremely difficult to form a high precision aspherical reflecting surface in the actual manufacturing process. Accordingly, various so-called catadioptric reducing optical systems achieved by using refractive optical members constituted of both optical glass that can be used in conjunction with exposure light with small wavelengths and reflecting mirrors, have been proposed.

[0006] Among these catadioptric systems, there is a type of catadioptric system that forms an intermediate image only once by using a single concave reflecting mirror. In such a catadioptric system, the optical system portion for reciprocal paths, of which the concave reflecting mirror is a component, only includes negative lenses and does not have any refractive optical member with positive power. As a result, light enters the concave reflecting mirror as a wide light flux, which requires that the concave reflecting mirror have a large diameter.

[0007] In particular, when the optical system portion for reciprocal paths having the concave reflecting mirror adopts a completely symmetrical configuration, the onus of the aberration correction imposed on the refractive optical system portion at the succeeding stage is reduced by minimizing the occurrence of aberration at the optical system portion for reciprocal paths. However, a sufficient working distance cannot be readily assured in the vicinity of the first plane in the symmetrical optical system for reciprocal paths. In addition, a half prism must be used to branch the optical path.

[0008] Furthermore, if a concave reflecting mirror is used at a secondary image forming optical system provided to the rear of the position at which the intermediate image is formed, the light needs to enter the concave reflecting mirror as a wide light flux in order to assure the degree of brightness required by the optical system. As a result, it is difficult to miniaturize the concave reflecting mirror whose diameter tends to be necessarily large.

[0009] There is also a type of catadioptric system that forms an intermediate image only once by using a plurality of reflecting mirrors. In this type of catadioptric optical system, the number of lenses required to constitute the refractive optical system portion can be reduced. However, the following problems must be addressed with regard to such catadioptric systems.

[0010] In the catadioptric system having the optical system portion for reciprocal paths adopting the structure described above provided toward the second plane on the reduction side, other restrictions imposed with regard to the reduction factor make it impossible to assure a sufficiently long distance to the second plane (the wafer surface) over which the light travels after it is reflected at the reflecting mirror. For this reason, a large number of lenses cannot be inserted in this optical path and the level of brightness achieved at the optical system is bound to be limited. In addition, even if an optical system with a large numerical aperture is achieved, numerous refractive optical members must be provided in the optical path with a limited length, and thus, it is not possible to assure a sufficiently long distance

between the wafer surface at the second plane and the surface of the lens toward the second plane, i.e., the so-called working distance WD cannot be set to a sufficiently long value.

[0011] Since the optical path has to be bent, the catadioptric system in the related art is bound to have a plurality of optical axes (an optical axis is a line extending through the center of the curvature of a refractive curved surface or a reflective curved surface constituting an optical system). As a result, a plurality of lens barrels must be included in the optical system configuration, which makes it extremely difficult to adjust the individual optical axes relative to one another and, ultimately, to achieve a high precision optical system. It is to be noted that a catadioptric system having all the optical members provided along a single linear optical axis may be achieved by using a pair of reflecting mirrors each having an opening (a light transmission portion) at the center. However, in this type of catadioptric system, the central light flux must be blocked, i.e., central shielding must be achieved, in order to block off unnecessary light which advances along the optical axis without being reflected at the reflecting mirrors. As a result, a problem arises in that the contrast becomes lowered in a specific frequency pattern due to the central shielding.

[0012] In addition, positions at which an effective field stop and an effective aperture stop should be installed can not be assured in the catadioptric systems in the related art. Also, as explained above, a sufficient working distance cannot be assured in the catadioptric systems in the related art. Furthermore concave reflecting mirrors tend to become large in the catadioptric systems in the related art, as described above, making it impossible to miniaturize the optical systems.

[0013] While the catadioptric system disclosed in EP1069448A1 achieves advantages in that a sufficient working distance is assured toward the second plane (on the wafer-side) and in that the system is configured along a single optical axis, it still has a problem in that a sufficiently long working distance cannot be assured toward the first plane (on the mask side) (the distance between the mask surface at the first plane and the surface of the lens closest to the first plane). In addition, the catadioptric system disclosed in WO 01/51979A2 poses a problem in that the diameter of the reflecting mirror is too large and thus, a sufficiently large numerical aperture cannot be achieved. Likewise, the diameter of the reflecting mirror is too large and, as a result, a sufficiently large numerical aperture cannot be achieved in the catadioptric system disclosed in Japanese Laid-open Patent Publication No. 2001-228401.

DISCLOSURE OF THE INVENTION

[0014] An object of the present invention, which has been achieved by addressing the problems discussed above, is to provide a catadioptric system that facilitates adjustment and high precision production of the optical system and is capable of achieving a high resolution of 0.1 μ m or less by using light in a vacuum ultraviolet wavelength range of, for instance, 180nm or smaller.

[0015] Another object of the present invention is to provide a catadioptric system that assures positions at which an effective field stop and an effective aperture stop should be installed and is capable of achieving a high resolution of 0.1 μ m or less by using light in a vacuum ultraviolet wavelength range of, for instance, 180nm or smaller.

[0016] Yet another object of the present invention is to provide a catadioptric system that assures a sufficiently long working distance and is capable of achieving a high resolution of 0.1 μ m or less by using light in a vacuum ultraviolet wavelength range of, for instance, 180nm or smaller.

[0017] A further object of the present invention is to provide a catadioptric system that achieves miniaturization of the optical system by keeping down the size of concave reflecting mirrors and is also capable of achieving a high resolution of 0.1 μ m or less by using light in a vacuum ultraviolet wavelength range of, for instance, 180nm or smaller.

[0018] A still further object of the present invention is to provide a catadioptric system that assures a sufficiently long working distance on the first plane side, achieves a satisfactorily large numerical aperture by keeping down the diameter of reflecting mirrors and is capable of achieving a high resolution of 0.1 μ m or less by using light in a vacuum ultraviolet wavelength range of, for instance, 180nm or smaller.

[0019] A still further object of the present invention is to provide an exposure apparatus that utilizes the catadioptric system according to the present invention as a projection optical system and is capable of achieving good projection exposure with a high resolution of 0.1 μ m or less by using exposure light with a wavelength of, for instance, 180nm or smaller.

[0020] A still further project of the present invention is to provide a micro device manufacturing method through which a high precision micro device can be manufactured by executing good projection exposure with a high resolution of, for instance, 0.1 μ m or less with the exposure apparatus according to the present invention.

[0021] In order to attain the above objects, a catadioptric system according to the present invention comprises: a first image forming optical system that includes at least two reflecting mirrors and forms a first intermediate image of a first plane with light originating from the first plane; a second image forming optical system that includes at least two reflecting mirrors and forms a second intermediate image of the first plane with light having traveled via the first image forming optical system; and a refractive type of third image forming optical system that forms a final image of the first plane onto a second plane with light having traveled via the second image forming optical system, and optical members

constituting the first image forming optical system, the second image forming optical system and the third image forming optical system are all disposed along a single linear optical axis.

[0022] In this catadioptric system, it is preferred that a field lens is provided in an optical path between the first image forming optical system and the second image forming optical system.

5 [0023] Also, it is preferred that the first image forming optical system includes the two reflecting mirrors and at least one lens element.

[0024] In these cases, it is preferred that a combined optical system comprising the first image forming optical system and the field lens achieves telecentricity toward the first plane and toward the second plane.

10 [0025] In each of the above catadioptric systems, it is preferred that the first image forming optical system includes at least one negative lens element provided in an optical path between the two reflecting mirrors.

[0026] Also, it is preferred that the second image forming optical system includes at least one negative lens element provided in an optical path between the two reflecting mirrors.

15 [0027] Another catadioptric system according to the present invention comprises a plurality of optical members that form two intermediate images of a first plane in an optical path between the first plane and a second plane and form a third intermediate image of the first plane onto the second plane as a final image, and the plurality of optical members are disposed along a single linear optical axis.

[0028] In this catadioptric system, it is preferred that the intermediate images are formed at positions off the optical axis.

20 [0029] Another catadioptric system according to the present invention comprises a plurality of reflecting mirrors disposed along a single linear optical axis, and an image over a rectangular area away from the optical axis on a first plane is formed onto a second plane.

[0030] In this catadioptric system, it is preferred that a field stop that defines an image area formed at the catadioptric system and an aperture stop that defines a numerical aperture of the catadioptric system, are further provided.

25 [0031] Another catadioptric system according to the present invention comprises: a first image forming optical system that includes at least a first reflecting mirror and a second reflecting mirror and forms a first intermediate image of a first plane with light originating from the first plane; a second image forming optical system that includes at least a third reflecting mirror and a fourth reflecting mirror and forms a second intermediate image of the first plane with light having traveled via the first image forming optical system; and a refractive type of third image forming optical system that forms a final image of the first plane onto a second plane with light having traveled via the second image forming optical system, and: optical members constituting the first image forming optical system, the second image forming optical system and the third image forming optical system are all disposed along a single linear optical axis; and at least one negative lens is provided immediately before each of two reflecting mirrors among the first reflecting mirror, the second reflecting mirror, the third reflecting mirror and the fourth reflecting mirrors on a reflecting surface side.

30 [0032] In this catadioptric system, it is preferred that: a magnification factor chromatic aberration is corrected by providing at least one negative lens immediately before each of the two reflecting mirrors on the reflecting surface side; and a magnification factor chromatic aberration coefficient LAT satisfies a condition expressed as $ILATl < 5 \times 10^{-6}$. In this case or in the above catadioptric system, it is preferred that: an on-axis chromatic aberration is corrected by providing at least one negative lens immediately before each of the two reflecting mirrors on the reflecting surface side; and an on-axis chromatic aberration coefficient AX satisfies a condition expressed as $IAXl < 2 \times 10^{-4}$.

40 [0033] An exposure apparatus according to the present invention comprises: an illumination system that illuminates a mask; and a projection optical system that forms an image of a pattern formed at the mask onto a photosensitive substrate, and: the projection optical system comprises a catadioptric system according to any one of claims 1 through 13; and the mask corresponds to the first plane in the catadioptric system and the photosensitive substrate corresponds to the second plane in the catadioptric system.

45 [0034] In this exposure apparatus, it is preferred that a drive system that causes the mask and the photosensitive substrate to move relative to the catadioptric system in order to scan the pattern of the mask to expose onto the photosensitive substrate, is further provided.

50 [0035] A micro device manufacturing method according to the present invention comprises: an exposure step in which the pattern of the mask is exposed onto the photosensitive substrate with the above exposure apparatus; and a development step in which the photosensitive substrate having undergone the exposure step is developed.

BRIEF DESCRIPTION OF THE DRAWINGS

[0036]

55 FIG. 1 illustrates the basic structure of a catadioptric system according to the present invention;
FIG. 2 schematically illustrates the overall structure of an exposure apparatus having the catadioptric system achieved in any of the embodiments of the present invention provided as a projection optical system;

FIG. 3 shows positional relationship between the rectangular exposure area (i.e., the effective exposure area) formed on the wafer and the reference optical axis;

FIG. 4 shows the lens configuration of the catadioptric system achieved in a first embodiment;

FIG. 5 shows the lateral aberration manifesting at the catadioptric system in the first embodiment;

5 FIG. 6 shows the lens configuration of the catadioptric system achieved in a second embodiment;

FIG. 7 shows the lateral aberration manifesting at the catadioptric system in the second embodiment;

FIG. 8 shows the lens configuration of the catadioptric system achieved in a third embodiment;

FIG. 9 shows the lateral aberration manifesting at the catadioptric system in the third embodiment;

10 FIG. 10 shows the lens configuration of the catadioptric system achieved in a fourth embodiment;

FIG. 11 shows the lateral aberration manifesting at the catadioptric system in the fourth embodiment;

FIG. 12 shows the lens configuration of the catadioptric system achieved in a fifth embodiment;

FIG. 13 shows the lateral aberration manifesting at the catadioptric system in the fifth embodiment;

FIG. 14 shows the lens configuration of the catadioptric system achieved in a sixth embodiment;

15 FIG. 15 shows that positional relationship between the arch-shaped effective exposure area formed on the wafer and the reference optical axis in the sixth embodiment;

FIG. 16 shows the lateral aberration manifesting at the catadioptric system in the sixth embodiment;

FIG. 17 shows the lens configuration of the catadioptric system achieved in a seventh embodiment;

FIG. 18 shows the lateral aberration manifesting at the catadioptric system in the seventh embodiment;

20 FIG. 19 shows the lateral aberration manifesting at the catadioptric system in the seventh embodiment;

FIG. 20 shows the lens configuration of the catadioptric system achieved in an eighth embodiment;

FIG. 21 shows the lateral aberration manifesting at the catadioptric system in the eighth embodiment;

FIG. 22 shows the lateral aberration manifesting at the catadioptric system in the eighth embodiment;

FIG. 23 shows the lens configuration of the catadioptric system achieved in a ninth embodiment;

25 FIG. 24 shows the lateral aberration manifesting at the catadioptric system in the ninth embodiment;

FIG. 25 shows the lateral aberration manifesting at the catadioptric system in the ninth embodiment;

FIG. 26 presents a flowchart of a method adopted to obtain a micro device constituted of a semiconductor device; and

FIG. 27 presents a flowchart of a method adopted to obtain a micro device constituted of a liquid crystal display element.

BEST MODE FOR CARRYING OUT THE INVENTION

[0037] FIG. 1 illustrates the basic structure adopted in a catadioptric system according to the present invention. It is to be noted that in FIG. 1, the catadioptric system according to the present invention is utilized as a projection optical system in an exposure apparatus that performs scanning exposure. As shown in FIG. 1, the catadioptric system according to the present invention includes a first image forming optical system G1 for forming a first intermediate image of the pattern at a reticle R constituting a projection original which is set at a first plane. It is to be noted that the first image forming optical system G1 includes at least two reflecting mirrors i.e., a first reflecting mirror and a second reflecting mirror.

40 [0038] Light having traveled through the first image forming optical system G1 then forms a second intermediate image of the pattern at the reticle R via a second image forming optical system G2 having at least two reflecting mirrors, i.e., a third reflecting mirror and a fourth reflecting mirror. The light having traveled through the second image forming optical system G2 forms a final image of the pattern at the reticle R onto a wafer W constituting a photosensitive substrate which is set at a second plane via a refractive third image forming optical system G3 having refractive optical members alone with no reflecting mirror. All the optical members constituting the first image forming optical system G1, the second image forming optical system G2 and the third image forming optical system G3 are disposed along a single linear optical axis AX.

45 [0039] In a more specific mode of the embodiment, a field lens FL is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. The field lens FL has a function of matching and connecting the first image forming optical system G1 and the second image forming optical system G2 without actively contributing to the formation of the first intermediate image. In addition, the first image forming optical system G1 includes at least one lens element as well as the two reflecting mirrors. Thus, the combined optical system constituted of the first image forming optical system G1 and the field lens FL achieves telecentricity toward the reticle (toward the first plane) and toward the wafer (toward the second plane). It is to be noted that a field lens may also be provided as necessary in the optical path between the second image forming optical system G2 and the third image forming optical system G3.

50 [0040] In the specific mode of the embodiment, it is desirable to provide at least one negative lens element (L13 or L21) in the optical path between the two reflecting mirrors at, at least either the first image forming optical system G1

or the second image forming optical system G2. This structure makes it possible to correct any chromatic aberration in a desirable manner even if the refractive optical members (lens elements) are formed with a single type of optical material.

[0041] A field stop FS that defines an area over which the image is formed at the catadioptric system may be provided near the field lens FL between the first image forming optical system G1 and the second image forming optical system G2 or near a field lens set between the second image forming optical system G2 and the third image forming optical system G3. In this case, the need to provide a field stop in the illumination optical system is eliminated. In addition, an aperture stop AS may be provided in the optical path at the third image forming optical system G3.

[0042] As described above, all the optical members are disposed along the single optical axis AX in the catadioptric system according to the present invention, unlike in catadioptric systems in the related art having a plurality of optical axes. Since this allows the optical system to be achieved without a plurality of lens barrels, the adjustment of the optical axes relative to one another becomes unnecessary and any tilting or misalignment of the individual optical members set along the single optical axis AX can be optically detected with ease, which, ultimately makes it possible to manufacture a high precision optical system. In addition, by aligning the single optical axis AX along the direction in which the gravitational force works (along the vertical direction) in this structure, the flexure of any lens caused by gravity can be made to achieve rotational symmetry and, as a result, the deterioration in the image forming performance can be minimized through an optical adjustment.

[0043] In particular, by utilizing the catadioptric system adopted in the projection optical system of the exposure apparatus in an upright attitude along the single optical axis AX, the reticle R and the wafer W can be set parallel to each other along a plane perpendicular to the direction of the gravitational force (i.e., along a horizontal plane) and all the lenses constituting the projection optical system can be set horizontally along the single optical axis AX extending along the direction of the gravitational force. As a result, the reticle R, the wafer W and all the lenses constituting the projection optical system are held level without becoming asymmetrically deformed due to their own weight, which is extremely advantageous in facilitating optical adjustment and mechanical design and in assuring high resolution.

[0044] In addition, the Petzval's sum, which tends to be a positive value due to the positive refracting power of the refractive optical system portion of the third image forming optical system G3, can be canceled out with the negative Petzval's sum at the concave reflecting mirror portion of the first image forming optical system G1 and the second image forming optical system G2 and, as a result, the overall Petzval's sum can be kept at exactly 0.

[0045] It is to be noted that the specific setting of the optical path of the reflecting mirrors is a crucial issue in a structure achieved by providing all the optical members including the reflecting mirrors along a single optical axis. As a solution, an opening (light transmission portion) may be formed at the center of each reflecting mirror as described earlier, to set the optical path via the central opening. However, this prior art solution necessitates the formation of central shielding over the entrance pupil area and such central shielding may lead to poorer optical image forming performance.

[0046] In contrast, the light flux from the reticle pattern travels around the outside of the first reflecting mirror and then enters the second reflecting mirror at the first image forming optical system G1. After the light flux having been reflected at the second reflecting mirror is reflected at the first reflecting mirror, the light flux travels around the outside of the second reflecting mirror and forms the first intermediate image. In addition, the light flux from the first intermediate image travels around the outside of the third reflecting mirror and enters the fourth reflecting mirror at the second image forming optical system G2. After the light flux having been reflected at the fourth reflecting mirror is reflected at the third reflecting mirror, the light flux travels around the outside of the fourth reflecting mirror and forms the second intermediate image. According to the present invention, the first image forming optical system G1 and the second image forming optical system G2 are set substantially symmetrical with respect to each other relative to the position at which the first intermediate image is formed. As a result, a large working distance (the distance between the optical surface closest to the reticle and the reticle along the optical axis) can be assured on the reticle side. In other words, by setting the position of the second intermediate image formed via the second image forming optical system G2 further away from the third reflecting mirror, a larger working distance is assured on the reticle side. According to Schupmann's principal of achromatism, "An achromat of the Schupmann (refer to R. Kingstake, "Lens Design Fundamentals", Academic Press, 1978, page 89)", it is difficult to achieve color correction if the difference between the distances from the negative lens to conjugate images (the reticle R and the intermediate image) ($= a + b - c$, with c representing the distance from the reticle R to the second reflecting mirror, b representing the distance from the second reflecting mirror to the first reflecting mirror and a representing the distance from the first reflecting mirror to the intermediate image in FIG. 1) is large. The present invention, in which the first image forming optical system G1 and the second image forming optical system G2 are set substantially symmetrical to each other relative to the position at which the first intermediate image is formed, allows the difference between the distances from the negative lens at the image forming optical system G1 to the conjugate images manifesting to be canceled out at the second the image forming optical system G2, providing an advantage in the chromatic aberration correction as well.

[0047] By adopting the structure described above, central shielding at the entrance pupil can be eliminated and,

ultimately, the optical image forming characteristics are not lowered because of central shielding. It is to be noted that the optical path can be set so as to run around the outside of the individual reflecting mirrors by selecting an appropriate image forming magnification factor for the entire catadioptric system. As a result, the final image of the reticle pattern formed over a relatively large rectangular illumination area IR, which is decentered from the optical axis AX in the reticle field, can be formed onto a relatively large rectangular effective exposure area ER, which is decentered from the optical axis AX at the wafer field, as shown in FIG. 1. In correspondence, the first intermediate image and the second intermediate image of the reticle pattern are formed at positions away from the optical axis AX.

[0048] The exposure apparatus having the catadioptric system according to the present invention mounted as its projection optical system as described above is capable of performing scanning exposure based upon the rectangular illumination area IR and the rectangular effective exposure area ER by moving the reticle R and the wafer W along a specific direction (scanning direction). In contrast, in an exposure apparatus in the related art having a catadioptric system with all its optical members disposed along a single optical axis mounted as the projection optical system, a relatively large rectangular illumination area and effective exposure area cannot be assured and, as a result, the exposure apparatus performs scanning exposure based upon a thin arch-shaped illumination area and effective exposure area.

[0049] In such an exposure apparatus in the related art having thin arch-shaped effective exposure area, it is difficult to adjust the tilt of the wafer stage so as to contain the effective exposure area within the focal depth of the projection optical system at all times during the scanning exposure operation. In addition, in the exposure apparatus in the related art having the thin arch-shaped effective exposure area, the reticle R and the wafer W need to move over a great distance along the scanning direction, i.e., the scanning width is bound to be large. According to the present invention, in which a relatively large rectangular effective exposure area is achieved, the tilt of the wafer stage can be adjusted with ease so as to contain the effective exposure area within the focal depth of the projection optical system at all times during the scanning exposure and thus, a smaller scanning width is achieved.

(Embodiments)

[0050] The following is an explanation of embodiments of the present invention, given in reference to the attached drawings.

[0051] FIG. 2 schematically illustrates the overall structure of an exposure apparatus having the catadioptric system achieved in any of the embodiments of the present invention as its projection optical system. It is to be noted that in FIG. 2, the Z axis is set parallel to a reference optical axis AX of the catadioptric system constituting a projection optical system PL, the Y axis is set parallel to the drawing sheet of FIG. 2 and the X axis is set perpendicular to the drawing sheet within a plane perpendicular to the optical axis AX.

[0052] The exposure apparatus in the figure includes a light source 100 constituted of an F₂ laser light source (with an oscillation central wavelength of 157.6nm) to supply illuminating light in the ultraviolet range. Light emitted from the light source 100 uniformly illuminates the reticle (mask) R having a specific pattern formed therein via an illumination optical system IL. It is to be noted that the optical path between the light source 100 and the illumination optical system IL is sealed with a casing (not shown), and the atmosphere in the space extending from the light source 100 to the optical member in the illumination optical system IL, which is the closest to the reticle, is replaced with an inert gas such as helium or nitrogen with a low exposure light absorption coefficient, or the space is sustained in a substantially vacuum state.

[0053] The reticle R is held parallel to the X Y plane on a reticle stage RS via a reticle holder RH. A pattern to be transferred is formed at the reticle R, and a rectangular area within the overall pattern, with its long side extending along the X direction and its short side extending along the Y direction is illuminated. The reticle stage RS can be made to move two-dimensionally along the reticle surface (i.e., the X Y plane) by a drive system (not shown), and the position of the reticle stage RS is controlled by measuring its positional coordinates with an interferometer RIF, which utilizes a reticle movement mirror RM.

[0054] Light from the pattern formed at the reticle R forms a reticle pattern image on the wafer W, which is a photo-sensitive substrate, via the catadioptric projection optical system PL. The wafer W is held parallel to the X Y plane on the wafer stage WS via a wafer table (wafer holder) WT. The pattern image is formed over a rectangular exposure area of the wafer W, with its long side extending along the X direction and its short side extending along the Y direction to optically match the rectangular illumination area on the reticle R. The wafer stage WS can be made to move two-dimensionally along the wafer surface (i.e., the X Y plane) by a drive system (not shown) and the position of the wafer stage WS is controlled by measuring its positional coordinates with an interferometer WIF which employs the wafer movement mirror WM.

[0055] FIG. 3 shows the positional relationships between the rectangular exposure area (i.e., the effective exposure area) formed on the wafer and the reference optical axis. As shown in FIG. 3, a rectangular effective exposure area ER in a desired size is set at a position off the reference optical axis AX along the -Y direction within a circular area

(image circle) IF with a radius A (which corresponds to the maximum image height) centered around the reference optical axis AX in all the embodiments except for the sixth embodiment. The effective exposure area ER measures LX along the X direction and measures LY along the Y direction.

[0056] Thus, the rectangular illumination area IR with a size and shape corresponding to those of the effective exposure area ER is formed on the reticle R at a position off the reference optical axis AX along the + Y direction as shown in FIG. 1. Namely, the rectangular illumination area IR with a desired size is set at a position off the reference optical axis AX along the + Y direction within a circular area having a radius B (which corresponds to the maximum object height) centering around the reference optical axis AX.

[0057] In addition, the space inside the projection optical system PL between the optical member set closest to the reticle (the lens L11 in the embodiments) and the optical member set closest to the wafer (the lens L38 in the first and second embodiments, the lens L312 in the third embodiment, the lens L39 in the fourth embodiment, the lens L315 in the fifth, sixth and ninth embodiments and the lens L317 in the seventh and eighth embodiments) among the optical members constituting the projection optical system PL is sustained in an airtight state in the exposure apparatus shown in the figure, with the atmosphere inside the projection optical system PL replaced with an inert gas such as helium gas or nitrogen gas, or sustained in the substantially vacuum state.

[0058] While the reticle R, the reticle stage RS and the like are provided at the narrow optical path between the illumination optical system IL and the projection optical system PL, the casing (not shown) which seals and encloses the reticle R and the reticle stage RS is filled with an inert gas such as nitrogen gas or helium gas or the space within the casing is sustained in a substantially vacuum state.

[0059] While the wafer W, the wafer stage WS and the like are provided at the narrow optical path between the projection optical system PL and the wafer W, the casing (not shown) which seals and encloses the reticle R and the wafer stage WS is filled with an inert gas such as nitrogen gas or helium gas or the space within the casing is sustained in a substantially vacuum state. Thus, an atmosphere into which the exposure light is hardly absorbed is formed over the entire optical path extending from the light source 100 to the wafer W.

[0060] As described earlier, the illumination area on the reticle R and the exposure area (i.e., the effective exposure area ER) on the wafer W defined by the projection optical system PL both have a rectangular shape with the short side extending along the Y direction. Thus, by synchronously moving (scanning) the reticle stage RS and the wafer stage WS, i.e., the reticle R and the wafer W, along opposite directions (toward opposite directions) in the direction in which the short sides of the rectangular exposure area and illumination area extend, i.e., in the Y direction, while controlling the positions of the reticle R and the wafer W with the drive systems and the interferometers (RIS and WIS), scanning exposure of the reticle pattern onto an area on the wafer W over an area having a width equal to the long side of the exposure area and a length corresponding to the distance over which the wafer W is scanned (the distance over which the wafer W moves) is achieved.

[0061] In each embodiment, the projection optical system PL constituted of the catadioptric system according to the present invention includes a catadioptric first image forming optical system G1 for forming a first intermediate image of the pattern at the reticle R set on the first plane, a catadioptric second image forming optical system G2 for forming a second intermediate image of the pattern at the reticle R by using the light traveling to the second image forming optical system G2 via the first image forming optical system G1 and a refractive third image forming optical system G3 for forming a final image of the reticle pattern (a reduced image of the reticle pattern) onto the wafer set on the second plane by using the light traveling to the third image forming optical system G3 via the second image forming optical system G2.

[0062] It is to be noted that in each of the embodiments, all the optical members constituting the first image forming optical system G1, the second image forming optical system G2 and the third image forming optical system G3 are disposed along a single linear optical axis AX. In addition, a first field lens is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. A second field lens is provided in the optical path between the second image forming optical system G2 and the third image forming optical system G3. It is to be noted that the reference optical axis AX is positioned along the direction of gravitational force (i.e., along the vertical direction). As a result, the reticle R and the wafer W are set parallel to each other along a plane perpendicular to the direction of gravitational force, i.e., along a horizontal plane. In addition, all the optical members (lenses and reflecting mirrors) constituting the projection optical system PL are disposed along the horizontal plane on the reference optical axis AX.

[0063] In each embodiment, all the refractive optical members (lens elements) constituting the projection optical system PL are formed by using fluorite (CaF_2 crystal). In addition, the oscillations central wavelength of F_2 laser light used as the exposure light is 157.6nm, and the change rate of the refractive index of CaF_2 in the vicinity of 157.6nm is -2×10^{-6} relative to a +1pm change in the wavelength and is $+2 \times 10^{-6}$ relative to a -1pm change in the wavelength. In other words, the variance ($dn/d\lambda$) of the refractive index of CaF_2 in the vicinity of 157.6nm is $2 \times 10^{-6}/\text{pm}$.

[0064] Accordingly, the refractive index of CaF_2 corresponding to the central wavelength of 157.6nm is 1.560000 in all the embodiments. In addition, in the first, second and fourth embodiments, the refractive index of CaF_2 corresponding

to 157.6nm + 0.5pm = 157.6005nm is 1.559999 and the refractive index of CaF₂ corresponding to 157.6nm - 0.5pm = 157.5995nm is 1.560001. In the third, fifth and sixth embodiments, the refractive index of CaF₂ corresponding to 157.6nm + 0.3pm = 157.6003nm is 1.5599994 and the refractive index of CaF₂ corresponding to 157.6nm - 0.3pm = 157.5997nm is 1.5600006. In the seventh ~ ninth embodiments, the refractive index of CaF₂ corresponding to 157.6nm + 0.4pm = 157.6004nm is 1.5599992 and the refractive index of CaF₂ corresponding to 157.6nm - 0.4pm = 157.5996nm is 1.5600008.

[0065] In addition, in all the embodiments, an aspherical surface is expressed as in a mathematical expression (a) below, with y representing the height along a direction perpendicular to the optical axis, z representing the distance from the tangential plane at the vertex of the aspherical surface to the position on the aspherical surface corresponding to the height y measured along the optical axis (the quantity of sag), r representing the radius of curvature at the vertex, κ representing the circular cone coefficient and C_n representing the aspherical coefficient of the nth degree.

$$z = (y^2/r) / [1 + \{1 - (1 + \kappa) \cdot y^2 / r^2\}^{1/2}] + C_4 \cdot y^4 + C_6 \cdot y^6 + C_8 \cdot y^8 + C_{10} \cdot y^{10} \quad (a)$$

[0066] In each embodiment, * is attached to the right side of the surface number assigned to a lens surface formed in an aspherical shape.

(First Embodiment)

[0067] FIG. 4 shows the lens configuration adopted in the catadioptric system (projection optical system PL) in the first embodiment. In the catadioptric system in FIG. 4, the first image forming optical system G1 is constituted with, starting on the reticle side, a positive meniscus lens L11 having an aspherical convex surface set facing toward the wafer, a positive meniscus lens L12 having an aspherical convex surface set facing toward the wafer, a concave reflecting mirror M1 having an almost flat concave surface set facing toward the wafer, a negative meniscus lens L13 having a concave surface set facing toward the reticle and a concave reflecting mirror M12 having a concave surface set facing toward the reticle.

[0068] In addition, the second image forming optical system G2 is constituted with, starting on the reticle side, a concave reflecting mirror M21 having a concave surface set facing toward the wafer, a negative meniscus lens L21 having a convex surface set facing toward the reticle and a concave reflecting mirror M22 having an almost flat concave surface set facing toward the reticle.

[0069] The third image forming optical system G3 is constituted with, starting on the reticle side, a negative meniscus lens L31 having an aspherical convex surface set facing toward the wafer, a negative meniscus lens L32 having an aspherical convex surface set facing toward the reticle, a positive meniscus lens L33 having an aspherical concave surface set facing toward the wafer, an aperture stop AS, a positive meniscus lens L34 having an aspherical concave surface set facing toward the reticle, a positive meniscus lens L35 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L36 having an aspherical lens with its concavity set facing toward the wafer, a biconvex lens L37 and a biconvex lens L38 having an aspherical convex surface set facing toward the wafer.

[0070] It is to be noted that a first field lens constituted with, starting on the reticle side, a positive meniscus lens L41 having an aspherical concave surface set facing toward the reticle, a biconvex lens L42 having an aspherical convex surface set facing toward the reticle and a positive meniscus lens L43 having an aspherical concave surface set facing toward the wafer is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. In addition, a second field lens constituted of a biconvex lens L51 having an aspherical convex surface set facing toward the reticle is provided in the optical path between the second image forming optical system G2 and the third image forming optical system G3.

[0071] Thus, light from the reticle R enters the concave reflecting mirror M12 via the positive meniscus lens L11 the positive meniscus lens L12 and the negative meniscus lens L13 in the first embodiment. After the light having been reflected at the concave reflecting mirror M12 is reflected at the concave reflecting mirror M11 via the negative meniscus lens L13, the light forms the first intermediate image of the reticle pattern within the first field lens (L41 ~ L43).

[0072] The light from the first intermediate image formed in the first field lens (L41 ~ L43) is reflected at the concave reflecting mirror M22, is reflected at the concave reflecting mirror M21 via the negative meniscus lens L21 and forms the second intermediate image of the reticle pattern near the second field lens L51 via the negative meniscus lens L21. The light from the second intermediate image formed near the second field lens L51 forms the final image of the reticle pattern onto the wafer W via the lenses L31 ~ L38 constituting the third image forming optical system G3.

[0073] Table (1) below lists data values regarding the catadioptric system achieved in the first embodiment. In the

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main data presented in Table (1), λ represents the central wavelength of the exposure light, β represents the projection magnification factor (the image forming magnification factor of the overall system), NA represents the image-side (wafer-side) numerical aperture, A represents the radius of the image circle IF on the wafer W, i.e., the maximum image height, B represents the maximum object height corresponding to the maximum image height A, LX represents the measurement of the effective exposure area ER along the X direction (the measurement of the long side) and LY represents the measurement of the effective exposure area ER along the Y direction (the measurement of the short side).

[0074] In addition, in the optical member data presented in Table (1), the surface numbers in the first column indicate the order in which the individual surfaces are set, starting from the reticle side, r in the second column indicates the radius of curvature of each surface (the radius of curvature at the vertex in the case of an aspherical surface: mm), d in the third column indicates the distances between the individual surfaces on the axis, i.e., the surface intervals (mm), and n in the fourth column indicates the refractive index corresponding to the central wavelength. It is to be noted that the sign attached to the value representing a surface interval d is switched each time the light is reflected. Accordingly, the sign attached to the values representing the surface intervals d within the optical path extending from the concave reflecting mirror M12 to the concave reflecting mirror M11 and the optical path extending from the concave reflecting mirror M22 to the concave reflecting mirror M21 is negative, and the sign is positive in the remaining optical path. In addition, regardless of the direction along which the light enters, the radius of curvature of a convex surface set facing toward the reticle assumes a positive value and the radius of curvature of a concave surface set facing toward the reticle assumes a negative value.

Table (1)

(main data)	
λ =	157.6nm
β =	1/4
NA=	0.70
A=	17mm
B=	68mm
LX=	22mm
LY=	5mm

(optical member data)			
surface			
number	r	d	n
(reticle surface)		64.582058	
1	-209.99497	24.525484	1.560000 (lens L11)
2*	-166.93294	2.218319	
3	-155.66573	15.657738	1.560000 (lens L12)
4*	-112.14862	222.368536	
5	-137.10069	10.687500	1.560000 (lens L13)
6	-297.35521	5.164034	
7	-230.99151	-5.164034	(concave reflecting mirror M12)
8	-297.35521	-10.687500	1.560000 (lens L13)
9	-137.10069	-202.268536	
10	9031.77704	238.120070	(concave reflecting mirror M11)
11*	-476.24503	35.519322	1.560000 (lens L41)
12	-183.40344	1.000000	
13*	232.87955	33.691524	1.560000 (lens L42)
14	-6107.18575	1.000000	
15	296.13333	25.457233	1.560000 (lens L43)
16*	365.41518	301.171316	
17	-2848.33830	-261.483816	(concave reflecting mirror M22)

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(continued)

(optical member data)			
surface			
number	r	d	n
18	165.31377	-10.687500	1.560000 (lens L21)
19	383.70240	-5.000000	
20	255.80102	5.000000	(concave reflecting mirror M21)
21	383.70240	10.687500	1.560000 (lens L21)
22	165.31377	281.483816	
23*	896.07542	60.560876	1.560000 (lens L51)
24	-133.46870	19.157687	
25	-130.23246	70.000000	1.560000 (lens L31)
26*	-151.76418	175.887352	
27*	132.53655	15.000000	1.560000 (lens L32)
28	94.29966	25.759223	
29	104.80691	17.096377	1.560000 (lens L33)
30*	291.29374	30.716267	
31	∞	6.113832	(aperture stop AS)
32*	-426.89300	18.954117	1.560000 (lens L34)
33	-107.18535	14.684919	
34	152.17692	18.992313	1.560000 (lens L35)
35	2173.98608	1.000000	
36	84.63119	31.851802	1.560000 (lens L36)
37*	383.82672	1.072291	
38	262.82386	15.136062	1.560000 (lens L37)
39	-676.46385	1.000000	
40	80.48028	37.973817	1.560000 (lens L38)
41*	-2872.34135	6.000000	
(wafer surface)			

(aspherical surface data)

surface 2

[0075] $\kappa=0.000000$

$C_4=-0.291653 \times 10^{-6}$ $C_6=0.688361 \times 10^{-11}$

$C_8=-0.173883 \times 10^{-15}$ $C_{10}=0.114644 \times 10^{-18}$

surface 4

[0076] $\kappa=0.000000$

$C_4=0.245562 \times 10^{-6}$ $C_6=0.937520 \times 10^{-11}$

$C_8=-0.121380 \times 10^{-14}$ $C_{10}=0.619768 \times 10^{-19}$

surface 11

[0077] $\kappa=0.000000$

$C_4=-0.317890 \times 10^{-7}$ $C_6=-0.350349 \times 10^{-11}$

$C_8=-0.549441 \times 10^{-15}$ $C_{10}=-0.185236 \times 10^{-19}$

surface 13

[0078] $\kappa=0.000000$

$$C_4=0.274807 \times 10^{-7} \quad C_6=-0.280710 \times 10^{-11} \\ C_8=-0.990831 \times 10^{-16} \quad C_{10}=-0.764627 \times 10^{-20}$$

surface 16

5

$$[0079] \quad \kappa=0.000000$$

$$C_4=0.507380 \times 10^{-7} \quad C_6=-0.797166 \times 10^{-11} \\ C_8=-0.693684 \times 10^{-6} \quad C_{10}=0.761192 \times 10^{-20}$$

10 surface 23

$$[0080] \quad \kappa=0.000000$$

$$C_4=-0.124616 \times 10^{-6} \quad C_6=0.245376 \times 10^{-10} \\ C_8=-0.436363 \times 10^{-14} \quad C_{10}=0.165599 \times 10^{-18}$$

15

surface 26

$$[0081] \quad \kappa=0.000000$$

$$C_4=-0.652972 \times 10^{-7} \quad C_6=0.117653 \times 10^{-10} \\ C_8=-0.107028 \times 10^{-14} \quad C_{10}=0.613946 \times 10^{-19}$$

20

surface 27

$$[0082] \quad \kappa=0.000000$$

$$C_4=-0.272313 \times 10^{-7} \quad C_6=-0.517344 \times 10^{-11} \\ C_8=-0.904051 \times 10^{-15} \quad C_{10}=-0.601541 \times 10^{-19}$$

25

surface 30

$$[0083] \quad \kappa=0.000000$$

$$C_4=0.303099 \times 10^{-6} \quad C_6=0.157674 \times 10^{-10} \\ C_8=0.136800 \times 10^{-14} \quad C_{10}=0.231671 \times 10^{-16}$$

30

surface 32

$$[0084] \quad \kappa=0.000000$$

$$C_4=-0.161006 \times 10^{-6} \quad C_6=0.118724 \times 10^{-10} \\ C_8=0.790687 \times 10^{-15} \quad C_{10}=0.271051 \times 10^{-19}$$

35

surface 37

$$[0085] \quad \kappa=0.000000$$

$$C_4=0.894445 \times 10^{-7} \quad C_6=0.728182 \times 10^{-10} \\ C_8=-0.886021 \times 10^{-14} \quad C_{10}=0.108877 \times 10^{-17}$$

40

surface 41

$$[0086] \quad \kappa=0.000000$$

$$C_4=0.677633 \times 10^{-6} \quad C_6=-0.377321 \times 10^{-9} \\ C_8=0.103549 \times 10^{-12} \quad C_{10}=0.227795 \times 10^{-16}$$

50

[0087] FIG. 5 shows the lateral aberration occurring in the catadioptric system in the first embodiment. In the aberration chart, Y represents the image height (mm). As the aberration chart clearly indicates, the chromatic aberration is properly corrected when the wavelength of the exposure light is within a range of $157.6\text{nm} \pm 0.5\text{pm}$ in the first embodiment. In addition, the chart confirms that the spherical aberration, the coma aberration, the astigmatism and the distortion are successfully corrected to an extent to which they are practically non-existent and thus, outstanding image forming performance is achieved.

55

(Second Embodiment)

[0088] FIG. 6 shows the configuration adopted in the catadioptric system (projection optical system PL) in the second embodiment. In the catadioptric system in FIG. 6, the first image forming optical system G1 is constituted with, starting on the reticle side, a positive meniscus lens L11 having an aspherical convex surface set facing toward the wafer, a positive meniscus lens L12 having an aspherical convex surface set facing toward the wafer, a concave reflecting mirror M11 having an almost flat concave surface set facing toward the wafer, a negative meniscus lens L13 having a concave surface set facing toward the reticle and a concave reflecting mirror M12 having a concave surface set facing toward the reticle.

[0089] In addition, the second image forming optical system G2 is constituted with, starting on the reticle side, a concave reflecting mirror M21 having a concave surface set facing toward the wafer, a negative meniscus lens L21 having a convex surface set facing toward the reticle and a concave reflecting mirror M22 having an almost flat concave surface set facing toward the reticle.

[0090] The third image forming optical system G3 is constituted with, starting on the reticle side, a negative meniscus lens L31 having an aspherical convex surface set facing toward the wafer, a negative meniscus lens L32 having an aspherical convex surface set facing toward the reticle, a biconvex lens L33 having an aspherical convex surface set facing toward the wafer, an aperture stop AS, a biconvex lens L34 having an aspherical convex surface set facing toward the reticle, a positive meniscus lens L35 having a convex surface set facing toward the reticle side, a positive meniscus lens L36 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L37 having a convex surface set facing toward the reticle and a biconvex lens L38 having an aspherical convex surface set facing toward the wafer.

[0091] It is to be noted that a first field lens constituted with, starting on the reticle side, a positive meniscus lens L41 having an aspherical concave surface set facing toward the reticle, a positive meniscus lens L42 having an aspherical convex surface set facing toward the reticle and a positive meniscus lens L43 having an aspherical concave surface set facing toward the wafer is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. In addition, a second field lens constituted of a biconvex lens L51 having an aspherical convex surface set facing toward the reticle is provided in the optical path between the second image forming optical system G2 and the third image forming optical system G3.

[0092] Thus, light from the reticle R enters the concave reflecting mirror M12 via the positive meniscus lens L11, the positive meniscus lens L12 and the negative meniscus lens L13 in the second embodiment. After the light having been reflected at the concave reflecting mirror M12 is reflected at the concave reflecting mirror M11 via the negative meniscus lens L13, the light forms the first intermediate image of the reticle pattern within the first field lens (L41 ~ L43).

[0093] The light from the first intermediate image formed in the first field lens (L41 ~ L43) is reflected at the concave reflecting mirror M22, is reflected at the concave reflecting mirror M21 via the negative meniscus lens L21 and forms the second intermediate image of the reticle pattern near the second field lens L51 via the negative meniscus lens L21. The light from the second intermediate image formed near the second field lens L51 forms the final image of the reticle pattern onto the wafer W via the lenses L31 ~ L38 constituting the third image forming optical system G3.

[0094] Table (2) below lists data values regarding the catadioptric system achieved in the second embodiment. In the main data presented in Table (2), λ represents the central wavelength of the exposure light, β represents the projection magnification factor (the image forming magnification factor of the overall system), NA represents the image-side (wafer-side) numerical aperture, A represents the radius of the image circle IF on the wafer W, i.e., the maximum image height, B represents the maximum object height corresponding to the maximum image height A, LX represents the measurement of the effective exposure area ER along the X direction (the measurement of the long side) and LY represents the measurement of the effective exposure area ER along the Y direction (the measurement of the short side).

[0095] In addition, in the optical member data presented in Table (2), the surface numbers in the first column indicate the order in which the individual surfaces are set, starting from the reticle side, r in the second column indicates the radius of curvature of each surface (the radius of curvature at the vertex in the case of an aspherical surface: mm), d in the third column indicates the distances between the individual surfaces on the axis, i.e., the surface intervals (mm,) and n in the fourth column indicates the refractive index corresponding to the central wavelength. It is to be noted that the sign attached to the value representing a surface interval d is switched each time the light is reflected. Accordingly, the sign attached to the values representing the surface intervals d within the optical path extending from the concave reflecting mirror M12 to the concave reflecting mirror M11 and the optical path extending from the concave reflecting mirror M22 to the concave reflecting mirror M21 is negative, and the sign is positive in the remaining optical path. In addition, regardless of the direction along which the light enters, the radius of curvature of a convex surface set facing toward the reticle assumes a positive value and the radius of curvature of a concave surface set facing toward the reticle assumes a negative value.

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Table (2)

(main data)	
$\lambda =$	157.6nm
$\beta =$	1/5
NA=	0.8
A=	21mm
B=	105mm
LX=	22mm
LY=	5mm

(optical member data)			
surface			
number	r	d	n
(reticle surface)		89.097796	
1	-183.14650	19.722044	1.560000 (lens L11)
2*	-172.17054	34.263431	
3	-461.61726	32.462803	1.560000 (lens L12)
4*	-180.99449	199.550635	
5	-272.56734	13.359375	1.560000 (lens L13)
6	-988.74052	13.790803	
7	-326.92312	-13.790803	(concave reflecting mirror M12)
8	-988.74052	-13.359375	1.560000 (lens L13)
9	-272.56734	-179.450635	
10	1164.40577	226.600813	(concave reflecting mirror M11)
11*	-673.49253	52.893617	1.560000 (lens L41)
12	-170.57409	1.000000	
13*	145.84783	18.775044	1.560000 (lens L42)
14	177.50368	1.000000	
15	174.53532	35.709621	1.560000 (lens L43)
16*	297.00962	294.044471	
17	-2044.05791	-247.356971	(concave reflecting mirror M22)
18	160.43373	-10.687500	1.560000 (lens L21)
19	366.71769	-12.000000	
20	264.23742	12.000000	(concave reflecting mirror M21)
21	366.71769	10.687500	1.560000 (lens L21)
22	160.43373	267.356971	
23*	385.86277	39.609336	1.560000 (lens L51)
24	-192.31716	45.851242	
25	-210.15146	15.000000	1.560000 (lens L31)
26*	-216.35913	193.996639	
27*	224.33623	28.450755	1.560000 (lens L32)
28	112.85221	2.259549	
29	118.06671	31.990438	1.560000 (lens L33)
30*	-575.87913	51.431023	
31	∞	32.226964	(aperture stop AS)
32*	739.93426	27.150099	1.560000 (lens L34)
33	-203.64309	1.000000	
34	180.06059	22.479157	1.560000 (lens L35)
35	737.32257	1.000000	

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(continued)

(optical member data)			
surface			
number	r	d	n
36	135.48460	23.362271	1.560000 (lens L36)
37*	559.50671	4.229139	
38	120.70160	24.487231	1.560000 (lens L37)
39	372.54409	8.973147	
40	91.59293	44.833371	1.560000 (lens L38)
41*	-2636.41853	6.000000	
(wafer surface)			

(aspherical surface data)

surface 2

[0096] $\kappa=0.000000$

$C_4=-0.264407 \times 10^{-7}$ $C_6=-0.476678 \times 10^{-12}$
 $C_8=0.155729 \times 10^{-15}$ $C_{10}=-0.517698 \times 10^{-20}$

surface 4

[0097] $\kappa=0.000000$

$C_4=0.280731 \times 10^{-7}$ $C_6=0.571906 \times 10^{-12}$
 $C_8=0.469828 \times 10^{-17}$ $C_{10}=0.988050 \times 10^{-21}$

surface 11

[0098] $\kappa=0.000000$

$C_4=0.275486 \times 10^{-7}$ $C_6=-0.57982 \times 10^{-11}$
 $C_8=0.188014 \times 10^{-15}$ $C_{10}=-0.327703 \times 10^{-20}$

surface 13

[0099] $\kappa=0.000000$

$C_4=-0.305645 \times 10^{-7}$ $C_6=-0.100924 \times 10^{-11}$
 $C_8=0.185962 \times 10^{-16}$ $C_{10}=-0.380314 \times 10^{-20}$

surface 16

[0100] $\kappa=0.000000$

$C_4=0.476746 \times 10^{-7}$ $C_6=-0.515517 \times 10^{-11}$
 $C_8=-0.536543 \times 10^{-16}$ $C_{10}=0.833063 \times 10^{-20}$

surface 23

[0101] $\kappa=0.000000$

$C_4=-0.916646 \times 10^{-7}$ $C_6=0.125088 \times 10^{-11}$
 $C_8=-0.367721 \times 10^{-16}$ $C_{10}=-0.108975 \times 10^{-20}$

surface 26

[0102] $\kappa=0.000000$

$C_4=-0.696241 \times 10^{-7}$ $C_6=0.269136 \times 10^{-10}$

$$C_8 = -0.305398 \times 10^{-14} \quad C_{10} = 0.112606 \times 10^{-18}$$

surface 27

5 [0103] $\kappa = 0.000000$

$$C_4 = 0.216592 \times 10^{-7} \quad C_6 = 0.590674 \times 10^{-11}$$

$$C_8 = 0.832609 \times 10^{-16} \quad C_{10} = -0.333598 \times 10^{-19}$$

surface 30

10

[0104] $\kappa = 0.000000$

$$C_4 = 0.180772 \times 10^{-6} \quad C_6 = -0.105754 \times 10^{-10}$$

$$C_8 = 0.691500 \times 10^{-15} \quad C_{10} = 0.189377 \times 10^{-19}$$

15 surface 32

[0105] $\kappa = 0.000000$

$$C_4 = -0.173909 \times 10^{-7} \quad C_6 = 0.507430 \times 10^{-11}$$

$$C_8 = -0.989619 \times 10^{-16} \quad C_{10} = -0.182632 \times 10^{-19}$$

20

surface 37

[0106] $\kappa = 0.000000$

$$C_4 = 0.764004 \times 10^{-7} \quad C_6 = 0.873773 \times 10^{-11}$$

$$25 \quad C_8 = -0.285150 \times 10^{-15} \quad C_{10} = 0.481104 \times 10^{-19}$$

surface 41

[0107] $\kappa = 0.000000$

$$30 \quad C_4 = 0.145715 \times 10^{-6} \quad C_6 = -0.124981 \times 10^{-9}$$

$$C_8 = 0.704755 \times 10^{-13} \quad C_{10} = -0.114853 \times 10^{-16}$$

[0108] FIG. 7 shows the lateral aberration occurring in the catadioptric system in the second embodiment. In the aberration chart, Y represents the image height (mm). As the aberration chart clearly indicates, the chromatic aberration is properly corrected in the second embodiment when the wavelength of the exposure light is within a range of 157.6nm \pm 0.5pm, as in the first embodiment. In addition, the chart confirms that the spherical aberration, the coma aberration, the astigmatism and the distortion are successfully corrected to an extent to which they are practically non-existent and thus, outstanding image forming performance is achieved.

35

(Third Embodiment)

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[0109] FIG. 8 shows the lens configuration adopted in the catadioptric system (projection optical system PL) in the third embodiment. In the catadioptric system in FIG. 8, the first image forming optical system G1 is constituted with, starting on the reticle side, a biconvex lens L11, a concave reflecting mirror M11 having an almost flat concave surface set facing toward the wafer and a concave reflecting mirror M12 having a concave surface set facing toward the reticle.

45 [0110] In addition, the second image forming optical system G2 is constituted with, starting on the reticle side, a concave reflecting mirror M21 having a concave surface set facing toward the wafer, a negative meniscus lens L21 having a convex surface set facing toward the reticle and a concave reflecting mirror M22 having an almost flat concave surface set facing toward the reticle.

50 [0111] The third image forming optical system G3 is constituted with, starting on the reticle side, a positive meniscus lens L31 having an aspherical concave surface set facing toward the reticle, a negative meniscus lens L32 having a convex surface set facing toward the reticle, a positive meniscus lens L33 having a convex surface set facing toward the reticle, a positive meniscus lens L34 having an aspherical concave surface set facing toward the wafer, a biconvex lens L35, a negative meniscus lens L36 having an aspherical concave surface set facing toward the reticle, an aperture stop AS, a negative meniscus lens L37 having an aspherical concave surface set facing toward the reticle, a biconvex lens L38 having an aspherical convex surface set facing toward the wafer, a positive meniscus lens L39 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L310 having a convex surface set facing toward the reticle, a biconcave lens L311 and a positive meniscus lens L312 having a convex surface set facing toward the reticle.

55

[0112] It is to be noted that a first field lens constituted with, starting on the reticle side, a biconvex lens L41 and a biconvex lens L42 having an aspherical convex surface set facing toward the wafer is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. In addition, a second field lens constituted with, starting on the reticle side, a positive meniscus lens L51 having a concave surface set facing toward the reticle and a biconvex lens L52 is provided in the optical path between the second image forming optical system G2 and the third image forming optical system G3.

[0113] Thus, light from the reticle R enters the concave reflecting mirror M12 via the biconvex lens L11 in the third embodiment. After the light having been reflected at the concave reflecting mirror M12 is reflected at the concave reflecting mirror M11, the light forms the first intermediate image of the reticle pattern via the first field lens (L41 and L42).

[0114] The light from the first intermediate image formed via the first field lens (L41 and L42) is reflected at the concave reflecting mirror M22, is reflected at the concave reflecting mirror M21 via the negative meniscus lens L21 and forms the second intermediate image of the reticle pattern near the second field lens (L51 and L52) via the negative meniscus lens L21. The light from the second intermediate image forms the final image of the reticle pattern onto the wafer W via the second field lens (L51 and L52) and the lenses L31 ~ L312 constituting the third image forming optical system G3.

[0115] Table (3) below lists data values regarding the catadioptric system achieved in the third embodiment. In the main data presented in Table (3), λ represents the central wavelength of the exposure light, β represents the projection magnification factor (the image forming magnification factor of the overall system), NA represents the image-side (wafer-side) numerical aperture, A represents the radius of the image circle IF on the wafer W, i.e., the maximum image height, B represents the maximum object height corresponding to the maximum image height A, LX represents the measurement of the effective exposure area ER along the X direction (the measurement of the long side) and LY represents the measurement of the effective exposure area ER along the Y direction (the measurement of the short side).

[0116] In addition, in the optical member data presented in Table (3), the surface numbers in the first column indicate the order in which the individual surfaces are set, starting from the reticle side, r in the second column indicates the radius of curvature of each surface (the radius of curvature at the vertex in the case of an aspherical surface: mm), d in the third column indicates the distances between the individual surfaces on the axis, i.e., the surface intervals (mm), and n in the fourth column indicates the reflective index corresponding to the central wavelength. It is to be noted that the sign attached to the value representing a surface interval d is switched each time the light is reflected. Accordingly, the sign attached to the values representing the surface intervals d within the optical path extending from the concave reflecting mirror M12 to the concave reflecting mirror M11 and the optical path extending from the concave reflecting mirror M22 to the concave reflecting mirror M21 is negative, and the sign is positive in the remaining optical path. In addition, regardless of the direction along which the light enters, the radius of curvature of a convex surface set facing toward the reticle assumes a positive value and the radius of curvature of a concave surface set facing toward the

Table (3)

(main data)	
λ =	157.6nm
β =	1/5
NA=	0.8
A=	18mm
B=	90mm
LX=	20mm
LY=	5mm

(optical member data)			
surface			
number	r	d	n
(reticle surface)		115.557292	1.560000 (lens L11)
1	637.80078	35.884968	
2	-384.35892	264.955326	
3	-649.27643	-234.955326	(concave reflecting mirror M12)

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(continued)

(optical member data)			
surface			
number	r	d	n
4	1823.09082	264.955326	(concave reflecting mirror M11)
5	801.77882	37.945664	1.560000 (lens L41)
6	-494.28706	3.445777	
7	369.70210	39.503113	1.560000 (lens L42)
8*	-792.94351	343.865788	
9	-1937.59830	-284.229026	(concave reflecting mirror M22)
10	155.49061	-12.344063	1.560000 (lens L21)
11	512.20865	-17.292699	
12	227.77903	17.292699	(concave reflecting mirror M21)
13	512.20865	12.344063	1.560000 (lens L21)
14	155.49061	314.229026	
15	-689.77068	17.668624	1.560000 (lens L51)
16	-259.40459	1.000000	
17	8014.40173	18.997331	1.560000 (lens L52)
18	-384.30480	56.716677	
19*	-1649.43052	30.000000	1.560000 (lens L31)
20	-393.58799	164.724808	
21	631.85472	15.000000	1.560000 (lens L32)
22	150.20509	19.656249	
23	538.55887	15.000000	1.560000 (lens L33)
24	1467.74312	31.821291	
25	165.43316	25.293398	1.560000 (lens L34)
26*	367.95233	6.929525	
27	350.71428	45.314099	1.560000 (lens L35)
28	-265.00281	45.939883	
29*	-222.47865	20.000000	1.560000 (lens L36)
30	-254.36058	1.000000	
31	∞	14.234702	(aperture stop AS)
32*	-300.54174	30.000000	1.560000 (lens L37)
33	-831.20280	1.000000	
34	202.39550	41.149482	1.560000 (lens L38)
35*	-341.32295	1.000000	
36	135.74819	60.768405	1.560000 (lens L39)
37*	873.19608	4.920450	
38	95.14679	23.732322	1.560000 (lens L310)
39	382.32196	4.152784	
40	-7890.70221	15.000000	1.560000 (lens L311)
41	554.20021	1.823828	
42	164.57547	17.998214	1.560000 (lens L312)
43	21350.59500	6.000000	
(wafer surface)			

(aspherical surface data)

surface 8

[0117] $\kappa=0.000000$

$$C_4=0.120134 \times 10^{-7} \quad C_6=-0.141075 \times 10^{-12}$$

$$C_8=0.191837 \times 10^{-17} \quad C_{10}=-0.169436 \times 10^{-22}$$

surface 19

5 **[0118]** $\kappa=0.000000$

$$C_4=-0.153558 \times 10^{-7} \quad C_6=-0.750057 \times 10^{-13}$$

$$C_8=0.110884 \times 10^{-16} \quad C_{10}=0.325196 \times 10^{-22}$$

10 surface 26

15 **[0119]** $\kappa=0.000000$

$$C_4=0.494425 \times 10^{-7} \quad C_6=0.707114 \times 10^{-12}$$

$$C_8=0.176474 \times 10^{-16} \quad C_{10}=0.0615523 \times 10^{-21}$$

surface 29

20 **[0120]** $\kappa=0.000000$

$$C_4=-0.755499 \times 10^{-8} \quad C_6=0.321947 \times 10^{-11}$$

$$C_8=-0.596697 \times 10^{-17} \quad C_{10}=-0.457591 \times 10^{-20}$$

surface 32

25 **[0121]** $\kappa=0.000000$

$$C_4=-0.509707 \times 10^{-7} \quad C_6=-0.426764 \times 10^{-11}$$

$$C_8=0.576131 \times 10^{-17} \quad C_{10}=-0.691255 \times 10^{-20}$$

surface 35

30 **[0122]** $\kappa=0.000000$

$$C_4=0.283140 \times 10^{-9} \quad C_6=0.915262 \times 10^{-12}$$

$$C_8=0.266523 \times 10^{-16} \quad C_{10}=0.112707 \times 10^{-21}$$

surface 37

35 **[0123]** $\kappa=0.000000$

$$C_4=0.443648 \times 10^{-7} \quad C_6=0.354423 \times 10^{-11}$$

$$C_8=0.351861 \times 10^{-16} \quad C_{10}=-0.206407 \times 10^{-19}$$

40 **[0124]** FIG. 9 shows the lateral aberration occurring in the catadioptric system in the third embodiment. In the aberration chart, Y represents the image height (mm). As the aberration chart clearly indicates, the chromatic aberration is properly corrected when the wavelength of the exposure light is within a range of $157.6\text{nm} \pm 0.3\text{pm}$ in the third embodiment. In addition, the chart confirms that the spherical aberration, the coma aberration, the astigmatism and the distortion are successfully corrected to an extent to which they are practically non-existent and thus, outstanding image forming performance is achieved.

45 (Fourth Embodiment)

50 **[0125]** FIG. 10 shows the lens configuration of the catadioptric system (projection optical system PL) achieved in the fourth embodiment. In the catadioptric system in FIG. 10, the first image forming optical system G1 is constituted with, starting on the reticle side, a biconvex lens 11 having an aspherical convex surface set facing toward the wafer, a negative meniscus lens L12 having an aspherical concave surface set facing toward the wafer, a concave reflecting mirror M11 having an almost flat concave surface set facing toward the wafer, a negative meniscus lens L13 having a concave surface set facing toward the reticle and a concave reflecting mirror M12 having a concave surface set facing toward the reticle.

55 **[0126]** In addition, the second image forming optical system G2 is constituted with, starting on the reticle side, a concave reflecting mirror M21 having a concave surface set facing toward the wafer, a negative meniscus lens L21 having a convex surface set facing toward the reticle and a concave reflecting mirror M22 having an almost flat concave surface set facing toward the reticle.

[0127] The third image forming optical system G3 is constituted with, starting on the reticle side, a positive meniscus lens L31 having an aspherical concave surface set facing toward the wafer, a negative meniscus lens L32 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L33 having an aspherical concave surface set facing toward the wafer, an aperture stop AS, a positive meniscus lens L34 having an aspherical concave surface set facing toward the reticle, a positive meniscus lens L35 having a convex surface set facing toward the reticle, a positive meniscus lens L36 having an aspherical concave surface set facing toward the wafer, a biconvex lens L37 having an aspherical convex surface set facing toward the wafer, a positive meniscus lens L38 having an aspherical concave surface set facing toward the wafer and a positive meniscus lens L39 having an aspherical convex surface set facing toward the reticle.

[0128] It is to be noted that a first field lens constituted with, starting on the reticle side, a positive meniscus lens L41 having a convex surface set facing toward the reticle, a positive meniscus lens L42 having an aspherical concave surface set facing toward the wafer and a positive meniscus lens L43 having an aspherical concave surface set facing toward the wafer is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. In addition, a second field lens constituted with, starting on the reticle side, a positive meniscus lens L51 having an aspherical concave surface set facing toward the wafer and a biconvex lens L52 having an aspherical convex surface set facing toward the wafer is provided in the optical path between the second image forming optical system G2 and the third image forming optical system G3.

[0129] Thus, light from the reticle R enters the concave reflecting mirror M12 via the biconvex lens L11, the negative meniscus lens L12 and the negative meniscus lens L13 in the fourth embodiment. After the light having been reflected at the concave reflecting mirror M12 is reflected at the concave reflecting mirror M11 via the negative meniscus lens L13, the light forms the first intermediate image of the reticle pattern in the first field lens (L41 ~ L43).

[0130] The light from the first intermediate image formed in the first field lens (L41 ~ L43) is reflected at the concave reflecting mirror M22, is reflected at the concave reflecting mirror M21 via the negative meniscus lens L21 and forms the second intermediate image of the reticle pattern in the second field lens (L51 and L52) via the negative meniscus lens L21. The light from the second intermediate image formed in the second field lens (L51 and L52) forms the final image of the reticle pattern onto the wafer W via the lenses L31 ~ L39 constituting the third image forming optical system G3.

[0131] Table (4) below lists data values regarding the catadioptric system achieved in the fourth embodiment. In the main data presented in Table (4), λ represents the central wavelength of the exposure light, β represents the projection magnification factor (the image forming magnification factor of the overall system), NA represents the image-side (wafer-side) numerical aperture, A represents the radius of the image circle IF on the wafer W, i.e., the maximum image height, B represents the maximum object height corresponding to the maximum image height A, LX represents the measurement of the effective exposure area ER along the X direction (the measurement of the long side) and LY represents the measurement of the effective exposure area ER along the Y direction (the measurement of the short side).

[0132] In addition, in the optical member data presented in Table (4), the surface numbers in the first column indicate the order in which the individual surfaces are set, starting from the reticle side, r in the second column indicates the radius of curvature of each surface (the radius of curvature at the vertex in the case of an aspherical surface: mm), d in the third column indicates the distances between the individual surfaces on the axis, i.e., the surface intervals (mm), and n in the fourth column indicates the refractive index corresponding to the central wavelength. It is to be noted that the sign attached to the value representing a surface interval d is switched each time the light is reflected. Accordingly, the sign attached to the values representing the surface intervals d within the optical path extending from the concave reflecting mirror M12 to the concave reflecting mirror M11 and the optical path extending from the concave reflecting mirror M22 to the concave reflecting mirror M21 is negative, and the sign is positive in the remaining optical path. In addition, regardless of the direction along which the light enters, the radius of curvature of a convex surface set facing toward the reticle assumes a positive value and the radius of curvature of a concave surface set facing toward the reticle assumes a negative value.

Table (4)

(main data)	
λ =	157.6nm
β =	1/5
NA=	0.6
A=	21mm
B=	105mm
LX=	22mm

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Table (4) (continued)

(main data)	
LY=	6mm

(optical member data)			
surface			
number	r	d	n
(reticle surface)		89.750712	
1	487.10912	59.670314	1.560000 (lens L11)
2*	-519.08376	1.000000	
3	903.03433	15.000000	1.560000 (lens L12)
4*	1000.08801	242.753250	
5	-175.15215	13.359375	1.560000 (lens L13)
6	-345.12145	4.339428	
7	-279.08379	-4.339428	(concave reflecting mirror M12)
8	-345.12145	-13.359375	1.560000 (lens L13)
9	-175.15215	-153.071977	
10	1708.26507	200.770780	(concave reflecting mirror M11)
11	249.41241	26.953146	1.560000 (lens L41)
12	718.70577	1.000000	
13	309.55923	20.466222	1.560000 (lens L42)
14*	307.16348	1.000000	
15	130.97653	54.347087	1.560000 (lens L43)
16*	-1198.98798	237.403998	
17	-932.83768	-186.980264	(concave reflecting mirror M22)
18	136.92807	-10.687500	1.560000 (lens L21)
19	362.11962	-9.736234	
20	239.02716	9.736234	(concave reflecting mirror M21)
21	362.11962	10.687500	1.560000 (lens L21)
22	136.92807	279.616570	
23	234.11735	35.444231	1.560000 (lens L51)
24*	166013.12617	19.145884	
25	443.29340	39.864137	1.560000 (lens L52)
26*	5423.37926	22.505878	
27	224.26889	15.000000	1.560000 (lens L31)
28*	450.00000	191.487329	
29	131.47312	15.000000	1.560000 (lens L32)
30*	73.42096	6.655173	
31	107.95341	21.906621	1.560000 (lens L33)
32*	-557437.69550	42.476569	
33	∞	2.832772	(aperture stop AS)
34*	-431.12055	17.973889	1.560000 (lens L34)
35	-118.75437	1.000000	
36	99.31449	15.000000	1.560000 (lens L35)
37	127.78163	1.000000	
38	92.45252	21.852801	1.560000 (lens L36)
39*	118.80433	6.195531	
40	198.80815	21.182933	1.560000 (lens L37)
41*	-156.29012	1.000000	

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(continued)

5

10

(optical member data)			
surface			
number	r	d	n
42	77.69761	24.589309 1	560000 (lens L38)
43*		443.02200	1.000000
44*	133.51267	31.188952	1.560000 (lens L39)
45	17904.27963	6.018159	
(wafer surface)			

(aspherical surface data)

15

surface 2

[0133] $\kappa=0.000000$

$C_4=-0.815643 \times 10^{-7}$ $C_6=0.413258 \times 10^{-11}$

20 $C_8=-0.113569 \times 10^{-15}$ $C_{10}=0.147898 \times 10^{-20}$

surface 4

[0134] $\kappa=0.000000$

25 $C_4=0.114732 \times 10^{-6}$ $C_6=-0.219867 \times 10^{-11}$

$C_8=0.617602 \times 10^{-16}$ $C_{10}=-0.322366 \times 10^{-21}$

surface 14

30 [0135] $\kappa=0.000000$

$C_4=-0.117278 \times 10^{-6}$ $C_6=0.199688 \times 10^{-11}$

$C_8=0.688425 \times 10^{-16}$ $C_{10}=-0.127291 \times 10^{-20}$

surface 16

35

[0136] $\kappa=0.000000$

$C_4=0.191460 \times 10^{-6}$ $C_6=0.172729 \times 10^{-11}$

$C_8=-0.417938 \times 10^{-15}$ $C_{10}=0.122892 \times 10^{-19}$

40 surface 24

[0137] $\kappa=0.000000$

$C_4=0.101006 \times 10^{-6}$ $C_6=-0.601731 \times 10^{-11}$

$C_8=0.336098 \times 10^{-15}$ $C_{10}=-0.113255 \times 10^{-19}$

45

surface 26

[0138] $\kappa=0.000000$

$C_4=-0.259409 \times 10^{-6}$ $C_6=0.200455 \times 10^{-10}$

50 $C_8=-0.886510 \times 10^{-15}$ $C_{10}=0.203312 \times 10^{-19}$

surface 28

[0139] $\kappa=0.000000$

55 $C_4=0.254720 \times 10^{-6}$ $C_6=-0.499612 \times 10^{-11}$

$C_8=-0.101235 \times 10^{-15}$ $C_{10}=0.475827 \times 10^{-19}$

surface 30

[0140] $\kappa=0.000000$

$C_4=-0.122986 \times 10^{-6}$ $C_6=-0.297417 \times 10^{-10}$

5 $C_8=-0.286999 \times 10^{-14}$ $C_{10}=-0.314877 \times 10^{-18}$

surface 32

[0141] $\kappa=0.000000$

10 $C_4=0.260763 \times 10^{-6}$ $C_6=0.278223 \times 10^{-10}$

$C_8=0.311168 \times 10^{-14}$ $C_{10}=0.409140 \times 10^{-18}$

surface 34

15 [0142] $\kappa=0.000000$

$C_4=-0.246966 \times 10^{-7}$ $C_6=-0.328800 \times 10^{-11}$

$C_8=0.155119 \times 10^{-14}$ $C_{10}=0.481917 \times 10^{-19}$

surface 39

20

[0143] $\kappa=0.000000$

$C_4=0.363517 \times 10^{-6}$ $C_6=0.688387 \times 10^{-12}$

$C_8=0.263082 \times 10^{-14}$ $C_{10}=0.401937 \times 10^{-18}$

25 surface 41

[0144] $\kappa=0.000000$

$C_4=0.171166 \times 10^{-6}$ $C_6=0.110988 \times 10^{-10}$

$C_8=0.989095 \times 10^{-15}$ $C_{10}=0.238040 \times 10^{-18}$

30

surface 43

[0145] $\kappa=0.000000$

$C_4=0.130469 \times 10^{-6}$ $C_6=0.132452 \times 10^{-9}$

35 $C_8=-0.246540 \times 10^{-13}$ $C_{10}=0.404311 \times 10^{-17}$

surface 44

[0146] $\kappa=0.000000$

40

$C_4=0.736368 \times 10^{-6}$ $C_6=0.554124 \times 10^{-10}$

$C_8=0.111988 \times 10^{-13}$ $C_{10}=0.498595 \times 10^{-17}$

[0147] FIG. 11 shows the lateral aberration occurring in the catadioptric system in the fourth embodiment. In the aberration chart, Y represents the image height (mm). As the aberration chart clearly indicates, the chromatic aberration is properly corrected in the fourth embodiment when the wavelength of the exposure light is within a range of $157.6\text{nm} \pm 0.5\text{pm}$, as in the first and second embodiments. In addition, the chart confirms that the spherical aberration, the coma aberration, the astigmatism and the distortion are successfully corrected to an extent to which they are practically non-existent and thus, outstanding image forming performance is achieved.

45

(Fifth Embodiment)

50

[0148] FIG. 12 shows the lens configuration of the catadioptric system (projection optical system PL) achieved in the fifth embodiment. In the catadioptric system in FIG. 12, the first image forming optical system G1 is constituted with, starting on the reticle side, a positive meniscus lens L1 having a convex surface set facing toward the reticle, a concave reflecting mirror M11 having an almost flat concave surface set facing toward the wafer, a negative meniscus lens L12 having a concave surface set facing toward the reticle and a concave reflecting mirror M12 having a concave surface set facing toward the reticle.

55

[0149] The second image forming optical system G2 is constituted with, starting on the reticle side, a concave reflecting mirror M21 having a concave surface set facing toward the wafer and a concave reflecting mirror M22 having

an almost flat concave surface set facing toward the reticle.

[0150] The third image forming optical system G3 is constituted with, starting on the reticle side, a biconcave lens L31, a positive meniscus lens L32 having an aspherical concave surface set facing toward the wafer, a biconvex lens L33, a negative meniscus lens L34 having a convex surface set facing toward the reticle, a positive meniscus lens L35 having a convex surface set facing toward the reticle, a positive meniscus lens L36 having an aspherical concave surface set facing toward the wafer, a biconvex lens L37, a negative meniscus lens L38 having a concave surface set facing toward the reticle, an aperture stop AS, a negative meniscus lens L39 having an aspherical concave surface set facing toward the reticle, a biconvex lens L310 having an aspherical convex surface set facing toward the wafer, a negative meniscus lens L311 having a concave surface set facing toward the reticle, a positive meniscus lens L312 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L313 having a convex surface set facing toward the reticle, a positive meniscus lens L314 having a convex surface set facing toward the reticle and a biconvex lens L315.

[0151] It is to be noted that a first field lens constituted with, starting on the reticle side, a biconvex lens L41 and a positive meniscus lens L42 having an aspherical concave surface set facing toward the wafer is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. A second field lens constituted with, starting on the reticle side, a positive meniscus lens L51 having an aspherical concave surface set facing toward the reticle and a biconvex lens L52 is provided in the optical path between the second image forming optical system G2 and the third image forming optical system G3.

[0152] Thus, light from the reticle R enters the concave reflecting mirror M12 via the positive meniscus lens L11 and the negative meniscus lens L12 in the fifth embodiment. After the light having been reflected at the concave reflecting mirror M12 is reflected at the concave reflecting mirror M11 via the negative meniscus lens L12, the light forms the first intermediate image of the reticle pattern near the first field lens (L41 and L42).

[0153] After the light from the first intermediate image is sequentially reflected at the concave reflecting mirror M22 and the concave reflecting mirror M21 via the first field lens (L41 and L42), the light forms the second intermediate image of the reticle pattern near the second field lens (L51 and L52). The light from the second intermediate image then forms the final image of the reticle pattern onto the wafer W via the second field lens (L51 and L52) and the lenses L31 ~ L315 constituting the third image forming optical system G3.

[0154] Table (5) below lists data values regarding the catadioptric system achieved in the fifth embodiment. In the main data presented in Table (5), λ represents the central wavelength of the exposure light, β represents the projection magnification factor (the image forming magnification factor of the overall system), NA represents the image-side (wafer-side) numerical aperture, A represents the radius of the image circle IF on the wafer W, i.e., the maximum image height, B represents the maximum object height corresponding to the maximum image height A, LX represents the measurement of the effective exposure area ER along the X direction (the measurement of the long side) and LY represents the measurement of the effective exposure area ER along the Y direction (the measurement of the short side).

[0155] In addition, in the optical member data presented in Table (5), the surface numbers in the first column indicate the order in which the individual surfaces are set, starting from the reticle side, r in the second column indicates the radius of curvature of each surface (the radius of curvature at the vertex in the case of an aspherical surface: mm), d in the third column indicates the distances between the individual surfaces on the axis, i.e., the surface intervals (mm,) and n in the fourth column indicates the refractive index corresponding to the central wavelength. It is to be noted that the sign attached to the value representing a surface interval d is switched each time the light is reflected. Accordingly, the sign attached to the values representing the surface intervals d within the optical path extending from the concave reflecting mirror M12 to the concave reflecting mirror M11 and the optical path extending from the concave reflecting mirror M22 to the concave reflecting mirror M21 is negative, and the sign is positive in the remaining optical path. In addition, regardless of the direction along which the light enters, the radius of curvature of a convex surface set facing toward the reticle assumes a positive value and the radius of curvature of a concave surface set facing toward the reticle assumes a negative value.

Table (5)

(main data)	
$\lambda =$	157.6nm
$\beta =$	1/5
NA=	0.8
A=	18mm
B=	90mm
LX=	20mm

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Table (5) (continued)

(main data)	
LY=	5mm

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(optical member data)			
surface			
number	r	d	n
(reticle surface)		61.000000	
1	211.27080	26.106514	1.560000 (lens L11)
2	459.51275	321.906829	
3	-213.95008	20.000000	1.560000 (lens L12)
4	-1566.75457	16.802820	
5	-284.67128	-16.802820	(concave reflecting mirror M12)
6	-1566.75457	-20.000000	1.560000 (lens L12)
7	-213.95008	-291.906829	
8	1086.35493	358.709650	(concave reflecting mirror M11)
9	318.29494	44.860140	1.560000 (lens L41)
10	-887.18127	1.000000	
11	171.70178	32.360508	1.560000 (lens L42)
12*	289.71170	292.761556	
13	-1680.12168	-262.761555	(concave reflecting mirror M22)
14	417.88785	346.788846	(concave reflecting mirror M21)
15*	-280.27770	23.000000	1.560000 (lens L51)
16	-181.49299	1.000000	
17	362.82014	70.000000	1.560000 (lens L52)
18	-416.73075	146.098155	
19	-156.85191	20.000000	1.560000 (lens L31)
20	267.60016	1.000000	
21	187.76395	25.225435	1.560000 (lens L32)
22*	384.80207	2.961318	
23	431.01527	41.508704	1.560000 (lens L33)
24	-276.05667	1.000000	
25	308.47916	20.000000	1.560000 (lens L34)
26	136.01010	20.206121	
27	277.79256	21.000000	1.560000 (lens L35)
28	333.49880	1.000000	
29	125.27880	25.793541	1.560000 (lens L36)
30*	216.27362	7.601524	
31	154.24702	48.496542	1.560000 (lens L37)
32	-544.19222	18.722230	
33	-285.23875	20.000000	1.560000 (lens L38)
34	-800.51580	10.000000	
35	∞	13.059929	(aperture stop AS)
36*	-322.74880	16.000000	1.560000 (lens L39)
37	-286.86928	1.000000	
38	164.94509	45.299315	1.560000 (lens L310)
39*	-210.06061	2.818820	
40	-163.13416	15.000000	1.560000 (lens L311)
41	-369.63693	1.000000	

(continued)

(optical member data)			
surface			
number	r	d	n
42	111.12796	27.284262	1.560000 (lens L312)
43*	1842.35594	1.000000	
44	92.22880	20.000000	1.560000 (lens L313)
45	177.36266	1.236998	
46	177.43094	16.861444	1.560000 (lens L314)
47	186.23389	1.000000	
48	165.56422	15.000000	1.560000 (lens L315)
49	-1131.06283	6.000000	
(wafer surface)			

(aspherical surface data)

surface 12

[0156] $\kappa=0.000000$ $C_4=0.181313 \times 10^{-7}$ $C_6=0.145718 \times 10^{-12}$ $C_8=-0.178341 \times 10^{-17}$ $C_{10}=0.265148 \times 10^{-21}$

surface 15

[0157] $\kappa=0.000000$ $C_4=0.588707 \times 10^{-7}$ $C_6=-0.844226 \times 10^{-12}$ $C_8=-0.743823 \times 10^{-16}$ $C_{10}=-0.197114 \times 10^{-21}$

surface 22

[0158] $\kappa=0.000000$ $C_4=-0.294829 \times 10^{-7}$ $C_6=0.384432 \times 10^{-11}$ $C_8=-0.393756 \times 10^{-16}$ $C_{10}=-0.345603 \times 10^{-21}$

surface 30

[0159] $\kappa=0.000000$ $C_4=0.100809 \times 10^{-6}$ $C_6=0.669526 \times 10^{-12}$ $C_8=-0.609327 \times 10^{-17}$ $C_{10}=0.830042 \times 10^{-21}$

surface 36

[0160] $\kappa=0.000000$ $C_4=-0.137850 \times 10^{-6}$ $C_6=-0.508803 \times 10^{-11}$ $C_8=-0.272924 \times 10^{-15}$ $C_{10}=-0.202953 \times 10^{-19}$

surface 39

[0161] $\kappa=0.000000$ $C_4=-0.111530 \times 10^{-6}$ $C_6=0.650079 \times 10^{-11}$ $C_8=0.157560 \times 10^{-15}$ $C_{10}=-0.172336 \times 10^{-19}$

surface 43

[0162] $\kappa=0.000000$

$C_4=0.170111 \times 10^{-6}$ $C_6=-0.258296 \times 10^{-11}$

5 $C_8=0.608232 \times 10^{-15}$ $C_{10}=0.232160 \times 10^{-19}$

[0163] FIG. 13 shows the lateral aberration occurring in the catadioptric system in the fifth embodiment. In the aberration chart, Y represents the image height (mm). As the aberration chart clearly indicates, the chromatic aberration is properly corrected in the fifth embodiment when the wavelength of the exposure light is within a range of $157.6\text{nm} \pm 0.3\text{pm}$, as in the third embodiment. In addition, the chart confirms that the spherical aberration, the coma aberration, the astigmatism and the distortion are successfully corrected to an extent to which they are practically non-existent and thus, outstanding image forming performance is achieved.

(Sixth Embodiment)

15 [0164] FIG. 14 shows the lens configuration of the catadioptric system (projection optical system PL) achieved in the sixth embodiment. In the catadioptric system in FIG. 14, the first image forming optical system G1 is constituted with, starting on the reticle side, a positive meniscus lens L11 having a convex surface set facing toward the reticle, a concave reflecting mirror M11 having an almost flat concave surface set facing toward the wafer and a concave reflecting mirror M12 having a concave surface set facing toward the reticle.

20 [0165] The second image forming optical system G2 is constituted with, starting on the reticle side, a concave reflecting mirror M21 having a concave surface set facing toward the wafer, a negative meniscus lens L21 having a convex surface set facing toward the reticle and a concave reflecting mirror M22 having an almost flat concave surface set facing toward the reticle.

[0166] The third image forming optical system G3 is constituted with, starting on the reticle side, a biconcave lens L31, a negative meniscus lens L32 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L33 having a convex surface set facing toward the reticle, a biconcave lens L34, a negative meniscus lens L35 having a concave surface set facing toward the reticle, a positive meniscus lens L36 having an aspherical concave surface set facing toward the wafer, a biconvex lens L37, a negative meniscus lens L38 having a concave surface set facing toward the reticle, an aperture stop AS, a positive meniscus lens L39 having an aspherical concave surface set facing toward the reticle, a biconvex lens L310 having an aspherical convex surface set facing toward the wafer, a negative meniscus lens L311 having a concave surface set facing toward the reticle, a positive meniscus lens L312 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L313 having a convex surface set facing toward the reticle, a negative meniscus lens L314 having a convex surface set facing toward the reticle and a biconvex lens L315.

35 [0167] It is to be noted that a first field lens constituted with, starting on the reticle side, a positive meniscus lens L41 having a concave surface set facing toward the reticle and a biconvex lens L42 having an aspherical convex surface set facing toward the wafer is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. In addition, a second field lens constituted with, starting on the reticle side, a biconvex lens L51 having an aspherical convex surface set facing toward the reticle and a biconvex lens L52 is provided in the optical path between the second image forming optical system G2 and the third image forming optical system G3.

40 [0168] Thus, light from the reticle R enters the concave reflecting mirror M12 via the positive meniscus lens L11 in the sixth embodiment. After the light having been reflected at the concave reflecting mirror M12 is reflected at the concave reflecting mirror M11, the light forms the first intermediate image of the reticle pattern in the first field lens (L41 and L42).

45 [0169] The light from the first intermediate image formed in the first field lens (L41 and L42) is reflected at the concave reflecting mirror M22, is reflected at the concave reflecting mirror M21 via the negative meniscus lens L21 and then forms the second intermediate image of the reticle pattern near the second field lens (L51 and L52) via the negative meniscus lens L21. The light from the second intermediate image then forms the final image of the reticle pattern onto the wafer W via the second field lens (L51 and L52) and the lens L31 ~ L315 constituting the third image forming optical system G3.

50 [0170] It is to be noted that while a rectangular effective exposure area ER is formed on the wafer W in the first ~ fifth embodiments described above, an effective exposure area ER in a circular arch shape is formed in the sixth embodiment. FIG. 15 shows the positional relationship between the circular arch-shaped effective exposure area formed on the wafer and the reference optical axis achieved in the sixth embodiment. As shown in FIG. 15, a circular arch-shaped effective exposure area ER in a desired size is set at a position off the reference optical axis AX along the +Y direction within a circular area (image circle) IF with a radius A (which corresponds to the maximum image height) centered around the reference optical axis in the sixth embodiment. The arch-shaped effective exposure area

ER measures LX' along the X direction and LY' along the Y direction. Thus, a circular arch-shaped illumination area IR having a size and shape corresponding to those of the circular arch-shaped effective exposure area ER is formed on the reticle R at a position off the reference optical axis AX along the - Y direction. Namely, the circular arch-shaped illumination area IR in a desired size is set at a position off the reference optical axis AX along the - Y direction within a circular area having a radius B (which corresponds to the maximum object height) centering around the reference optical axis AX.

[0171] Table (6) below lists data values regarding the catadioptric system achieved in the sixth embodiment. In the main data presented in Table (6), λ represents the central wavelength of the exposure light, β represents the projection magnification factor (the image forming magnification factor of the overall system), NA represents the image-side (wafer-side) numerical aperture, A represents the radius of the image circle IF on the wafer W, i.e., the maximum image height, B represents the maximum object height corresponding to the maximum image height A, LX' represents the measurement of the circular arch-shaped effective exposure area ER along the X direction and LY' represents the measurement of the circular arch-shaped effective exposure area ER along the Y direction.

[0172] In addition, in the optical member data presented in Table (6), the surface numbers in the first column indicate the order in which the individual surfaces are set, starting from the reticle side, r in the second column indicates the radius of curvature of each surface (the radius of curvature at the vertex in the case of an aspherical surface: mm), d in the third column indicates the distances between the individual surfaces on the axis, i.e., the surface intervals (mm,) and n in the fourth column indicates the reflective index corresponding to the central wavelength. It is to be noted that the sign attached to the value representing a surface interval d is switched each time the light is reflected. Accordingly, the sign attached to the values representing the surface intervals d within the optical path extending from the concave reflecting mirror M12 to the concave reflecting mirror M11 and the optical path extending from the concave reflecting mirror M22 to the concave reflecting mirror M21 is negative, and the sign is positive in the remaining optical path. In addition, regardless of the direction along which the light enters, the radius of curvature of the convex surface set facing toward the reticle assumes a positive value and the radius of curvature of a concave surface set facing toward the reticle assumes a negative value.

Table (6)

(main data)	
λ =	157.6nm
β =	1/5
NA=	0.8
A=	18mm
B=	90mm
LX' =	20mm
LY' =	3mm

(optical member data)			
surface			
number	r	d	n
(reticle surface)		60.000000	
1	419.18852	19.580407	1.560000 (lens L11)
2	1680.57391	254.993608	
3	-489.61861	-224.993608	(concave reflecting mirror M12)
4	2084.90414	254.993608	(concave reflecting mirror M11)
5	-1514.77737	69.985952	1.560000 (lens L41)
6	-244.82172	1.000000	
7	364.28042	32.967769	1.560000 (lens L42)
8*	-3138.44099	509.623508	
9	-2184.60801	-442.835110	(concave reflecting mirror M22)
10	149.68327	-20.000000	1.560000 (lens L21)
11	559.08929	-16.788398	
12	263.00265	16.788398	(concave reflecting mirror M21)

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(continued)

(optical member data)			
surface			
number	r	d	n
13	559.08929	20.000000	1.560000 (lens L21)
14	149.68327	442.835110	
15*	1889.70924	23.000000	1.560000 (lens L51)
16	-264.21722	1.000000	
17	233.99661	35.823627	1.560000 (lens L52)
18	-619.37646	38.987456	
19	-5441.96593	20.000000	1.560000 (lens L31)
20	502.25155	1.000000	
21	182.75539	20.000000	1.560000 (lens L32)
22*	97.20773	1.457183	
23	97.56626	26.063961	1.560000 (lens L33)
24	183.48181	23.001316	
25	-240.13113	20.000000	1.560000 (lens L34)
26	145.02922	19.973246	
27	-950.10258	21.000000	1.560000 (lens L35)
28	-183.48772	69.067372	
29	126.47126	23.315183	1.560000 (lens L36)
30*	187.64534	7.841194	
31	217.50174	40.946892	1.560000 (lens L37)
32	-326.63509	22.449513	
33	-196.62797	20.000000	1.560000 (lens L38)
34	-267.67602	10.000000	
35	∞	12.422431	(aperture stop AS)
36*	-340.00000	16.000000	1.560000 (lens L39)
37	-248.51990	1.000000	
38	156.19975	43.018450	1.560000 (lens L310)
39*	-324.35639	5.121067	
40	-177.96849	15.000000	1.560000 (lens L311)
41	-358.98302	1.000000	
42	107.39866	29.810536	1.560000 (lens L312)
43*	-5286.38967	1.000000	
44	88.60392	20.000000	1.560000 (lens L313)
45	178.21372	1.000000	
46	177.28766	17.334341	1.560000 (lens L314)
47	131.47878	1.213668	
48	131.32841	15.001321	1.560000 (lens L315)
49	-1923.73296	6.000000	
(wafer surface)			

(aspherical surface data)

surface 8

[0173] $\kappa=0.000000$

$C_4=0.554200 \times 10^{-8}$ $C_6=-0.280967 \times 10^{-13}$

$C_8=0.778972 \times 10^{-18}$ $C_{10}=-0.177500 \times 10^{-22}$

surface 15

[0174] $\kappa=0.000000$

$C_4=-0.109228 \times 10^{-7}$ $C_6=-0.364285 \times 10^{-12}$

5 $C_8=0.142762 \times 10^{-16}$ $C_{10}=-0.362739 \times 10^{-21}$

surface 22

[0175] $\kappa=0.000000$

10 $C_4=0.225626 \times 10^{-7}$ $C_6=-0.154524 \times 10^{-12}$

$C_8=0.164766 \times 10^{-16}$ $C_{10}=0.164885 \times 10^{-20}$

surface 30

15 [0176] $\kappa=0.000000$

$C_4=0.379428 \times 10^{-7}$ $C_6=0.163017 \times 10^{-11}$

$C_8=0.684667 \times 10^{-16}$ $C_{10}=-0.115849 \times 10^{-20}$

surface 36

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[0177] $\kappa=0.000000$

$C_4=-0.146106 \times 10^{-6}$ $C_6=-0.502919 \times 10^{-11}$

$C_8=-0.270461 \times 10^{-15}$ $C_{10}=-0.186877 \times 10^{-19}$

25 surface 39

[0178] $\kappa=0.000000$

$C_4=-0.159225 \times 10^{-6}$ $C_6=0.844367 \times 10^{-11}$

$C_8=-0.120649 \times 10^{-15}$ $C_{10}=-0.173041 \times 10^{-19}$

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surface 43

[0179] $\kappa=0.000000$

$C_4=0.204302 \times 10^{-6}$ $C_6=-0.422928 \times 10^{-11}$

35 $C_8=0.824463 \times 10^{-15}$ $C_{10}=0.719034 \times 10^{-20}$

[0180] FIG. 16 shows the lateral aberration occurring in the catadioptric system in the sixth embodiment. In the aberration chart, Y represents the image height (mm). As the aberration chart clearly indicates, in the sixth embodiment, the chromatic aberration is properly corrected when the wavelength of the exposure light is within a range of 157.6nm \pm 0.3pm, as in the third and fifth embodiments. In addition, the chart confirms that the spherical aberration, the coma aberration, the astigmatism and the distortion are successfully corrected to an extent to which they are practically non-existent and thus, outstanding image forming performance is achieved.

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(Seventh Embodiment)

45 [0181] FIG. 17 shows the lens configuration of the catadioptric system (projection optical system PL) achieved in the seventh embodiment. In the catadioptric system in FIG. 17, the first image forming optical system G1 is constituted with, starting on the reticle side, a biconvex lens L11, a convex reflecting mirror M11 having an almost flat convex surface set facing toward the wafer and a concave reflecting mirror M12 having a concave surface set facing toward the reticle.

50 [0182] The second image forming optical system G2 is constituted with, starting on the reticle side, a concave reflecting mirror M21 having a concave surface set facing toward the wafer, a negative meniscus lens L21 having a convex surface set facing toward the reticle, a negative meniscus lens L22 having a concave surface set facing toward the reticle and a concave reflecting mirror M22 having a concave surface set facing toward the reticle.

55 [0183] In addition, the third image forming optical system G3 is constituted with, starting on the reticle side, a positive meniscus lens L31 having a convex surface set facing toward the reticle, a negative meniscus lens L32 having a convex surface set facing toward the reticle, a positive meniscus lens L33 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L34 having a convex surface set facing toward the reticle, a negative meniscus lens L35 having a convex surface set facing toward the reticle, a negative meniscus lens L36 having a concave

surface set facing toward the reticle, a positive meniscus lens L37 having an aspherical concave surface set facing toward the wafer, a biconvex lens L38, a positive meniscus lens L39 having a concave surface set facing toward the reticle, a negative meniscus lens L310 having a concave surface set facing toward the reticle, a negative meniscus lens L311 having an aspherical concave surface set facing toward the reticle, a positive meniscus lens L312 having a convex surface set facing toward the reticle, a biconvex lens L313 having an aspherical convex surface set facing toward the wafer, a negative meniscus lens L314 having a concave surface set facing toward the reticle, a positive meniscus lens L315 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L316 having a convex surface set facing toward the reticle and a positive meniscus lens L317 having a convex surface set facing toward the reticle.

[0184] It is to be noted that a first field lens constituted with, starting on the reticle side, a biconvex lens L41 and a biconvex lens L42 having an aspherical convex surface set facing toward the wafer is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. In addition, a second field lens constituted of a biconvex lens L51 having an aspherical convex surface set facing toward the reticle is provided in the optical path between the second image forming optical system G2 and the third image forming optical system G3.

[0185] Thus, light from the reticle R enters the concave reflecting mirror M12 via the biconvex lens L11 in the seventh embodiment. After the light having been reflected at the concave reflecting mirror M12 is reflected at the convex reflecting mirror M11, the light forms the first intermediate image of the reticle pattern near the first field lens (L41 and L42).

[0186] The light from the first intermediate image is first reflected at the concave reflecting mirror M22 via the negative meniscus lens L22 and then enters the concave reflecting mirror M21 via the negative meniscus lens L22 and the negative meniscus lens L21. The light reflected at the concave reflecting mirror M21 forms the second intermediate image of the reticle pattern near the second field lens (L51) via the negative meniscus lens L21. The light from the second intermediate image then forms the final image of the reticle pattern onto the wafer W via the lenses L31~L317 constituting the third image forming optical system G3.

[0187] Table (7) below lists data values regarding the catadioptric system achieved in the seventh embodiment. In the main data presented in Table (5), λ represents the central wavelength of the exposure light, β represents the projection magnification factor (the image forming magnification factor of the overall system), NA represents the image-side (wafer-side) numerical aperture, A represents the radius of the image circle IF on the wafer W, i.e., the maximum image height, B represents the maximum object height corresponding to the maximum image height A, LX represents the measurement of the effective exposure area ER along the X direction (the measurement of the long side) and LY represents the measurement of the effective exposure area ER along the Y direction (the measurement of the short side).

[0188] In addition, in the optical member data presented in Table (7), the surface numbers in the first column indicate the order in which the individual surfaces are set, starting from the reticle side, r in the second column indicates the radius of curvature of each surface (the radius of curvature at the vertex in the case of an aspherical surface: mm), d in the third column indicates the distances between the individual surfaces on the axis, i.e., the surface intervals (mm), and n in the fourth column indicates the refractive index corresponding to the central wavelength. It is to be noted that the sign attached to the value representing a surface interval d is switched each time the light is reflected. Accordingly, the sign attached to the values representing the surface intervals d within the optical path extending from the concave reflecting mirror M12 to the concave reflecting mirror M11 and the optical path extending from the concave reflecting mirror M22 to the concave reflecting mirror M21 is negative, and the sign is positive in the remaining optical path. In addition, regardless of the direction along which the light enters, the radius of curvature of the convex surface set facing toward the reticle assumes a positive value and the radius of curvature of the concave surface set facing toward the reticle assumes a negative value. Also, conditional expression corresponding values LAT and AX respectively indicate the magnification factor chromatic aberration coefficient and the on-axis chromatic aberration coefficient in Table (7).

Table (7)

(main data)	
λ =	157.6nm
β =	1/4
NA=	0.845
A=	18mm
B=	72mm
LX=	22mm
LY=	4mm

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(optical member data)			
surface			
number	r	d	n
(reticle surface)		64.313122	
1	633.35560	29.362563	1.560000 (lens L11)
2	-297.41454	217.631552	
3	-376.41908	-187.631552	(concave reflecting mirror M12)
4	-1719.92425	217.631552	(convex reflecting mirror M11)
5	1020.41099	44.070507	1.560000 (lens L41)
6	-406.99116	1.000000	
7	426.60624	46.118329	1.560000 (lens L42)
8*	-604.42303	465.826853	
9	-401.62011	20.000000	1.560000 (lens L22)
10	-2157.31867	6.871072	
11	-632.50781	-6.871072	(concave reflecting mirror M22)
12	-2157.31867	-20.000000	1.560000 (lens L22)
13	-401.62011	-401.565841	
14	163.07026	-20.000000	1.560000 (lens L21)
15	512.54817	-14.261012	
16	296.41597	14.261013	(concave reflecting mirror M21)
17	512.54817	20.000000	1.560000 (lens L21)
18	163.07026	458.436913	
19*	8910.30168	26.990021	1.560000 (lens-L51)
20	-390.02333	1.000000	
21	154.61680	27.437462	1.560000 (lens L31)
22	266.36618	10.838480	
23	578.36195	20.000000	1.560000 (lens L32)
24	156.58391	10.000000	
25	200.15045	20.000000	1.560000 (lens L33)
26*	355.24067	10.000000	
27	199.94207	20.000000	1.560000 (lens L34)
28	565.87990	165.714184	
29	1057.18610	20.000000	1.560000 (lens L35)
30	132.35645	30.141989	
31	-325.89570	21.445301	1.560000 (lens L36)
32	-460.40857	1.000000	
33	180.42036	25.000000	1.560000 (lens L37)
34*	290.73962	15.607903	
35	153.52191	54.725337	1.560000 (lens L38)
36	-377.47953	10.000000	
37	-596.78960	16.523215	1.560000 (lens L39)
38	-292.83030	4.261011	
39	-234.60209	20.000000	1.560000 (lens L310)
40	-317.15396	19.987264	
41*	-596.23286	16.000000	1.560000 (lens L311)
42	-10714.58691	1.000000	
43	201.11330	20.217332	1.560000 (lens L312)
44	561.52434	5.000000	
45	161.81186	41.142108	1.560000 (lens L313)
46*	-311.48442	7.344549	

(continued)

(optical member data)			
surface			
number	r	d	n
47	-177.28368	15.000000	1.560000 (lens L314)
48	-264.46461	1.000000	
49	114.47887	21.221832	1.560000 (lens L315)
50*	284.79460	1.000000	
51	87.32352	28.536749	1.560000 (lens L316)
52	301.26342	4.000000	
53	149.71418	26.671264	1.560000 (lens L317)
54	1921.15947	6.000000	
(wafer surface)			

(aspherical surface data)

surface 8

[0189] $\kappa=0.000000$ $C_4=0.118332 \times 10^{-7}$ $C_6=-0.901477 \times 10^{-13}$ $C_8=0.456579 \times 10^{-18}$ $C_{10}=0.500107 \times 10^{-23}$

surface 19

[0190] $\kappa=0.000000$ $C_4=0.362526 \times 10^{-7}$ $C_6=-0.325425 \times 10^{-12}$ $C_8=-0.715942 \times 10^{-17}$ $C_{10}=0.938233 \times 10^{-22}$

surface 26

[0191] $\kappa=0.000000$ $C_4=0.784516 \times 10^{-7}$ $C_6=0.132181 \times 10^{-11}$ $C_8=0.390546 \times 10^{-16}$ $C_{10}=0.194862 \times 10^{-20}$

surface 34

[0192] $\kappa=0.000000$ $C_4=0.770740 \times 10^{-7}$ $C_6=0.108454 \times 10^{-11}$ $C_8=-0.141384 \times 10^{-16}$ $C_{10}=-0.154327 \times 10^{-20}$

surface 41

[0193] $\kappa=0.000000$ $C_4=-0.111168 \times 10^{-6}$ $C_6=-0.459164 \times 10^{-11}$ $C_8=-0.179391 \times 10^{-15}$ $C_{10}=-0.627753 \times 10^{-20}$

surface 46

[0194] $\kappa=0.000000$ $C_4=-0.806181 \times 10^{-7}$ $C_6=0.979363 \times 10^{-11}$ $C_8=-0.432122 \times 10^{-15}$ $C_{10}=0.353438 \times 10^{-20}$

surface 50

[0195] $\kappa=0.000000$

$C_4=0.171550 \times 10^{-6}$ $C_6=-0.506941 \times 10^{-11}$

5 $C_8=0.172612 \times 10^{-14}$ $C_{10}=-0.907247 \times 10^{-19}$

(conditional expression corresponding values)

[0196]

10

$LAT=-3.9 \times 10^{-7}$

15

$AX=-5.2 \times 10^{-5}$

[0197] FIGS. 18 and 19 show the lateral aberration occurring in the catadioptric system in the seventh embodiment. In the aberration chart, Y represents the image height (mm). As the aberration chart clearly indicates, the chromatic aberration is properly corrected when the wavelength of the exposure light is within a range of $157.6\text{nm} \pm 0.4\text{pm}$ in the seventh embodiment. In addition, the chart confirms that the spherical aberration, the coma aberration, the astigmatism and the distortion are successfully corrected to an extent to which they are practically non-existent and thus, outstanding image forming performance is achieved.

20

(Eighth Embodiment)

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[0198] FIG. 20 shows the lens configuration of the catadioptric system (projection optical system PL) achieved in the eighth embodiment. In the catadioptric system in FIG. 20, the first image forming optical system G1 is constituted with, starting on the reticle side, a biconvex lens L11, a convex reflecting mirror M11 having an almost flat convex surface set facing toward the wafer and a concave reflecting mirror M12 having a concave surface set facing toward the reticle.

30

[0199] The second image forming optical system G2 is constituted with, starting on the reticle side, a concave reflecting mirror M21 having a concave surface set facing toward the wafer, a negative meniscus lens L21 having a convex surface set facing toward the reticle, a negative meniscus lens L22 having a concave surface set facing toward the reticle and a concave reflecting mirror M22 having a concave surface set facing toward the reticle.

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[0200] The third image forming optical system G3 is constituted with, starting on the reticle side, a negative meniscus lens L31 having a concave surface set facing toward the reticle, a negative meniscus lens L32 having a convex surface set facing toward the reticle, a biconvex lens L33, a negative meniscus lens L34 having an aspherical concave surface set facing toward the wafer, a biconcave lens L35, a negative meniscus lens L36 having a concave surface set facing toward the reticle, a positive meniscus lens L37 having an aspherical concave surface set facing toward the wafer, a biconvex lens L38, a positive meniscus lens L39 having a concave surface set facing toward the reticle, a negative meniscus lens L310 having a concave surface set facing toward the reticle, a negative meniscus lens L311 having an aspherical concave surface set facing toward the reticle, a positive meniscus lens L312 having a convex surface set facing toward the reticle, a biconvex lens L313 having an aspherical convex surface set facing toward the wafer, a negative meniscus lens L314 having a concave surface set facing toward the reticle, a positive meniscus lens L315 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L316 having a convex surface set facing toward the reticle and a positive meniscus lens L317 having a convex surface set facing toward the reticle.

40

45

[0201] It is to be noted that a first field lens constituted with, starting on the reticle side, a biconvex lens L41 and a biconvex lens L42 having an aspherical convex surface set facing toward the wafer is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. In addition, a second field lens constituted of a positive meniscus lens L51 having an aspherical concave surface set facing toward the reticle is provided in the optical path between the second image forming optical system G2 and the third image forming optical system G3.

50

[0202] Thus, light from the reticle R enters the concave reflecting mirror M12 via the biconvex lens L11 in the eighth embodiment. After the light having been reflected at the concave reflecting mirror M12 is reflected at the convex reflecting mirror M11, the light forms the first intermediate image of the reticle pattern near the first field lens (L41 and L42).

55

[0203] The light from the first intermediate image is first reflected at the concave reflecting mirror M22 via the negative meniscus lens L22 and then enters the concave reflecting mirror M21 via the negative meniscus lens L22 and the

negative meniscus lens L21. The light reflected at the concave reflecting mirror M21 forms the second intermediate image of the reticle pattern near the second field lens (L51) via the negative meniscus lens L21. The light from the second intermediate image then forms the final image of the reticle pattern onto the wafer W via the lenses L31~L317 constituting the third image forming optical system G3.

[0204] Table (8) below lists data values regarding the catadioptric system achieved in the seventh embodiment. In the main data presented in Table (5), λ represents the central wavelength of the exposure light, β represents the projection magnification factor (the image forming magnification factor of the overall system), NA represents the image-side (wafer-side) numerical aperture, A represents the radius of the image circle IF on the wafer W, i.e., the maximum image height, B represents the maximum object height corresponding to the maximum image height A, LX represents the measurement of the effective exposure area ER along the X direction (the measurement of the long side) and LY represents the measurement of the effective exposure area ER along the Y direction (the measurement of the short side).

[0205] In addition, in the optical member data presented in Table (8), the surface numbers in the first column indicate the order in which the individual surfaces are set, starting from the reticle side, r in the second column indicates the radius of curvature of each surface (the radius of curvature at the vertex in the case of an aspherical surface: mm), d in the third column indicates the distances between the individual surfaces on the axis, i.e., the surface intervals (mm), and n in the fourth column indicates the refractive index corresponding to the central wavelength. It is to be noted that the sign attached to the value representing a surface interval d is switched each time the light is reflected. Accordingly, the sign attached to the values representing the surface intervals d within the optical path extending from the concave reflecting mirror M12 to the concave reflecting mirror M11 and the optical path extending from the concave reflecting mirror M22 to the concave reflecting mirror M21 is negative, and the sign is positive in the remaining optical path. In addition, regardless of the direction along which the light enters, the radius of curvature of a convex surface set facing toward the reticle assumes a positive value and the radius of curvature of a concave surface set facing toward the reticle assumes a negative value. Also, conditional expression corresponding values LAT and AX respectively indicate the magnification factor chromatic aberration coefficient and the on-axis chromatic aberration coefficient in Table (8).

Table (8)

(main data)	
λ =	157.6nm
β =	1/4
NA=	0.845
A=	18mm
B=	72mm
LX=	22mm
LY=	4mm

(optical member data)			
surface			
number	r	d	n
(reticle surface)		64.644427	
1	567.00647	29.774149	1.560000 (lens L11)
2	-305.96356	215.805682	
3	-375.35826	-185.805682	(concave reflecting mirror M12)
4	-1771.14235	215.805682	(convex reflecting mirror M11)
5	1046.06672	43.621058	1.560000 (lens L41)
6	-403.21536	1.000000	
7	421.69510	45.558190	1.560000 (lens L42)
8*	-640.00612	490.635779	
9	-305.40131	10.000000	1.560000 (lens L22)
10	-663.42492	1.000000	
11	-681.00059	-1.000000	(concave reflecting mirror M22)
12	-663.42492	-10.000000	1.560000 (lens L22)

(continued)

(optical member data)			
surface			
number	r	d	n
13	-305.40131	-433.352800	
14	163.68529	-12.344063	1.560000 (lens L21)
15	526.44415	-14.938916	
16	294.23457	14.938916	(concave reflecting mirror M21)
17	526.44415	12.344063	1.560000 (lens L21)
18	163.68529	474.352800	
19*	-742.11875	26.894368	1.560000 (lens L51)
20	-266.21012	1.000000	
21	-400.00000	15.000000	1.560000 (lens L31)
22	-534.63536	1.000000	
23	184.35678	20.000000	1.560000 (lens L32)
24	153.88212	10.000000	
25	168.88100	50.000000	1.560000 (lens L33)
26	-1758.10942	10.000000	
27	235.07511	20.000000	1.560000 (lens L34)
28*	189.46638	163.801245	
29	-2896.25856	20.000000	1.560000 (lens L35)
30	124.65800	29.898504	
31	-242.21131	17.005799	1.560000 (lens L36)
32	-357.22247	1.000000	
33	192.53113	25.000000	1.560000 (lens L37)
34*	412.29894	8.987693	
35	152.52351	53.177839	1.560000 (lens L38)
36	-296.92089	10.000000	
37	-316.87875	15.000000	1.560000 (lens L39)
38	-219.63445	3.105791	
39	-194.61097	20.000000	1.560000 (lens L310)
40	-271.06241	20.333056	
41*	-523.95508	16.000000	1.560000 (lens L311)
42	-1588.24429	1.000000	
43	255.61070	18.833104	1.560000 (lens L312)
44	1097.97464	5.000000	
45	151.14790	42.445707	1.560000 (lens L313)
46*	-331.45182	8.725261	
47	-170.85207	15.000000	1.560000 (lens L314)
48	-227.87568	1.000000	
49	112.98983	21.658527	1.560000 (lens L315)
50*	277.63494	1.000000	
51	85.92800	24.591365	1.560000 (lens L316)
52	235.86682	4.000000	
53	137.24923	31.502456	1.560000 (lens L317)
54	1707.95360	6.000000	
(wafer surface)			

(aspherical surface data)

surface 8

5 [0206] $\kappa=0.000000$
 $C_4=-0.115614 \times 10^{-7}$ $C_6=-0.898054 \times 10^{-13}$
 $C_8=0.586813 \times 10^{-18}$ $C_{10}=0.189867 \times 10^{-23}$

surface 19

10 [0207] $\kappa=0.000000$
 $C_4=0.128999 \times 10^{-7}$ $C_6=-0.445747 \times 10^{-12}$
 $C_8=0.542677 \times 10^{-17}$ $C_{10}=-0.302494 \times 10^{-22}$

surface 28

15 [0208] $\kappa=0.000000$
 $C_4=0.535059 \times 10^{-7}$ $C_6=0.132973 \times 10^{-11}$
 $C_8=0.750691 \times 10^{-16}$ $C_{10}=0.629454 \times 10^{-20}$

surface 34

20 [0209] $\kappa=0.000000$
 $C_4=0.887048 \times 10^{-7}$ $C_6=0.117209 \times 10^{-11}$
 $C_8=-0.416125 \times 10^{-16}$ $C_{10}=-0.382530 \times 10^{-20}$

surface 41

30 [0210] $\kappa=0.000000$
 $C_4=-0.113856 \times 10^{-6}$ $C_6=-0.516355 \times 10^{-11}$
 $C_8=-0.221902 \times 10^{-15}$ $C_{10}=-0.928183 \times 10^{-20}$

surface 46

35 [0211] $\kappa=0.000000$
 $C_4=-0.824280 \times 10^{-7}$ $C_6=0.998838 \times 10^{-11}$
 $C_8=-0.426713 \times 10^{-15}$ $C_{10}=0.170015 \times 10^{-20}$

surface 50

40 [0212] $\kappa=0.000000$
 $C_4=-0.159085 \times 10^{-6}$ $C_6=-0.478787 \times 10^{-11}$
 $C_8=0.166305 \times 10^{-14}$ $C_{10}=-0.824509 \times 10^{-19}$

45 (conditional expression corresponding values)

[0213]

50 LAT= -5.7×10^{-8}

AX= -3.9×10^{-5}

55 [0214] FIGS. 21 and 22 show the lateral aberration occurring in the catadioptric system in the eighth embodiment. In the aberration chart, Y represents the image height (mm). As the aberration chart clearly indicates, the chromatic aberration is properly corrected in the eighth embodiment when the wavelength of the exposure light is within a range of $157.6\text{nm} \pm 0.4\mu\text{m}$, as in the seventh embodiment. In addition, the chart confirms that the spherical aberration, the

coma aberration, the astigmatism and the distortion are successfully corrected to an extent to which they are practically non-existent and thus, outstanding image forming performance is achieved.

(Ninth Embodiment)

[0215] FIG. 23 shows the lens configuration of the catadioptric system (projection optical system PL) achieved in the ninth embodiment. In the catadioptric system in FIG. 23, the first image forming optical system G1 is constituted with, starting on the reticle side, a biconvex lens L11, a convex reflecting mirror M11 having an almost flat convex surface set facing toward the wafer, a negative meniscus lens L12 having a concave surface set facing toward the reticle and a concave reflecting mirror M12 having a concave surface set facing toward the reticle.

[0216] The second image forming optical system G2 is constituted with, starting on the reticle side, a concave reflecting mirror M21 having a concave surface set facing toward the wafer, a negative meniscus lens L21 having a convex surface set facing toward the reticle and a concave reflecting mirror M22 having an almost flat concave surface set facing toward the reticle.

[0217] The third image forming optical system G3 is constituted with, starting on the reticle side, a biconvex lens L31, a biconcave lens L32 having an aspherical concave surface set facing toward the wafer, a positive meniscus lens L33 having a convex surface set facing toward the reticle, a biconcave lens L34, a negative meniscus lens L35 having a convex surface set facing toward the reticle, a positive meniscus lens L36 having an aspherical concave surface set facing toward the wafer, a biconvex lens L37, a positive meniscus lens L38 having a concave surface set facing toward the reticle, a biconcave lens L39 having an aspherical concave surface set facing toward the reticle, a biconvex lens L310, a biconvex lens L311 having an aspherical convex surface set facing toward the wafer, a negative meniscus lens L312 having a concave surface set facing toward the reticle, a positive meniscus lens L313 having an aspherical a concave surface set facing toward the wafer, a positive meniscus lens L314 having a convex surface set facing toward the reticle and a positive meniscus lens L315 having a convex surface set facing toward the reticle.

[0218] It is to be noted that a first field lens constituted with, starting on the reticle side, a biconvex lens L41 and a biconvex lens L42 having an aspherical convex surface set facing toward the wafer is provided in the optical path between the first image forming optical system G1 and the second image forming optical system G2. In addition, a second field lens constituted of a positive meniscus lens L51 having an aspherical concave surface set facing toward the reticle and a positive meniscus lens L52 having a concave surface set facing toward the reticle is provided in the optical path between the second image forming optical system G2 and the third image forming optical system G3.

[0219] Thus, light from the reticle R enters the concave reflecting mirror M12 via the biconvex lens L1 and the negative meniscus lens L12 in the ninth embodiment. After the light having been reflected at the concave reflecting mirror M12 is reflected at the convex reflecting mirror M11, the light forms the first intermediate image of the reticle pattern near the first field lens (L41 and L42).

[0220] The light from the first intermediate image is first reflected at the concave reflecting mirror M22 and then enters the concave reflecting mirror M21 via the negative meniscus lens L21. The light reflected at the concave reflecting mirror M21 forms the second intermediate image of the reticle pattern near the second field lens (L51 and L52) via the negative meniscus lens L21. The light from the second intermediate image forms the final image of the reticle pattern onto the wafer W via the lenses L31 ~ L315 constituting the third image forming optical system G3.

[0221] Table (9) below lists data values regarding the catadioptric system achieved in the ninth embodiment. In the main data presented in Table (5), λ represents the central wavelength of the exposure light, β represents the projection magnification factor (the image forming magnification factor of the overall system), NA represents the image-side (wafer-side) numerical aperture, A represents the radius of the image circle IF on the wafer W, i.e., the maximum image height, B represents the maximum object height corresponding to the maximum image height A, LX represents the measurement of the effective exposure area ER along the X direction (the measurement of the long side) and LY represents the measurement of the effective exposure area ER along the Y direction (the measurement of the short side).

[0222] In addition, in the optical member data presented in Table (9), the surface numbers in the first column indicate the order in which the individual surfaces are set, starting from the reticle side, r in the second column indicates the radius of curvature of each surface (the radius of curvature at the vertex in the case of an aspherical surface: mm), d in the third column indicates the distances between the individual surfaces on the axis, i.e., the surface intervals (mm), and n in the fourth column indicates the refractive index corresponding to the central wavelength. It is to be noted that the sign attached to the value representing a surface interval d is switched each time the light is reflected. Accordingly, the sign attached to the values representing the surface intervals d within the optical path extending from the concave reflecting mirror M12 to the concave reflecting mirror M11 and the optical path extending from the concave reflecting mirror M22 to the concave reflecting mirror M21 is negative, and the sign is positive in the remaining optical path. In addition, regardless of the direction along which the light enters, the radius of curvature of a convex surface set facing toward the reticle assumes a positive value and the radius of curvature of a concave surface set facing toward the

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reticle assumes a negative value. Also, conditional expression corresponding values LAT and AX respectively indicate the magnification factor chromatic aberration coefficient and the on-axis chromatic aberration coefficient in Table (9).

Table (9)

(main data)	
$\lambda =$	157.6nm
$\beta =$	1/4
NA=	0.845
A=	18mm
B=	72mm
LX=	22mm
LY=	4mm

(optical member data)			
surface			
number	r	d	n
(reticle surface)		60.000000	
1	991.47248	28.195143	1.560000 (lens L11)
2	-267.50588	192.866330	
3	-212.01226	15.000000	1.560000 (lens L12)
4	-359.05656	7.438380	
5	-274.13902	-7.438380	(concave reflecting mirror M12)
6	-359.05656	-15.000000	1.560000 (lens L12)
7	-212.01226	-162.866330	
8	-2397.49986	215.304710	(convex reflecting mirror M11)
9	480.51853	46.865206	1.560000 (lens L41)
10	-546.66851	1.000000	
11	379.33588	44.717026	1.560000 (lens L42)
12*	-630.25132	422.571113	
13	-1860.74365	-369.081141	(concave reflecting mirror M22)
14	136.07113	-15.000000	1.560000 (lens L21)
15	388.51075	-8.489972	
16	269.57337	8.489972	(concave reflecting mirror M21)
17	388.51075	15.000000	1.560000 (lens L21)
18	136.07113	399.081141	
19*	-368.26543	30.000000	1.560000 (lens L51)
20	-253.70093	1.000000	
21	-2467.73840	30.000000	1.560000 (lens L52)
22	-400.60099	68.350972	
23	171.28983	44.279149	1.560000 (lens L31)
24	-3312.88121	44.770000	
25	-448.65736	20.000000	1.560000 (lens L32)
26*	168.02309	10.000000	
27	170.42305	25.208415	1.560000 (lens L33)
28	769.81302	99.804041	
29	-1652.36364	20.000000	1.560000 (lens L34)
30	132.90519	15.026016	
31	530.98620	70.000000	1.560000 (lens L35)
32	452.64324	1.000000	
33	177.34168	25.000000	1.560000 (lens L36)

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(continued)

(optical member data)			
surface			
number	r	d	n
34*	415.66350	1.000000	
35	138.37477	47.565338	1.560000 (lens L37)
36	-654.96909	10.000000	
37	-2112.93849	34.994222	1.560000 (lens L38)
38	-411.84982	16.215559	
39*	-4467.59569	16.000000	1.560000 (lens L39)
40	568.03899	1.000000	
41	359.65731	20.527531	1.560000 (lens L310)
42	-5233.89502	5.000000	
43	146.19360	42.262782	1.560000 (lens L311)
44*	-225.18468	5.392886	
45	-155.97378	15.000000	1.560000 (lens L312)
46	-257.64593	1.000000	
47	87.50795	24.651827	1.560000 (lens L313)
48*	221.10625	1.000000	
49	83.17065	29.222819	1.560000 (lens L314)
50	263.21163	4.000000	
51	149.89321	16.010949	1.560000 (lens L315)
52	1461.12239	6.000000	
(wafer surface)			

(aspherical surface data)

surface 12

[0223] $\kappa=0.000000$

$C_4=0.269991 \times 10^{-7}$ $C_6=-0.510706 \times 10^{-12}$
 $C_8=0.110177 \times 10^{-16}$ $C_{10}=-0.123713 \times 10^{-21}$

surface 19

[0224] $\kappa=0.000000$

$C_4=0.121430 \times 10^{-7}$ $C_6=-0.146728 \times 10^{-12}$
 $C_8=0.126272 \times 10^{-18}$ $C_{10}=0.894134 \times 10^{-23}$

surface 26

[0225] $\kappa=0.000000$

$C_4=0.691903 \times 10^{-7}$ $C_6=0.102075 \times 10^{-11}$
 $C_8=0.983473 \times 10^{-16}$ $C_{10}=0.117306 \times 10^{-20}$

surface 34

[0226] $\kappa=0.000000$

$C_4=0.993275 \times 10^{-7}$ $C_6=0.240380 \times 10^{-11}$
 $C_8=0.301051 \times 10^{-16}$ $C_{10}=-0.215154 \times 10^{-20}$

surface 39

[0227] $\kappa=0.000000$

$C_4=-0.140256 \times 10^{-6}$ $C_6=-0.785178 \times 10^{-11}$

5 $C_8=-0.323968 \times 10^{-15}$ $C_{10}=-0.150679 \times 10^{-19}$

surface 44

[0228] $\kappa=0.000000$

10 $C_4=-0.100300 \times 10^{-6}$ $C_6=0.114834 \times 10^{-10}$

$C_8=-0.384285 \times 10^{-15}$ $C_{10}=-0.139887 \times 10^{-20}$

surface 48

15 [0229] $\kappa=0.000000$

$C_4=0.200382 \times 10^{-6}$ $C_6=-0.794777 \times 10^{-11}$

$C_8=0.361073 \times 10^{-14}$ $C_{10}=-0.138717 \times 10^{-18}$

(conditional expression corresponding values)

20

[0230]

LAT= $+9.7 \times 10^{-7}$

25

AX= -4.5×10^{-5}

[0231] FIGS. 24 and 25 show the lateral aberration occurring in the catadioptric system in the ninth embodiment. In the aberration chart, Y represents the image height (mm). As the aberration chart clearly indicates, the chromatic aberration is properly corrected in the ninth embodiment when the wavelength of the exposure light is within a range of $157.6\text{nm} \pm 0.4\mu\text{m}$, as in the seventh embodiment. In addition, the chart confirms that the spherical aberration, the coma aberration, the astigmatism and the distortion are successfully corrected to an extent to which they are practically non-existent and thus, outstanding image forming performance is achieved.

[0232] As described above, an image-side NA of 0.7 is assured in conjunction with F_2 laser light with a central wavelength of 157.6nm, and an image circle with a 17mm radius in which the various aberrations including the chromatic aberration are fully corrected is assured on the wafer W in the first embodiment. In the second embodiment, an image-side NA of 0.8 is assured in conjunction with F_2 laser light with a central wavelength of 157.6nm, and an image circle with a 21mm radius in which the various aberrations including the chromatic aberration are fully corrected is assured on the wafer W. In addition, in the third, fifth and sixth embodiments, an image-side NA of 0.8 is assured in conjunction with F_2 laser light with a central wavelength of 157.6nm and an image circle with an 18mm radius in which the various aberrations including the chromatic aberration are fully corrected is assured on the wafer W. In the fourth embodiment, an image-side NA of 0.6 is assured in conjunction with F_2 laser light with a central wavelength of 157.6nm, and an image circle with a 21mm radius in which the various aberrations including the chromatic aberration are fully corrected is assured on the wafer W. Furthermore, in the seventh ~ ninth embodiments, an image-side NA of 0.845 is assured in conjunction with F_2 laser light with a central wavelength of 157.6nm, and an image circle with a 18mm radius with the various aberrations including the chromatic aberration are fully corrected is assured on the wafer W.

[0233] As a result, a high resolution with 0.1 μm or less can be achieved while assuring a sufficiently large rectangular effective exposure area measuring 22mm x 5mm in the first and second embodiments and assuring a sufficiently large rectangular effective exposure area measuring 22mm x approximately 6mm in the fourth embodiment. The pattern at the reticle R can be transferred with a high degree of accuracy through scanning exposure onto individual exposure areas on the wafer W each achieving, for instance, a 22mm x 33mm size. In addition, a high resolution of 0.1 μm or less can be achieved while assuring a sufficiently large rectangular effective exposure area measuring 20mm x 5mm in the third and fifth embodiments. In these embodiments, the pattern at the reticle R can be transferred with a high degree of accuracy through scanning exposure onto individual exposure areas on the wafer W each achieving, for instance, a 20mm x 33mm size. In the sixth embodiment, a high resolution of 0.1 μm or less can be achieved while assuring a sufficiently large circular arc-shaped effective exposure area measuring 20mm x 3mm. In the sixth embodiment, the pattern at the reticle R can be transferred with a high degree of accuracy through scanning exposure onto

individual exposure areas on the wafer W each achieving, for instance, 20mm x 33mm size. Furthermore, a high resolution of 0.1 μ m or less can be achieved while assuring a sufficiently large rectangular effective exposure area measuring 22mm x 4mm in the seventh ~ ninth embodiments. In these embodiments, the pattern at the reticle R can be transferred with a high degree of accuracy through scanning exposure onto individual exposure areas on the wafer W each achieving, for instance, a 22mm x 33mm size. It is to be noted that a sufficiently long wafer-side working distance measuring approximately 6mm can be assured in all of the embodiments described above. Moreover, a sufficiently long mask-side working distance measuring approximately 60mm ~ 115mm can be assured in the embodiments.

[0234] In addition, in the first embodiment, the lens L41 has the largest effective diameter at approximately 240mm and the effective diameters of the other lenses are mostly equal to or smaller than 200mm. In the second embodiment, the concave reflecting mirror M21 has the largest effective diameter among the reflecting mirrors at approximately 250mm and the lens L41 has the largest effective diameter of approximately 268mm among the lenses. The effective diameters of the other lenses are mostly equal to or smaller than 200mm. In addition, in the third embodiment, the lens L41 has the largest effective diameter of approximately 260mm and the effective diameters of the other lenses are mostly equal to or smaller than 200mm. In the fourth embodiment, the lens L11 has the largest effective diameter of approximately 235mm and the effective diameters of the other lenses are mostly equal to or smaller than 200mm. In the fifth embodiment, the lens L41 has the largest effective diameter of approximately 250mm and the effective diameters of the other lenses are mostly equal to or smaller than 200mm. Furthermore, in the sixth embodiment, the lens L41 has the largest effective diameter of approximately 250mm and the effective diameters of the other lenses are mostly equal to or smaller than 200mm. In the seventh embodiment, the concave reflecting mirror M21 has the largest effective diameter among the reflecting mirrors at approximately 260mm and the lenses L41 and L42 have a largest effective diameter of approximately 280mm. The effective diameters of the other lenses are mostly equal to or smaller than 190mm. In the eighth embodiment, the concave reflecting mirror M21 has the largest effective diameter among the reflecting mirrors at approximately 260mm and the lenses L41 and L42 have the largest effective diameter of approximately 277mm. The effective diameters of the other lenses are mostly equal to or smaller than 179mm. In the ninth embodiment, the concave reflecting mirror M21 has the largest effective diameter among the reflecting mirrors at approximately 217mm and the lenses L41 and L42 have a largest effective diameter of approximately 280mm. The effective diameters of the other lenses are mostly equal to or smaller than 176mm. Thus, the sizes of the concave reflecting mirrors and the lenses are kept down to achieve miniaturization of the optical systems in all the embodiments.

[0235] Moreover, the number of lenses used to form the image three times in the projection optical system achieved in each of the embodiments described above is extremely small (16 lenses are used in the first and second embodiments, 18 lenses are used in the third and fourth embodiments, 21 lenses are used in the fifth and sixth embodiments, 23 lenses are used in the seventh and eighth embodiments and 21 lenses are used in the ninth embodiment). Since an effective reflection reducing coating cannot be formed in an optical system that uses F₂ laser light, the extent of light loss occurring at the lens surfaces tends to be significant if a great number of lenses is employed in the optical system. From this viewpoint, the number of lenses is minimized to reduce the quantity of light loss at the lens surfaces in each of the embodiments described above. In addition, the number of aspherical surfaces used in each of the embodiments is extremely small (12 aspherical surfaces in the first and second embodiments, 14 aspherical surfaces in the third and fourth embodiments, 7 aspherical surfaces in the fifth and sixth the embodiments and 7 aspherical surfaces in the seventh ~ ninth embodiments), as well.

[0236] In the seventh ~ ninth embodiments, two reflecting mirrors among the two reflecting mirrors M11 and M12 included in the first image forming optical system G1 and the two reflecting mirrors M21 and M22 included in the second image forming optical system G2 are each immediately preceded by a negative lens. More specifically, the negative meniscus lens L21 is set to immediately precede the concave reflecting mirror M21 and the negative meniscus lens L22 is set to immediately precede the concave reflecting mirror M22 in the seventh and eighth embodiments. In the ninth embodiment, on the other hand, the negative meniscus lens L12 is set to immediately precede the concave reflecting mirror M12 and the negative meniscus lens L21 is set to immediately precede the concave reflecting mirror M21. Thus, in the seventh ~ ninth embodiments, in which a negative lens is set to immediately precede each of the two reflecting mirrors as described above, the magnification factor chromatic aberration and the on-axis chromatic aberration are corrected.

[0237] To explain this point in reference to the conditional expression corresponding values presented in Tables (7) ~ (9), the magnification factor chromatic aberration coefficient LAT and the on-axis chromatic aberration coefficient AX respectively satisfy the following conditional expressions (1) and (2) in the seventh ~ ninth embodiments.

$$|LAT| < 5 \times 10^{-6}$$

(1)

$$|AXI| < 2 \times 10^{-4}$$

(2)

[0238] It is to be noted that the magnification factor chromatic aberration and the on-axis chromatic aberration can be corrected even better by setting the upper limit for the conditional expression (1) to 2.5×10^{-6} and the upper limit for the conditional expression (2) to 1.0×10^{-4} .

[0239] With the exposure apparatus achieved in any of the embodiments described above, micro devices (semiconductor elements, image-capturing elements, liquid crystal display elements, thin film magnetic heads, etc.) can be manufactured by illuminating the reticle (mask) with the illumination optical system (an illumination step) and then scanning the transfer pattern at the reticle onto a photosensitive substrate with the projection optical system (an exposure step). The following is an explanation of an example of a method that maybe adopted to manufacture a micro device, e.g., a semiconductor device, by forming a specific circuit pattern onto a photosensitive substrate such as a wafer with the exposure apparatus achieved in one of the embodiments given in reference to the flowchart presented in FIG. 26.

[0240] First, a metal film is vapor-deposited onto a single lot of wafers in step 301 in FIG. 26. In the following step 302, a photoresist is applied onto the metal film on the single lot of wafers. Then in step 303, an image of the pattern on the reticle is sequentially exposed and transferred onto individual shot areas on the single lot of wafers with the projection optical system achieved in one of the embodiments. In step 304, the photoresist on the single lot of wafers is developed and then, in step 305, the single lot of wafers are etched by using the resist pattern as a mask, thereby forming a circuit pattern corresponding to the pattern at the reticle in the individual shot areas of each wafer. Subsequently, a circuit pattern in an upper layer is formed and the like and thus, a device such as a semiconductor element is manufactured. By adopting the semiconductor device manufacturing method described above, a high throughput is achieved in manufacturing semiconductor devices having extremely fine circuit patterns.

[0241] In addition, the exposure apparatus in any of the embodiments can be employed to manufacture micro devices, e.g., liquid crystal display elements, by forming a specific pattern (a circuit pattern, an electrode pattern, etc.) onto a plate (a glass substrate). The following is an explanation of an example of a manufacturing method that may be adopted, given in reference to the flowchart presented in FIG. 27. In a pattern formation process 401 in FIG. 27, a photolithography process is executed to transfer and expose the pattern at the reticle onto a photosensitive substrate (such as a glass substrate having resist applied thereto) with the exposure apparatus achieved in one of the embodiments. Through this photolithography process, a specific pattern which includes numerous electrodes and the like is formed on the photosensitive substrate. Subsequently, the substrate having undergone the exposure process further undergoes various processes such as a development process, an etching process and a reticle removal process and, as a result, a specific pattern is formed on the substrate. Then, the operation shifts to the next step, i.e., a color filter formation process 402.

[0242] In the color filter formation process 402, color filters are formed by arraying numerous dot sets each constituted of three dots corresponding to R (red), G (green) and B (blue) in a matrix pattern or by arraying a plurality of stripe filter sets each constituted of three stripes corresponding to R, G and B along the direction in which the horizontal scanning line extends. Following the color filters formation process 402, a cell assembly process 403 is executed. In the cell assembly process 403, a liquid crystal panel (liquid crystal cell) is assembled by using the substrate with the specific pattern obtained through the pattern formation process 401 and the color filters obtained through the color filter formation process 402. In the cell assembly process 403, a liquid crystal panel (liquid crystal cell) is manufactured by, for instance, injecting liquid crystal between the substrate with the specific pattern obtained through the pattern formation process 401 and the color filters obtained through the color filter formation process 402.

[0243] Subsequently, various parts such as an electric circuit and a backlighting system for enabling the assembled liquid crystal panel (liquid crystal cell) to perform a display operation are mounted to obtain a finished product, i.e., a liquid crystal display element, in a module assembly process 404. By adopting the liquid crystal display element manufacturing method described above, a high throughput is achieved in manufacturing liquid crystal display elements with extremely fine circuit patterns.

[0244] It is to be noted that while F_2 laser capable of supplying light at a wavelength of 157.6nm is used in the embodiments described above, the present invention is not limited to this example, and it may be adopted in conjunction with a KrF excimer laser which supplies light with a 248nm wavelength, an ArF excimer laser that supplies light with a 193nm wavelength or an Ar₂ laser that supplies light with a 126nm wavelength, for instance.

[0245] In addition, while the present invention is adopted in a projection optical system of a scanning exposure type exposure apparatus in the embodiments described above, the present invention is not limited to this example and it may be adopted in a projection optical system of a batch exposure type exposure apparatus (stepper type) or any image forming optical system that is not a projection optical system in an exposure apparatus as well.

Claims

1. A catadioptric system comprising:

5 a first image forming optical system that includes at least two reflecting mirrors and forms a first intermediate image of a first plane with light originating from the first plane;
a second image forming optical system that includes at least two reflecting mirrors and forms a second intermediate image of the first plane with light having traveled via the first image forming optical system; and
10 a refractive type of third image forming optical system that forms a final image of the first plane onto a second plane with light having traveled via the second image forming optical system, wherein:

optical members constituting the first image forming optical system, the second image forming optical system and the third image forming optical system are all disposed along a single linear optical axis.

15 2. A catadioptric system according to claim 1, wherein:

a field lens is provided in an optical path between the first image forming optical system and the second image forming optical system.

20 3. A catadioptric system according to claim 1 or 2, wherein:

the first image forming optical system includes the two reflecting mirrors and at least one lens element.

25 4. A catadioptric system according to claim 2 or 3, wherein:

a combined optical system comprising the first image forming optical system and the field lens achieves telecentricity toward the first plane and toward the second plane.

30 5. A catadioptric system according to any one of claims 1 through 4, wherein:

the first image forming optical system includes at least one negative lens element provided in an optical path between the two reflecting mirrors.

35 6. A catadioptric system according to any one of claims 1 through 5, wherein:

the second image forming optical system includes at least one negative lens element provided in an optical path between the two reflecting mirrors.

40 7. A catadioptric system comprising:

a plurality of optical members that form two intermediate images of a first plane in an optical path between the first plane and a second plane and form a third intermediate image of the first plane onto the second plane as a final image, wherein:

45 the plurality of optical members are disposed along a single linear optical axis.

8. A catadioptric system according to claim 7, wherein:

50 the intermediate images are formed at positions off the optical axis.

9. A catadioptric system comprising:

a plurality of reflecting mirrors disposed along a single linear optical axis, wherein:

55 an image over a rectangular area away from the optical axis on a first plane is formed onto a second plane.

10. A catadioptric system according to claim 9, further comprising:

a field stop that defines an image area formed at the catadioptric system; and
an aperture stop that defines a numerical aperture of the catadioptric system.

11. A catadioptric system comprising:

a first image forming optical system that includes at least a first reflecting mirror and a second reflecting mirror and forms a first intermediate image of a first plane with light originating from the first plane;
a second image forming optical system that includes at least a third reflecting mirror and a fourth reflecting mirror and forms a second intermediate image of the first plane with light having traveled via the first image forming optical system; and
a refractive type of third image forming optical system that forms a final image of the first plane onto a second plane with light having traveled via the second image forming optical system, wherein:

optical members constituting the first image forming optical system, the second image forming optical system and the third image forming optical system are all disposed along a single linear optical axis; and
at least one negative lens is provided immediately before each of two reflecting mirrors among the first reflecting mirror, the second reflecting mirror, the third reflecting mirror and the fourth reflecting mirrors on a reflecting surface side.

12. A catadioptric system according to claim 11, wherein:

a magnification factor chromatic aberration is corrected by providing at least one negative lens immediately before each of the two reflecting mirrors on the reflecting surface side; and
a magnification factor chromatic aberration coefficient LAT satisfies a condition expressed as

$$|LAT| < 5 \times 10^{-6}.$$

13. A catadioptric system according to claim 11 or 12, wherein:

an on-axis chromatic aberration is corrected by providing at least one negative lens immediately before each of the two reflecting mirrors on the reflecting surface side; and
an on-axis chromatic aberration coefficient AX satisfies a condition expressed as

$$|AX| < 2 \times 10^{-4}.$$

14. An exposure apparatus comprising:

an illumination system that illuminates a mask; and
a projection optical system that forms an image of a pattern formed at the mask onto a photosensitive substrate,

wherein:

the projection optical systems comprises a catadioptric system according to any one of claims 1 through 13; and
the mask corresponds to the first plane in the catadioptric system and the photosensitive substrate corresponds to the second plane in the catadioptric system.

15. An exposure apparatus according to claim 14, further comprising:

a drive system that causes the mask and the photosensitive substrate to move relative to the catadioptric system in order to scan the pattern of the mask to expose onto the photosensitive substrate.

16. A micro device manufacturing method, comprising:

an exposure step in which the pattern of the mask is exposed onto the photosensitive substrate with an exposure apparatus according to claim 14 or 15; and

a development step in which the photosensitive substrate having undergone the exposure step is developed.

Amended claims under Art. 19.1 PCT

5

1. (amended)

A catadioptric system comprising:

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a first image forming optical system including, at least, a first reflecting mirror and a second reflecting mirror with the first reflecting mirror set further toward a first plane, in which light from the first plane travels around outside of the first reflecting mirror and enters the second reflecting mirror, light reflected at the second reflecting mirror enters the first reflecting mirror and, after light is reflected at the first reflecting mirror, light travels around outside of the second reflecting mirror so as to form a first intermediate image of the first plane;

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a second image forming optical system including, at least, a third reflecting mirror and a fourth reflecting mirror with the third reflecting mirror set further toward the first plane, in which light having traveled via the first image forming optical system travels around outside of the third reflecting mirror and enters the fourth reflecting mirror, light reflected at the fourth reflecting mirror enters the third reflecting mirror and, after light is reflected at the third reflecting mirror, light travels around outside of the fourth reflecting mirror so as to form a second intermediate image of the first plane; and

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a refractive type of third image forming optical system that forms a final image of the first plane onto a second plane with light having traveled via the second image forming optical system, wherein:

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optical members constituting the first image forming optical system, the second image forming optical system and the third image forming optical system are all disposed along a single linear optical axis.

2. A catadioptric system according to claim 2, wherein:

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a field lens is provided in an optical path between the first image forming optical system and the second image forming optical system.

3. A catadioptric system according to claim 1 or 2, wherein:

the first image forming optical system includes the two reflecting mirrors and at least one lens element.

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4. A catadioptric system according to claim 2 or 3, wherein:

a combined optical system comprising the first image forming optical system and the field lens achieves telecentricity toward the first plane and toward the second plane.

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5. A catadioptric system according to any one of claims 1 through 4, wherein:

the first image forming optical system includes at least one negative lens element provided in an optical path between the two reflecting mirrors.

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6. A catadioptric system according to any one of claims 1 through 5, wherein:

the second image forming optical system includes at least one negative lens element provided in an optical path between the two reflecting mirrors.

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7. (amended)

A catadioptric system according to any one of claims 1 through 6, wherein:

the first image forming optical system and the second image forming optical system are provided so as to achieve substantial symmetry relative to a position at which the first intermediate image is formed.

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9. (amended)

A catadioptric system according to any one of claims 1 through 8, wherein:

an image over a rectangular or circular arch-shaped area off the optical axis on the first plane is formed at the second plane.

10. (amended)

5 A catadioptric system according to any one of claims 1 through 9, further comprising:

a field stop that defines an image area formed at the catadioptric system; and
an aperture stop that defines a numerical aperture of the catadioptric system.

10 11. (amended)

A catadioptric system comprising:

a first image forming optical system including, at least, a first reflecting mirror and a second reflecting mirror with the first reflecting mirror set further toward a first plane, in which light from the first plane travels around outside of the first reflecting mirror and enters the second reflecting mirror, light reflected at the second reflecting mirror enters the first reflecting mirror and, after light is reflected at the first reflecting mirror, light travels around outside of the second reflecting mirror so as to form a first intermediate image of the first plane;

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a second image forming optical system including, at least, a third reflecting mirror and a fourth reflecting mirror with the third reflecting mirror set further toward the first plane, in which light having traveled via the first image forming optical system travels around outside of the third reflecting mirror and enters the fourth reflecting mirror, light reflected at the fourth reflecting mirror enters the third reflecting mirror and, after light is reflected at the third reflecting mirror, light travels around outside of the fourth reflecting mirror so as to form a second intermediate image of the first plane; and

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a refractive type of third image forming optical system that forms a final image of the first plane onto a second plane with light having traveled via the second image forming optical system, wherein:

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optical members constituting the first image forming optical system, the second image forming optical system and the third image forming optical system are all disposed along a single linear optical axis; and at least one negative lens is provided immediately before each of two reflecting mirrors among the first reflecting mirror, the second reflecting mirror, the third reflecting mirror and the fourth reflecting mirrors are each immediately preceded by, at least, one negative lens on a reflecting surface side.

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12. A catadioptric system according to claim 11, wherein:

a magnification factor chromatic aberration is corrected by providing at least one negative lens immediately before each of the two reflecting mirrors on the reflecting surface side; and
a magnification factor chromatic aberration coefficient LAT satisfies a condition expressed as

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$$|LAT| < 5 \times 10^{-6}.$$

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13. A catadioptric system according to claim 11 or 12, wherein:

an on-axis chromatic aberration is corrected by providing at least one negative lens immediately before each of the two reflecting mirrors on the reflecting surface side; and
an on-axis chromatic aberration coefficient AX satisfies a condition expressed as

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$$|AX| < 2 \times 10^{-4}.$$

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14. An exposure apparatus comprising:

an illumination system that illuminates a mask; and
a projection optical system that forms an image of a pattern formed at the mask onto a photosensitive substrate,

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wherein:

the projection optical systems comprises a catadioptric system according to any one of claims 1 through 13; and

the mask corresponds to the first plane in the catadioptric system and the photosensitive substrate corresponds to the second plane in the catadioptric system.

15. An exposure apparatus according to claim 14, further comprising:

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a drive system that causes the mask and the photosensitive substrate to move relative to the catadioptric system in order to scan the pattern of the mask to expose onto the photosensitive substrate.

16. A micro device manufacturing method, comprising:

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an exposure step in which the pattern of the mask is exposed onto the photosensitive substrate with an exposure apparatus according to claim 14 or 15; and

a development step in which the photosensitive substrate having undergone the exposure step is developed.

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FIG. 1

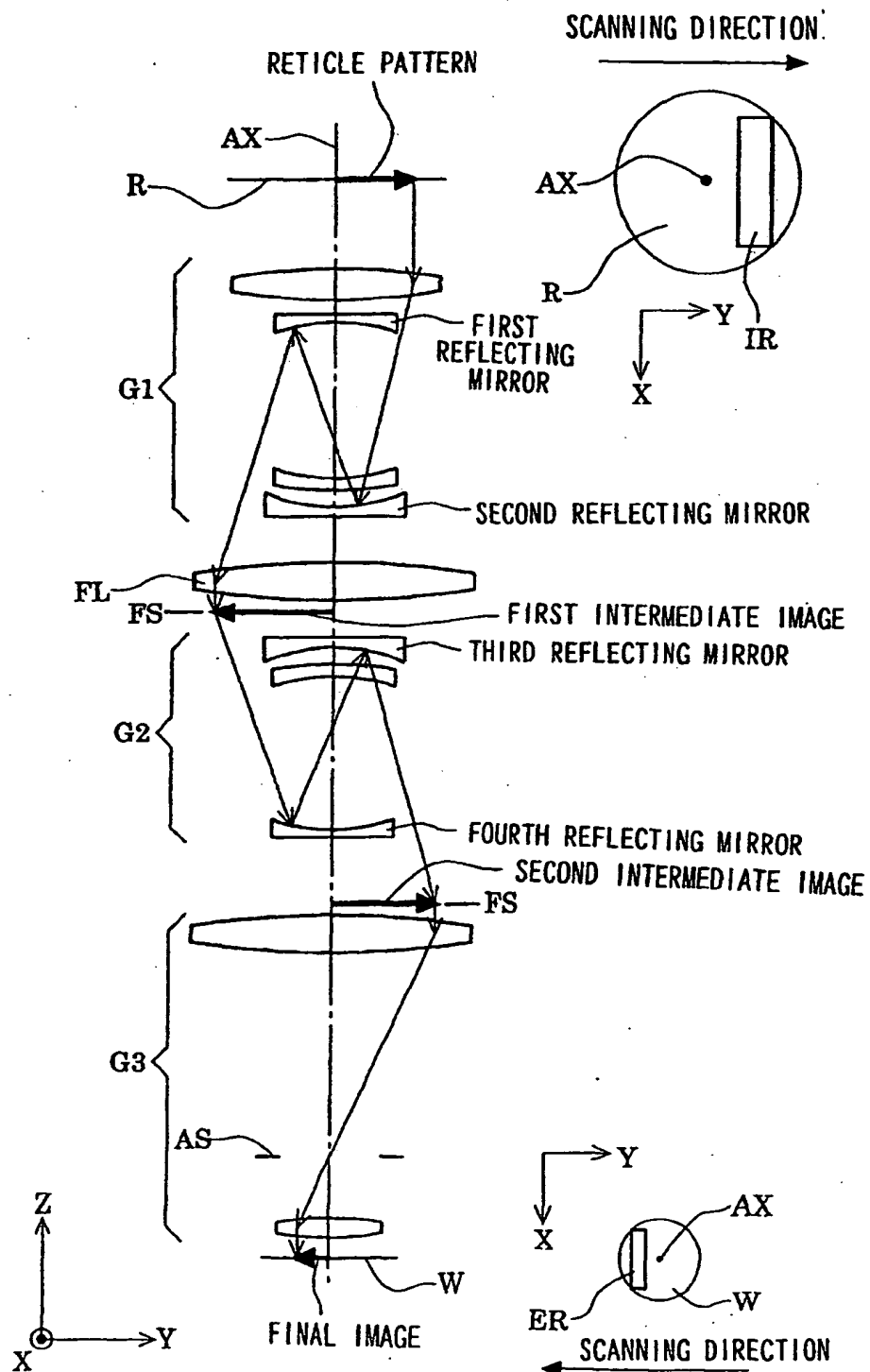


FIG. 2

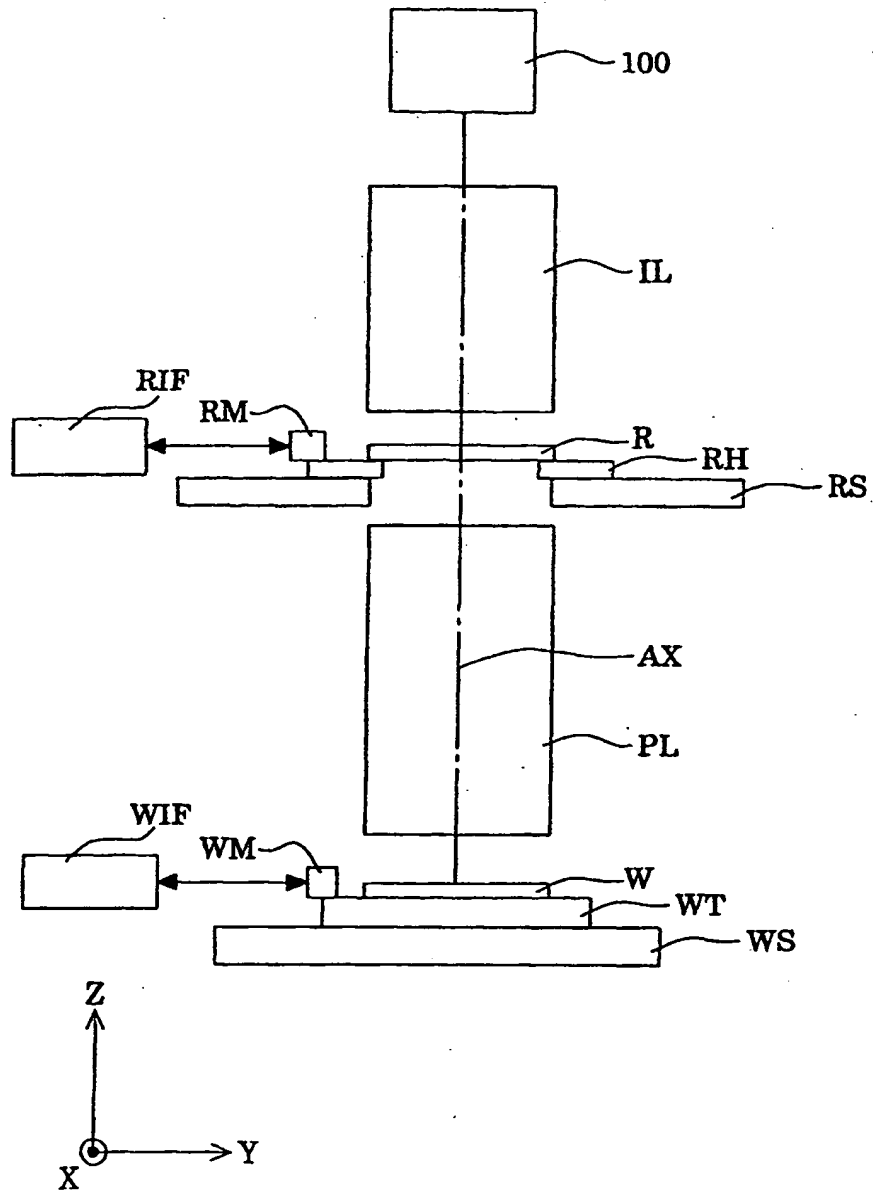


FIG. 3

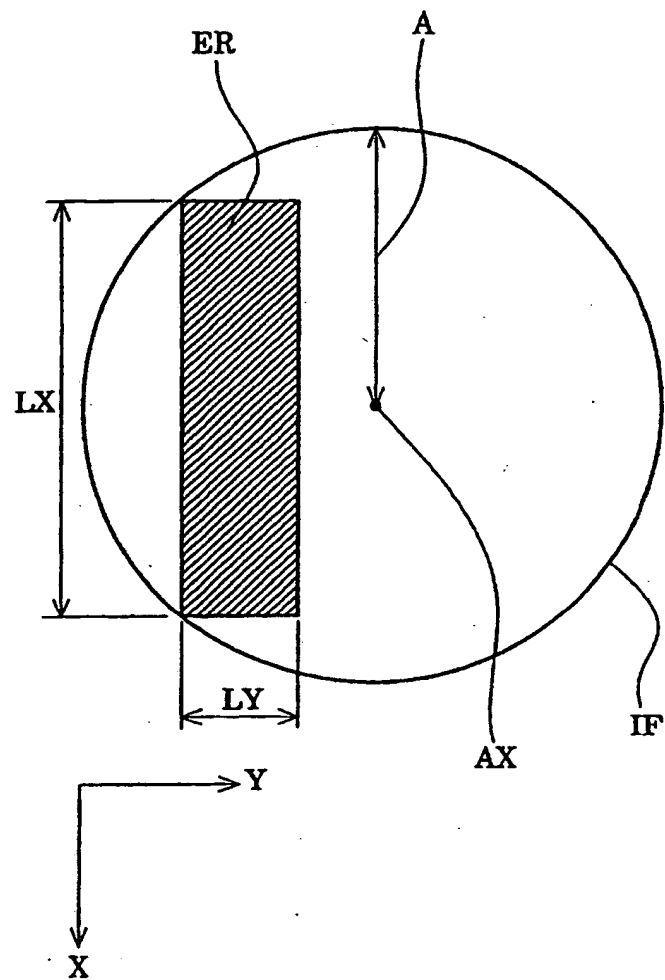


FIG. 4

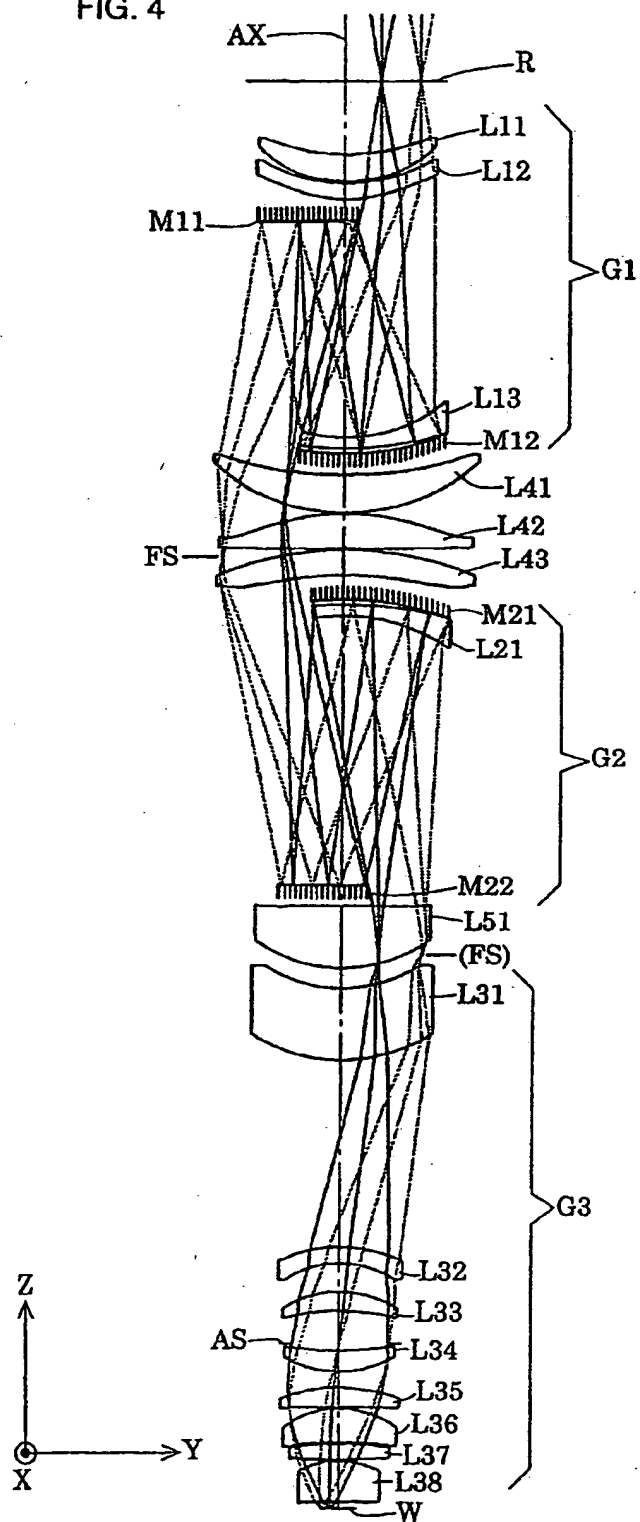


FIG. 5

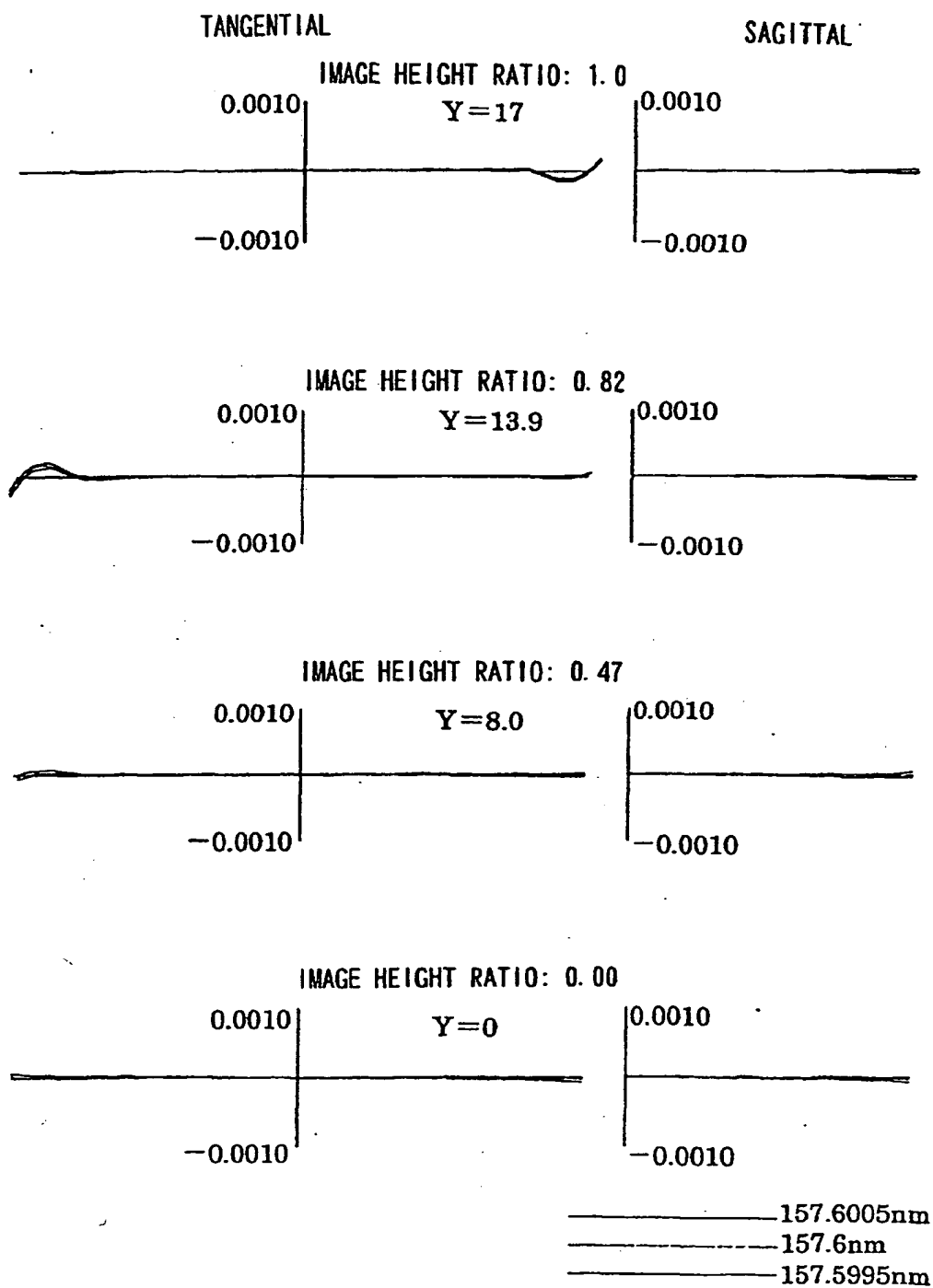


FIG. 6

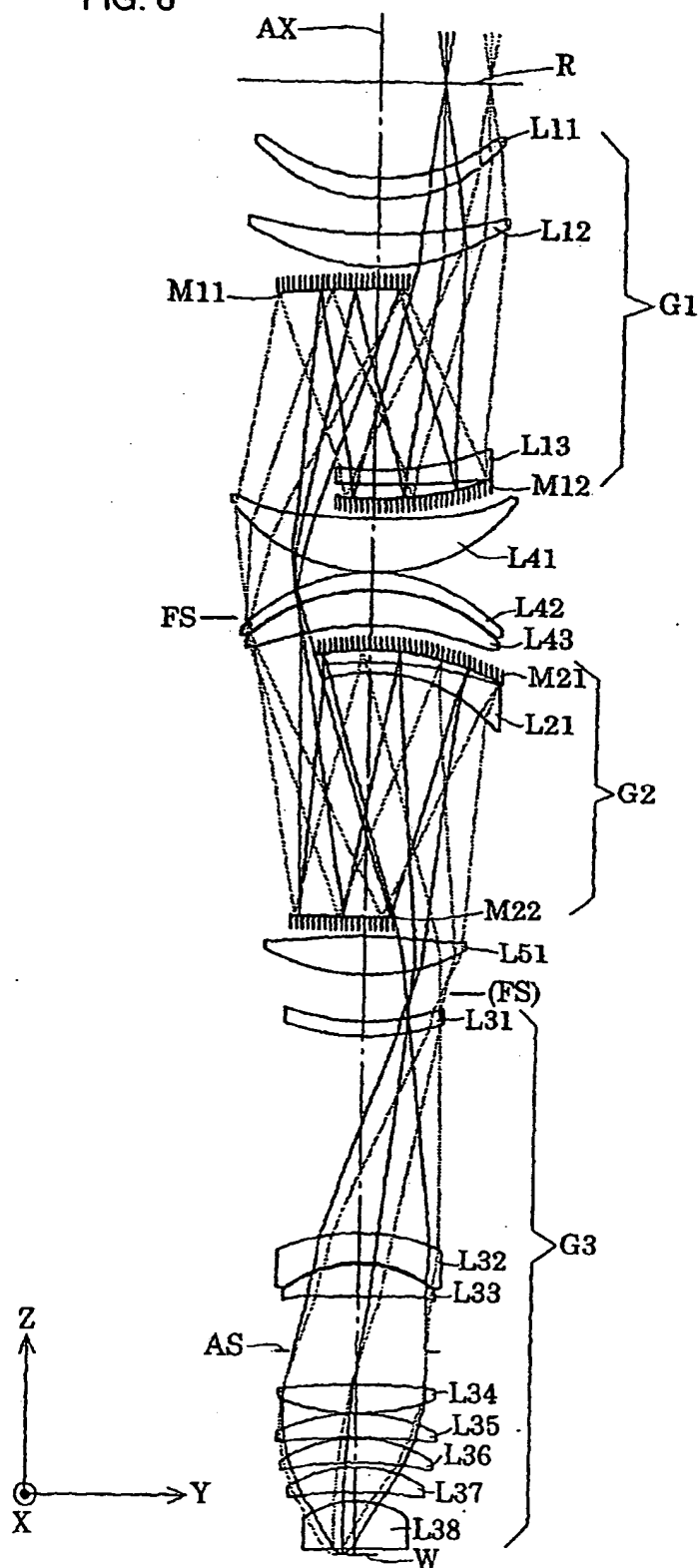


FIG. 7

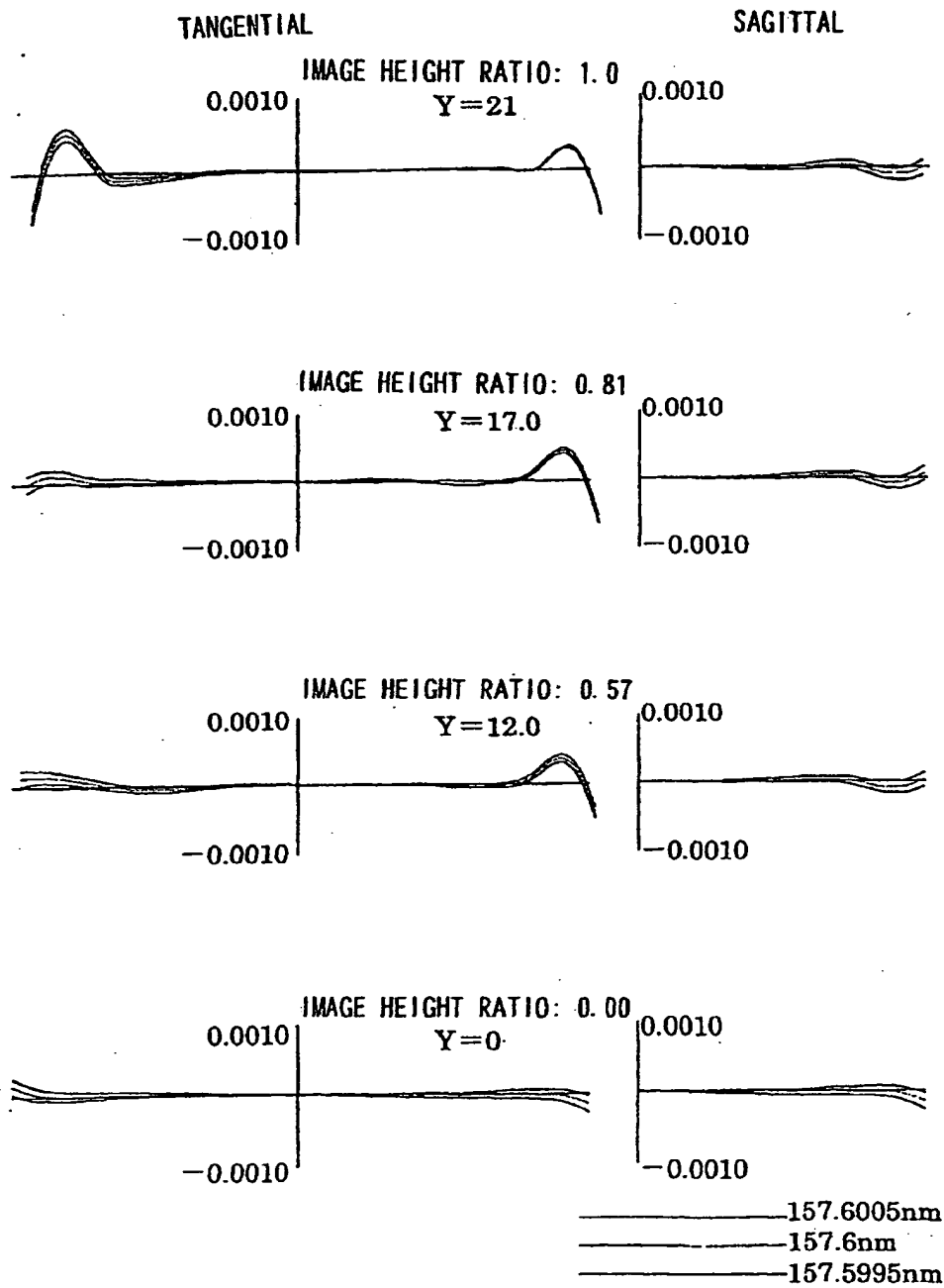


FIG. 8

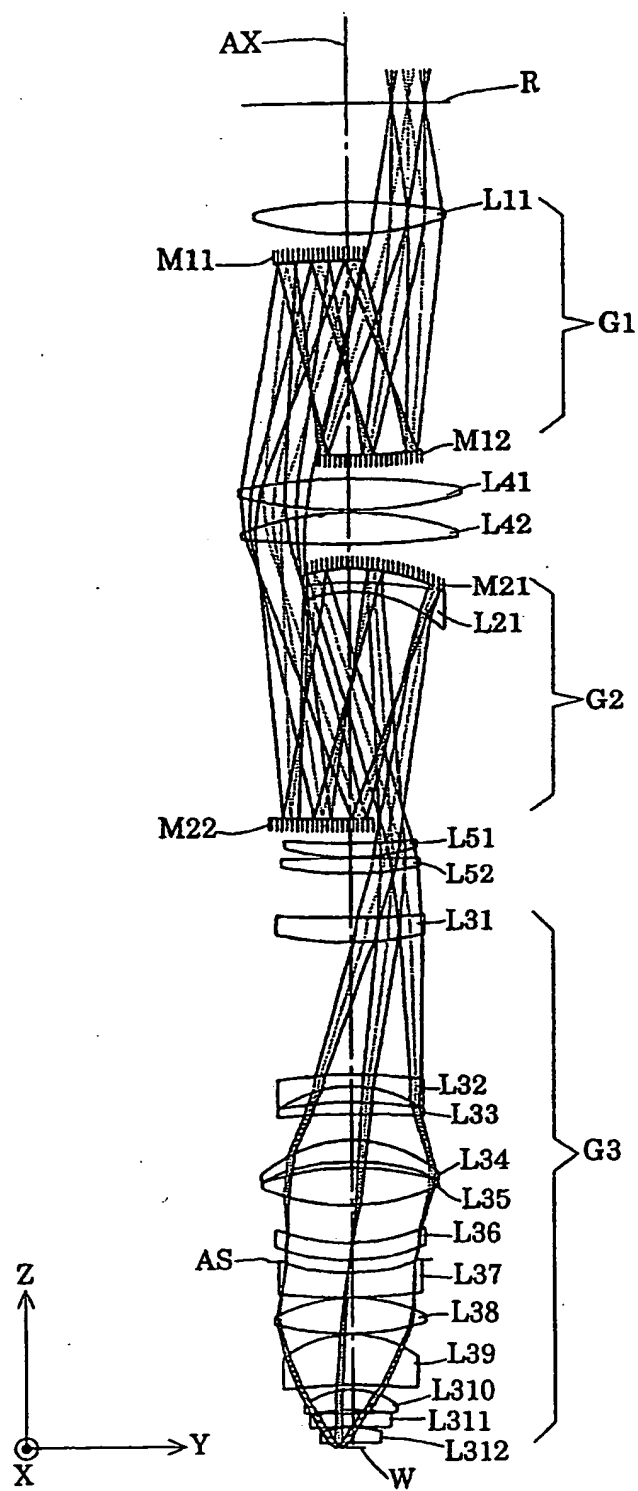


FIG. 9

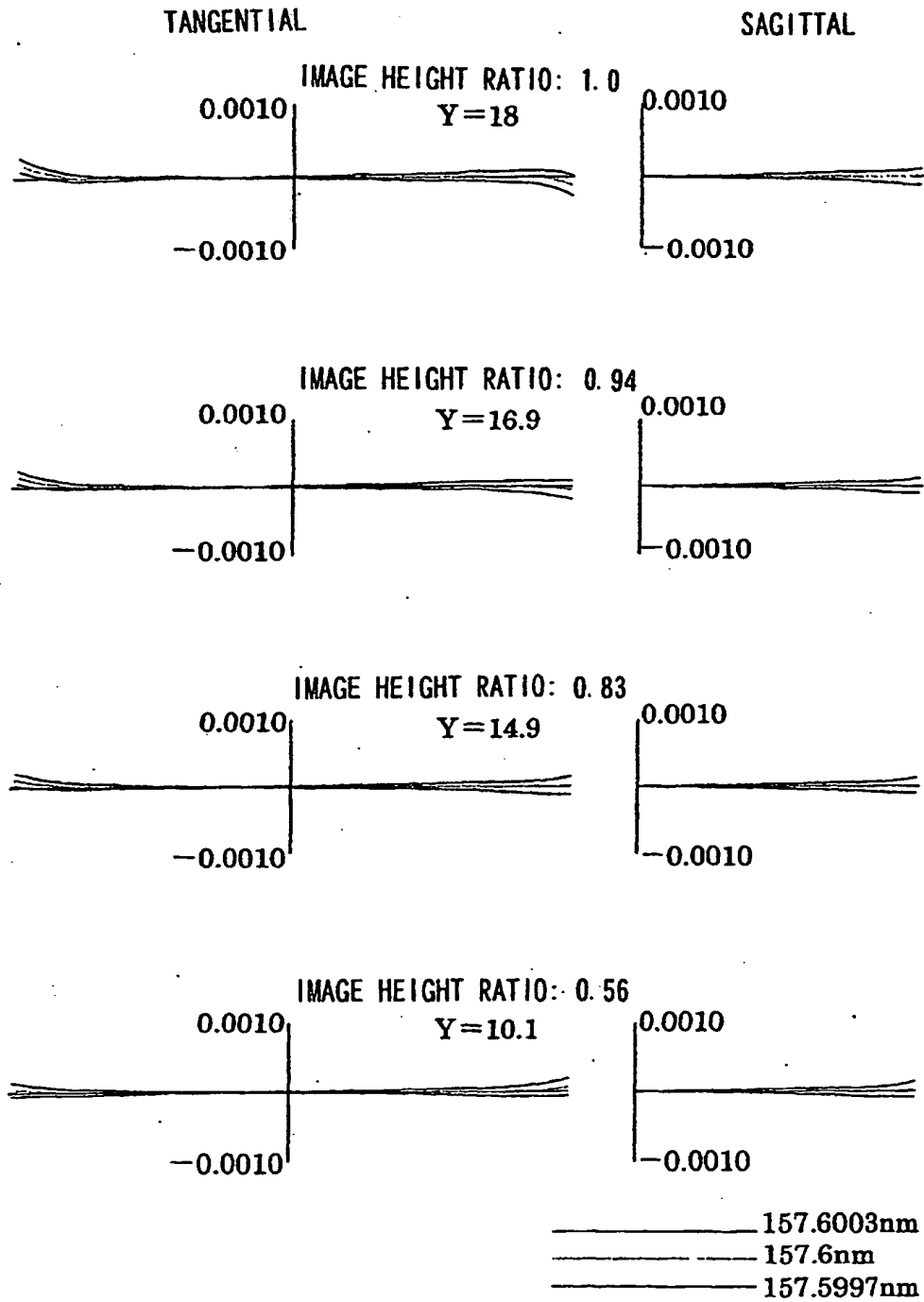


FIG. 10

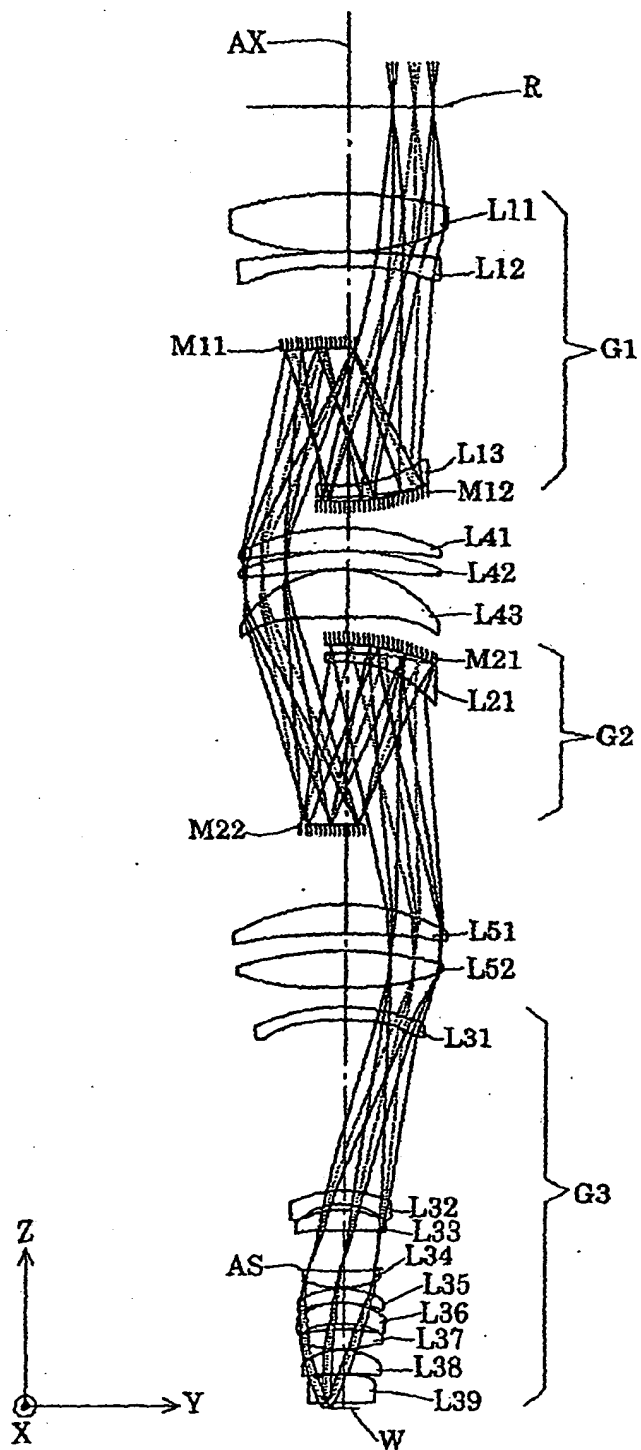


FIG. 11

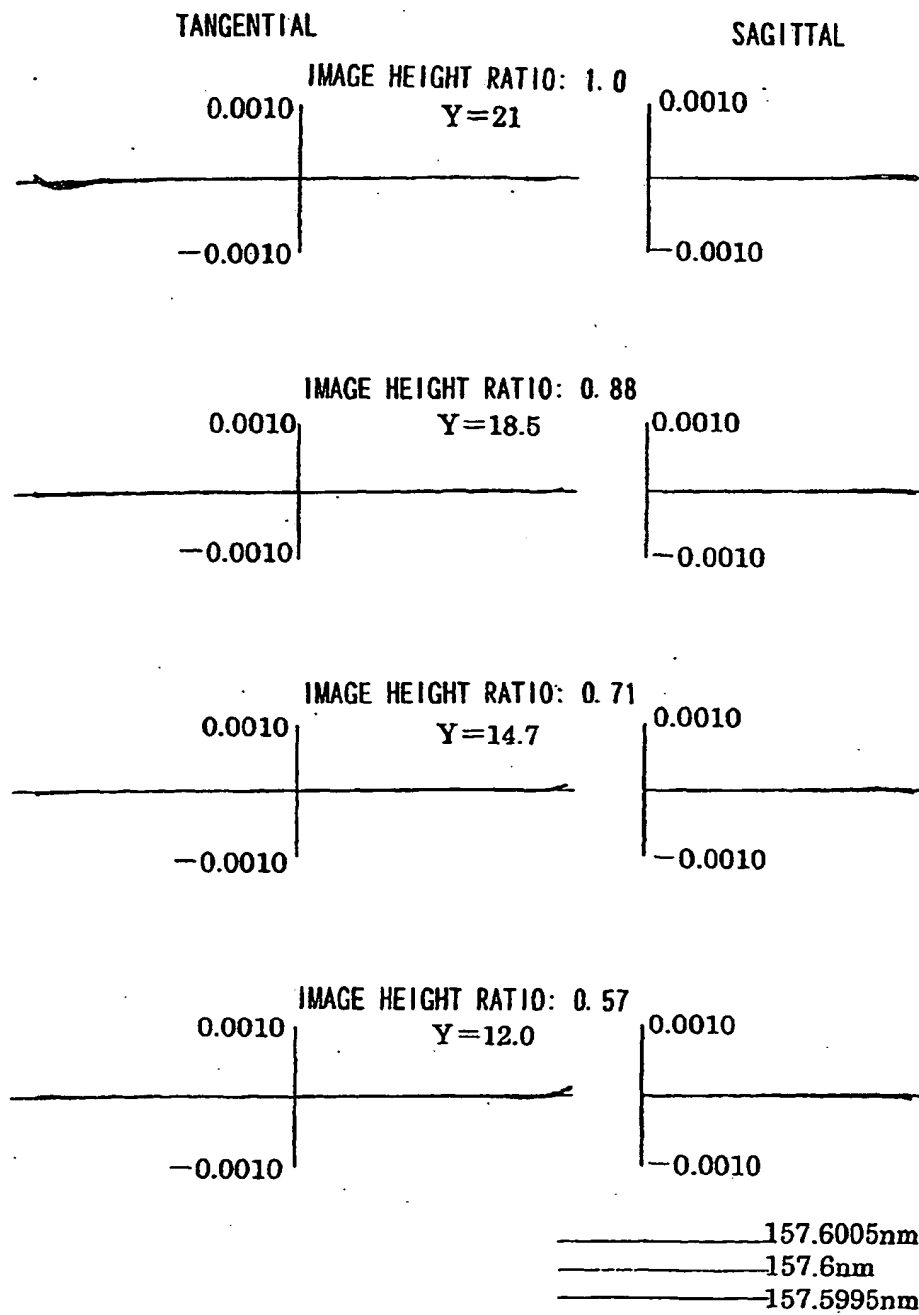


FIG. 12

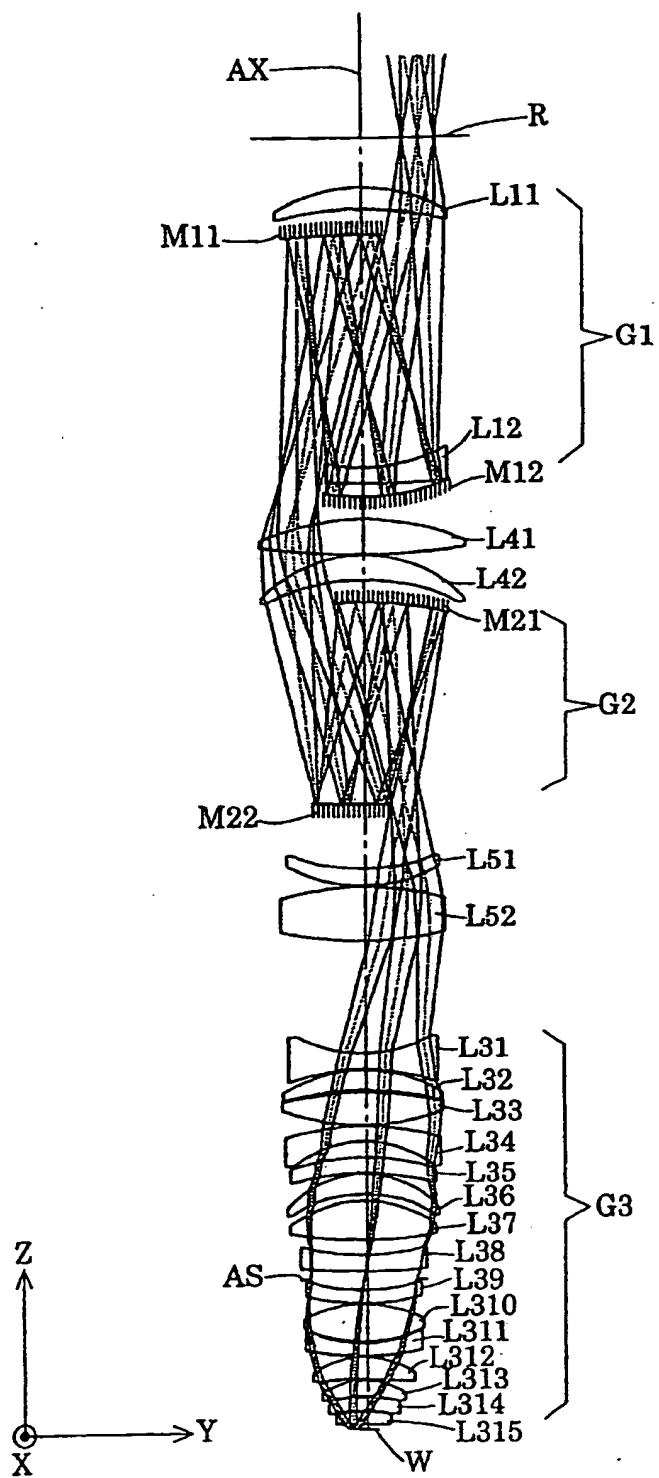


FIG. 13

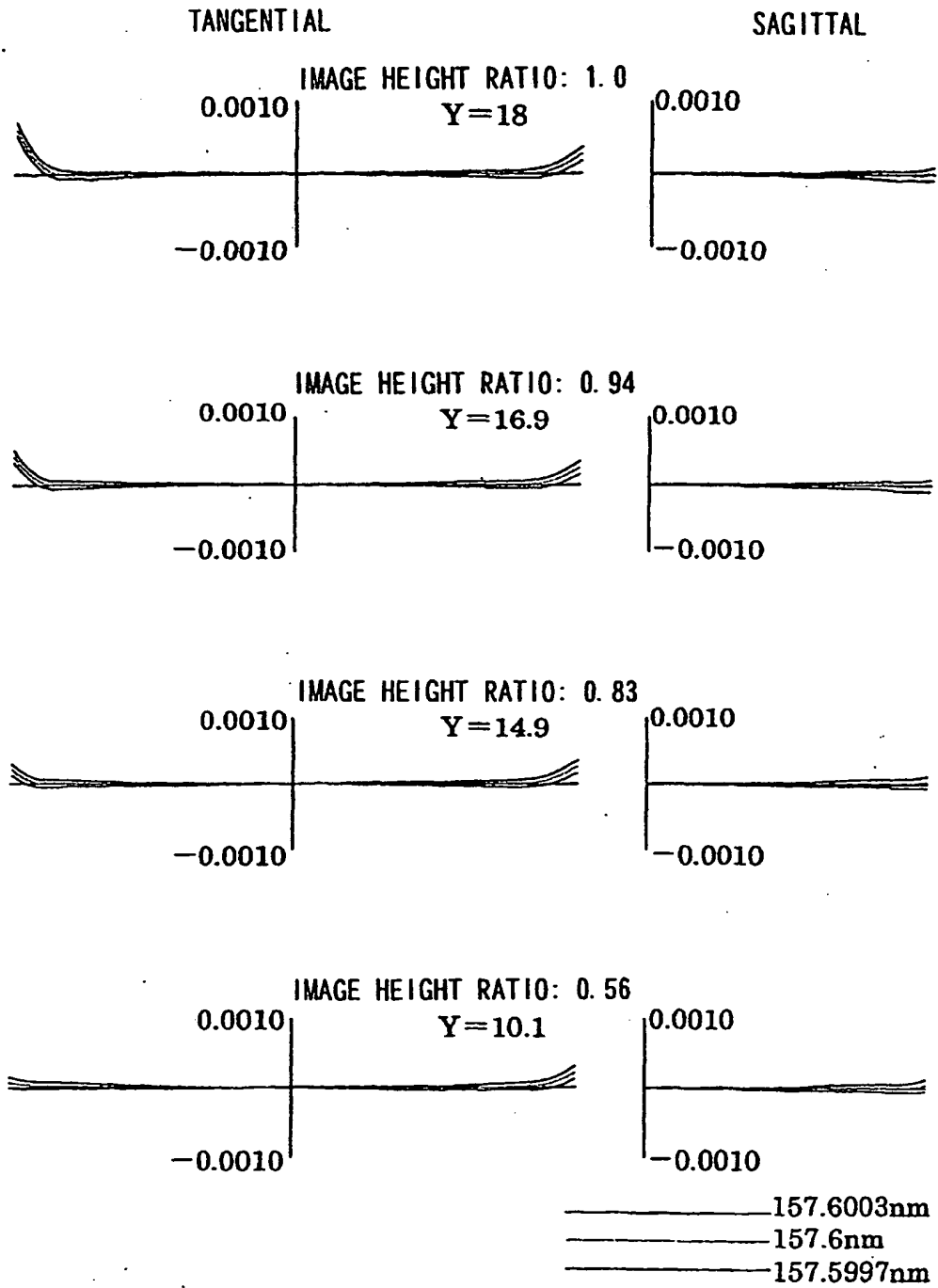


FIG. 14

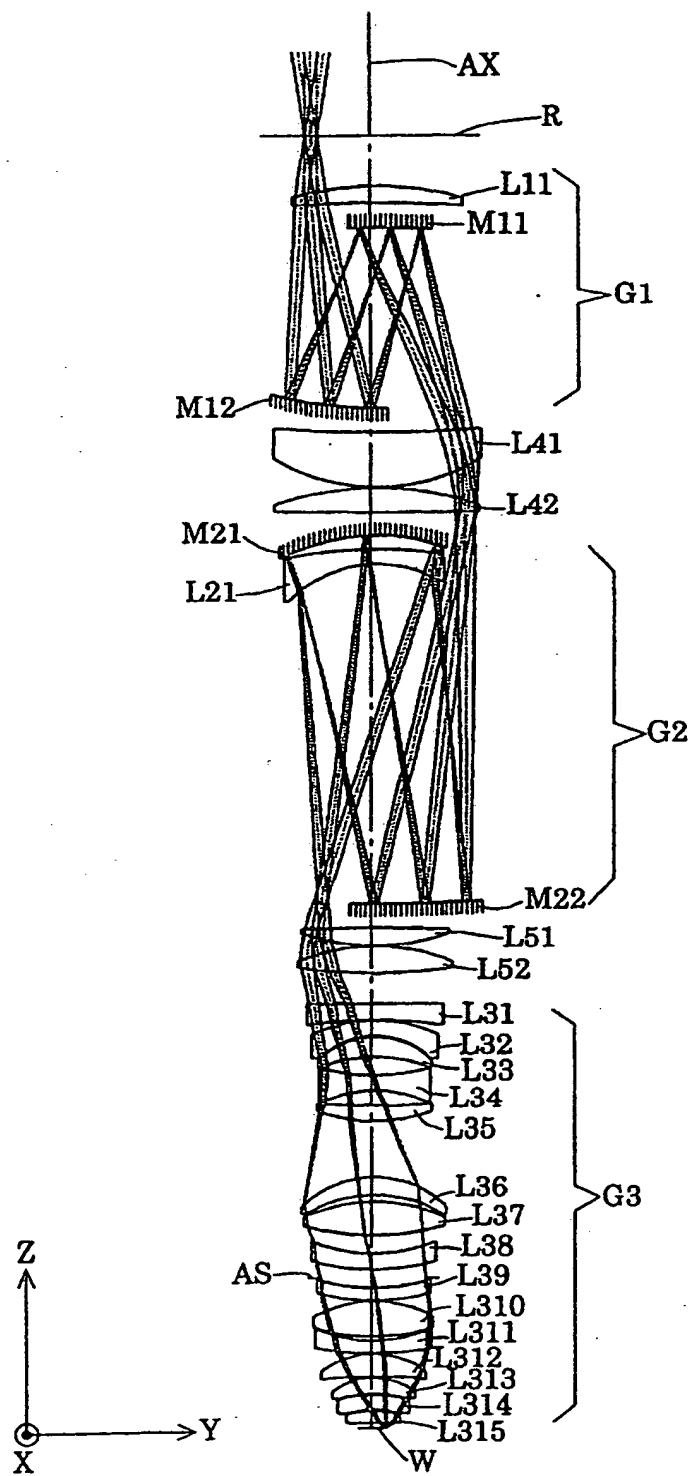


FIG. 15

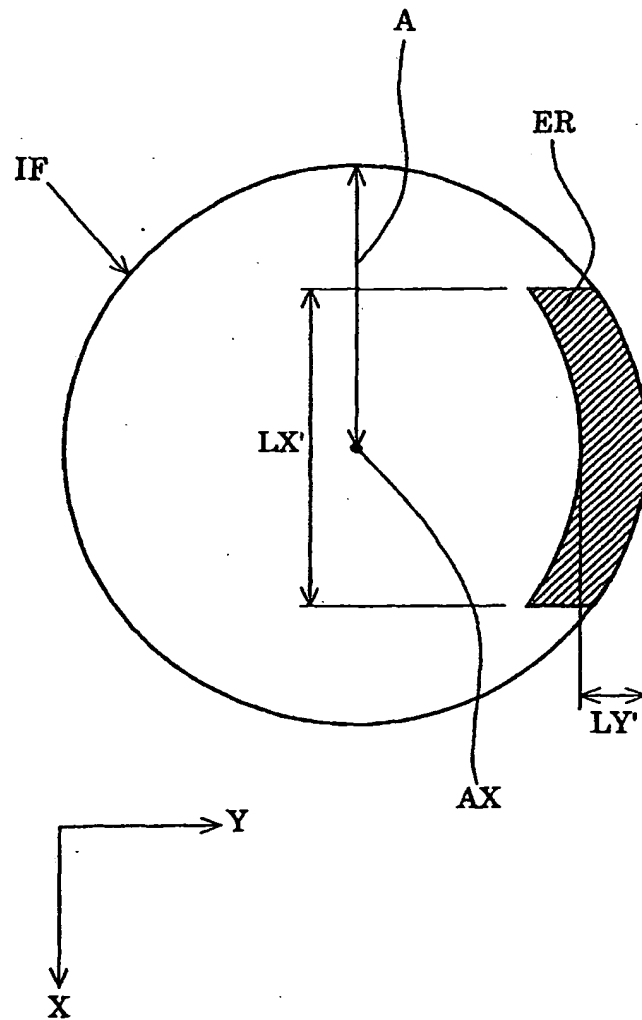


FIG. 16

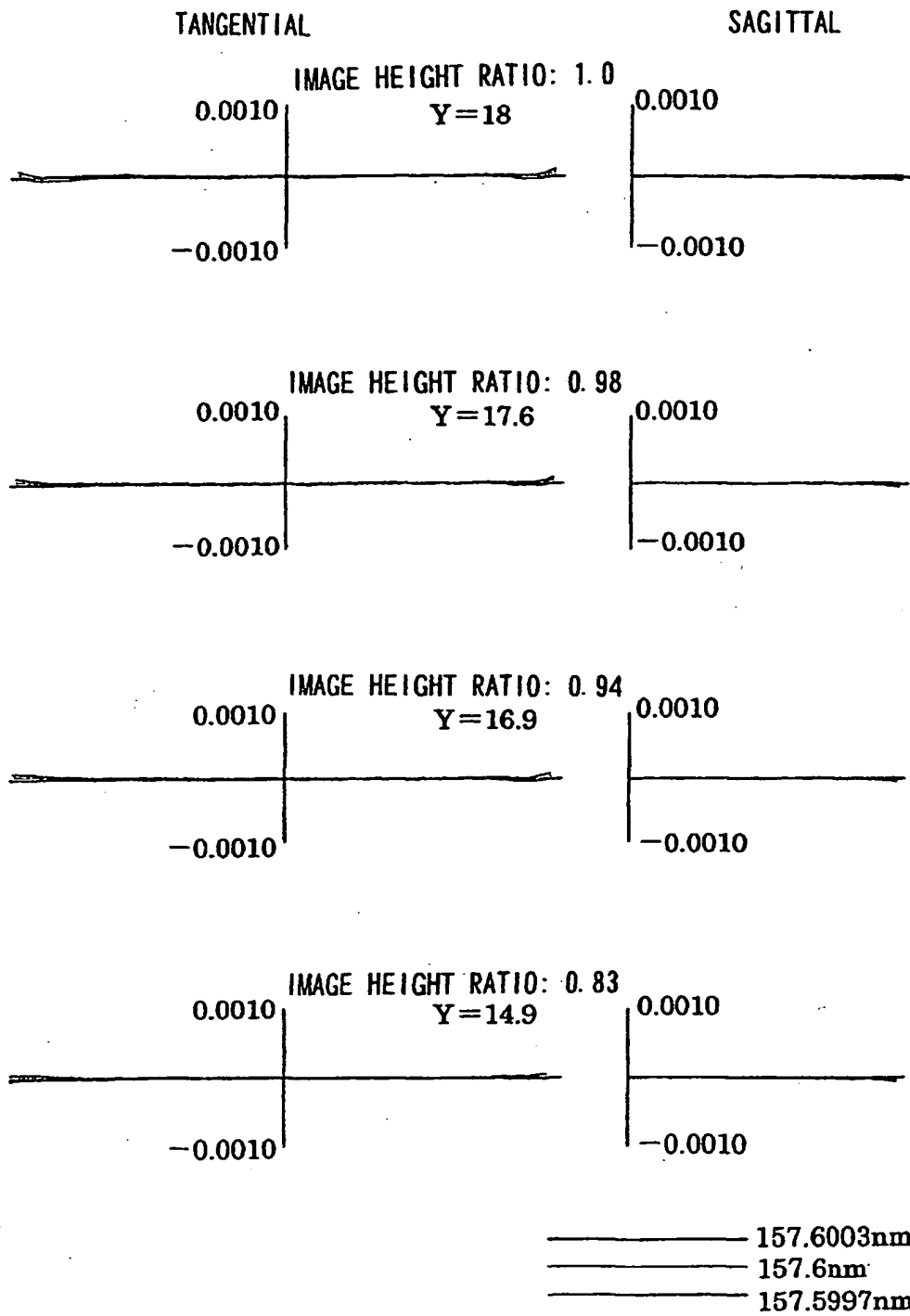


FIG. 17

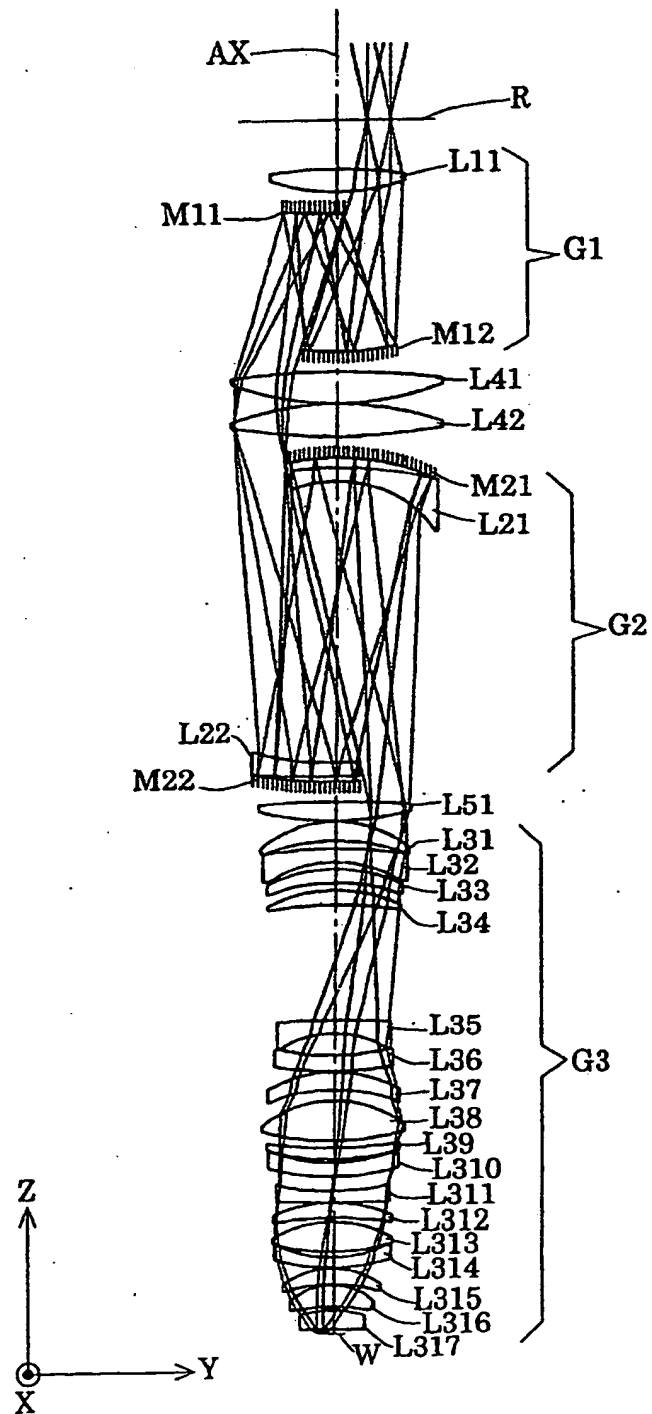


FIG. 18

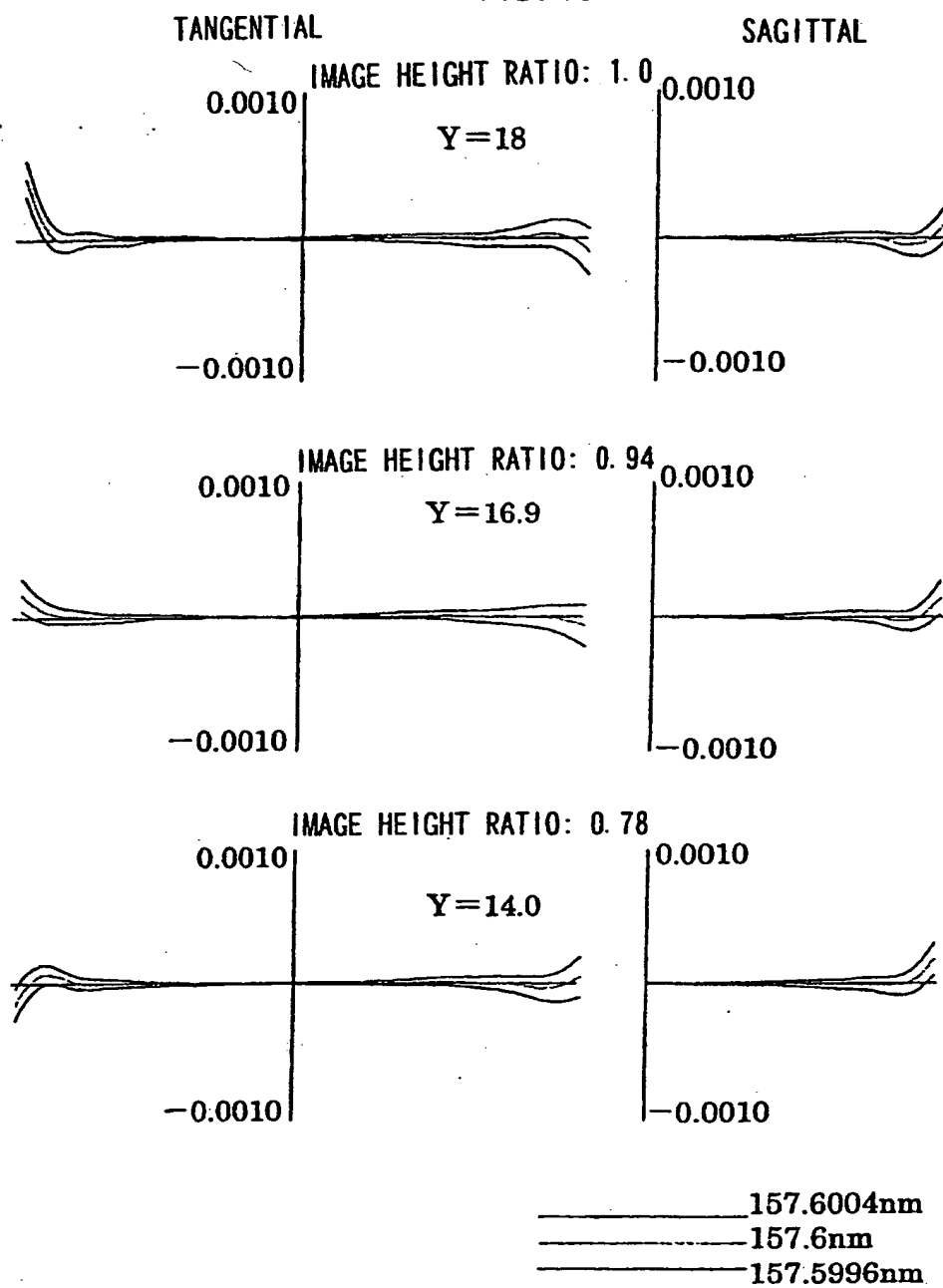


FIG. 19

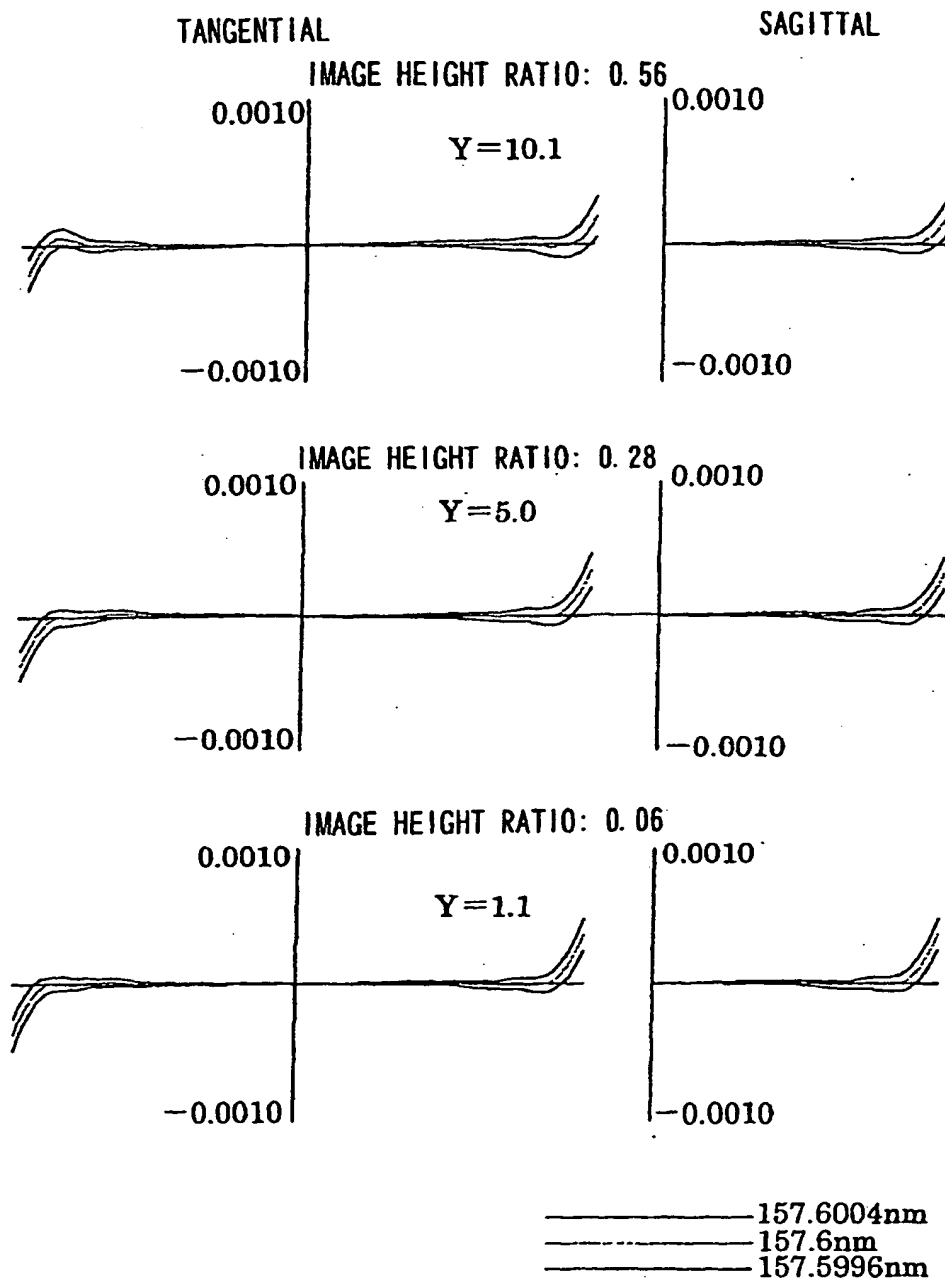


FIG. 20

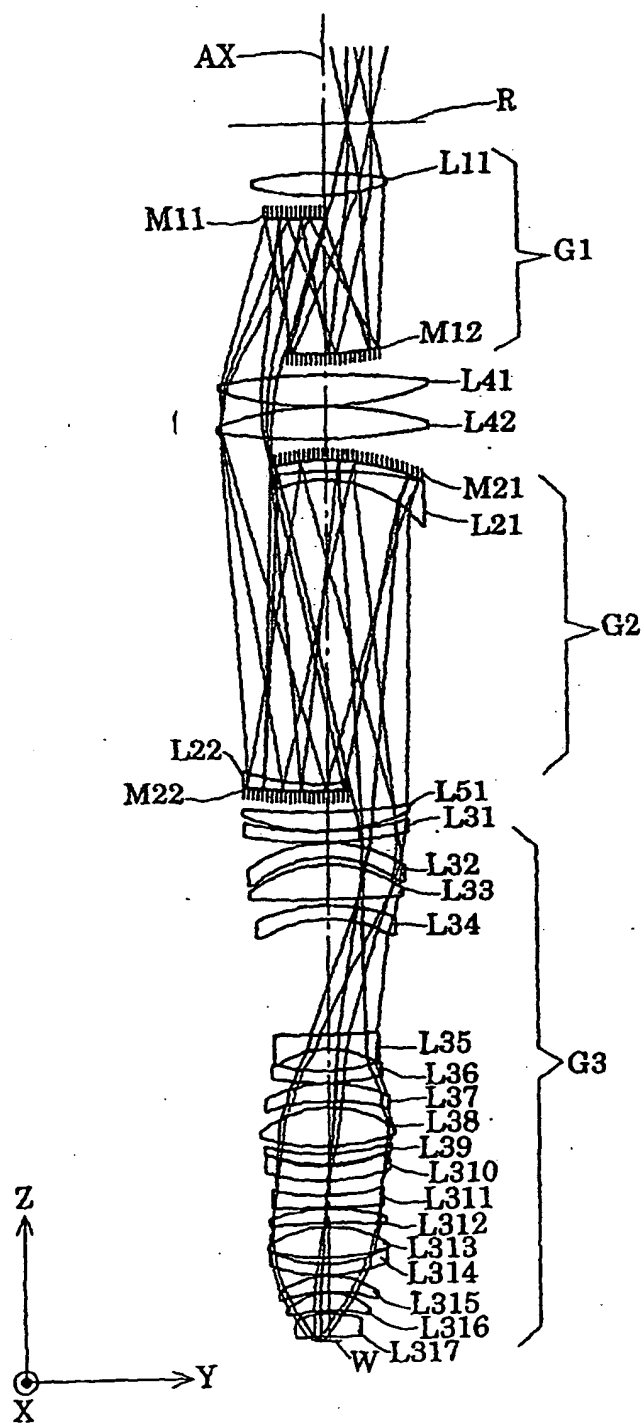


FIG. 21

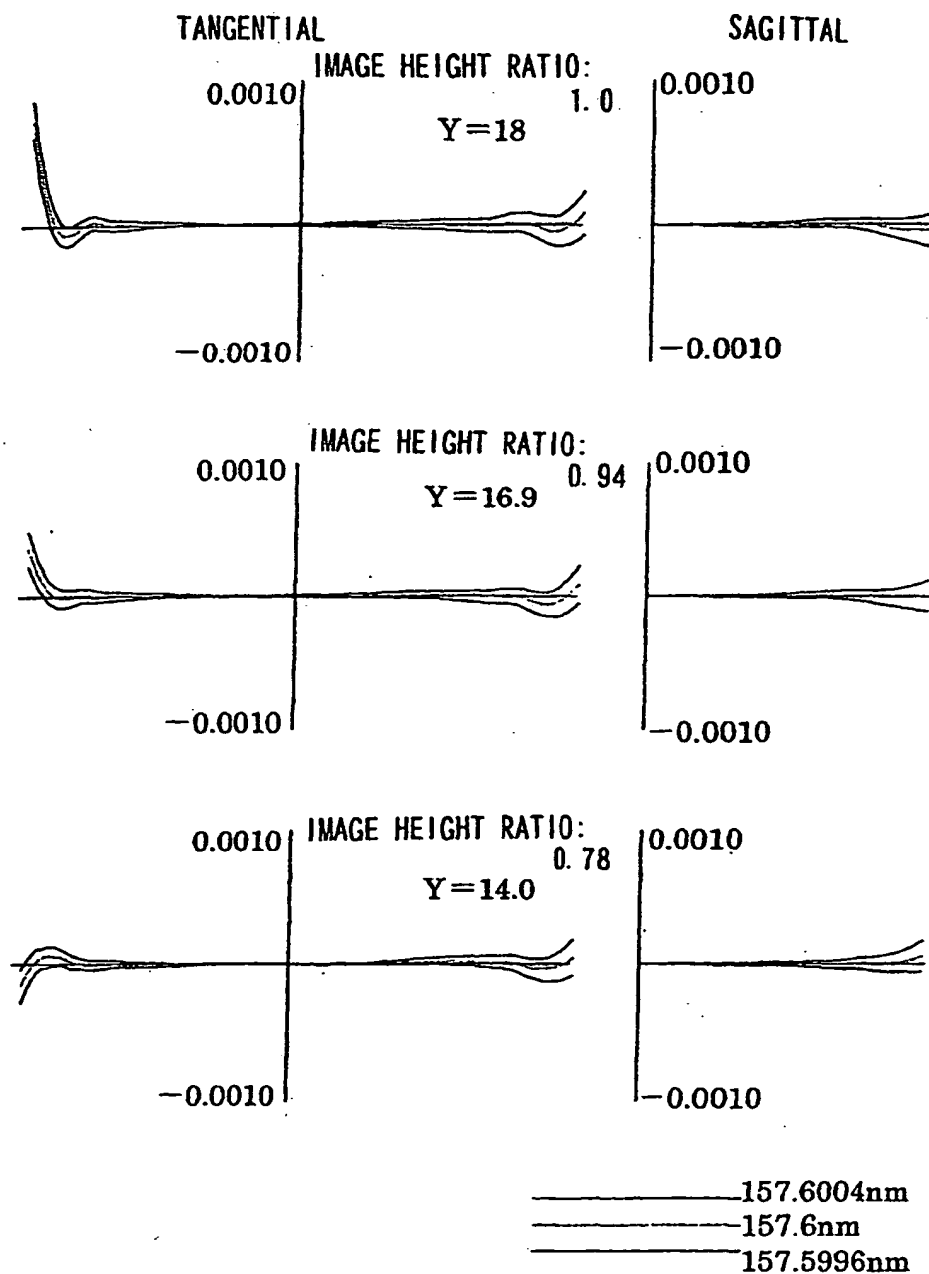


FIG. 22

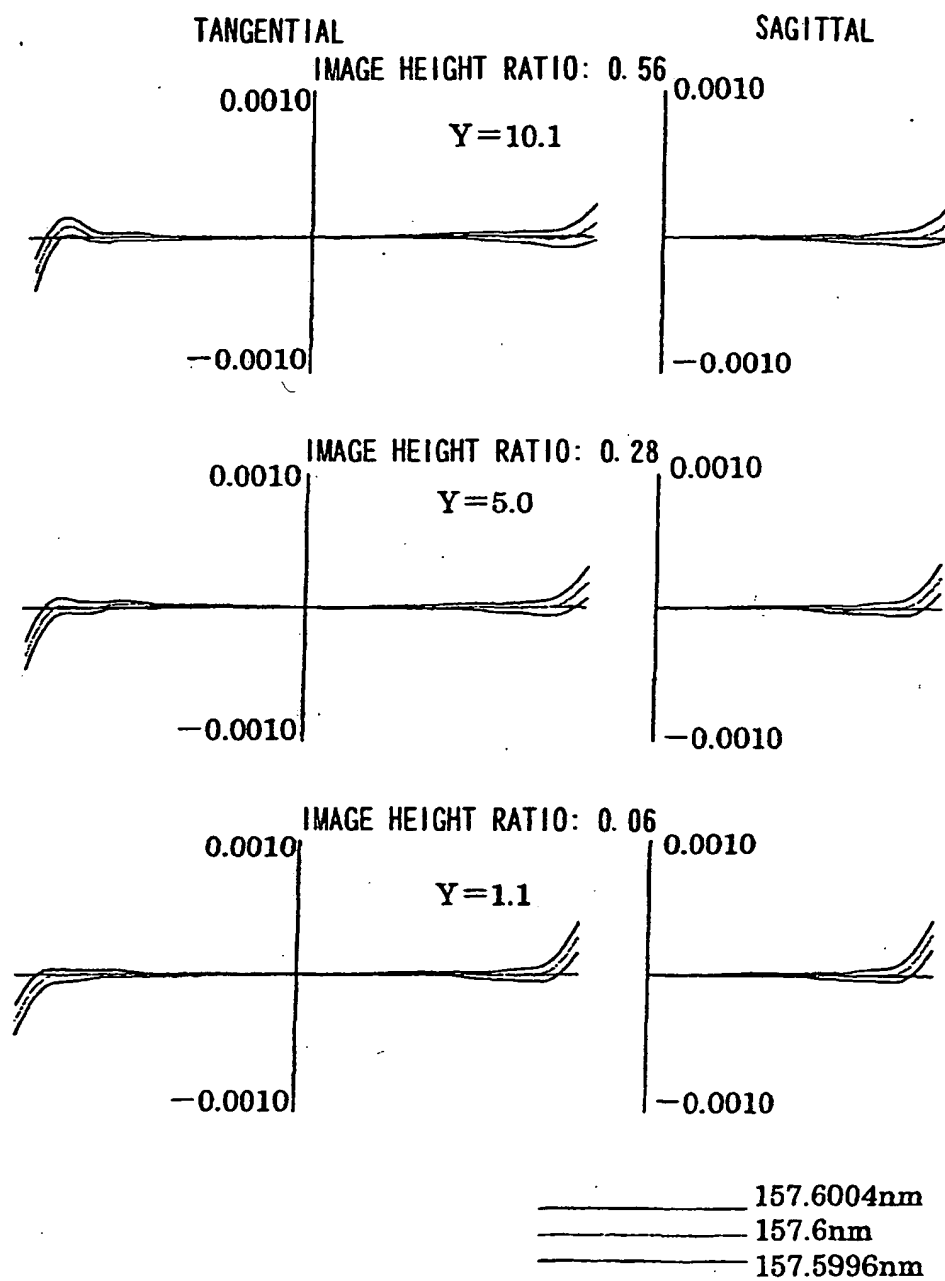


FIG. 23

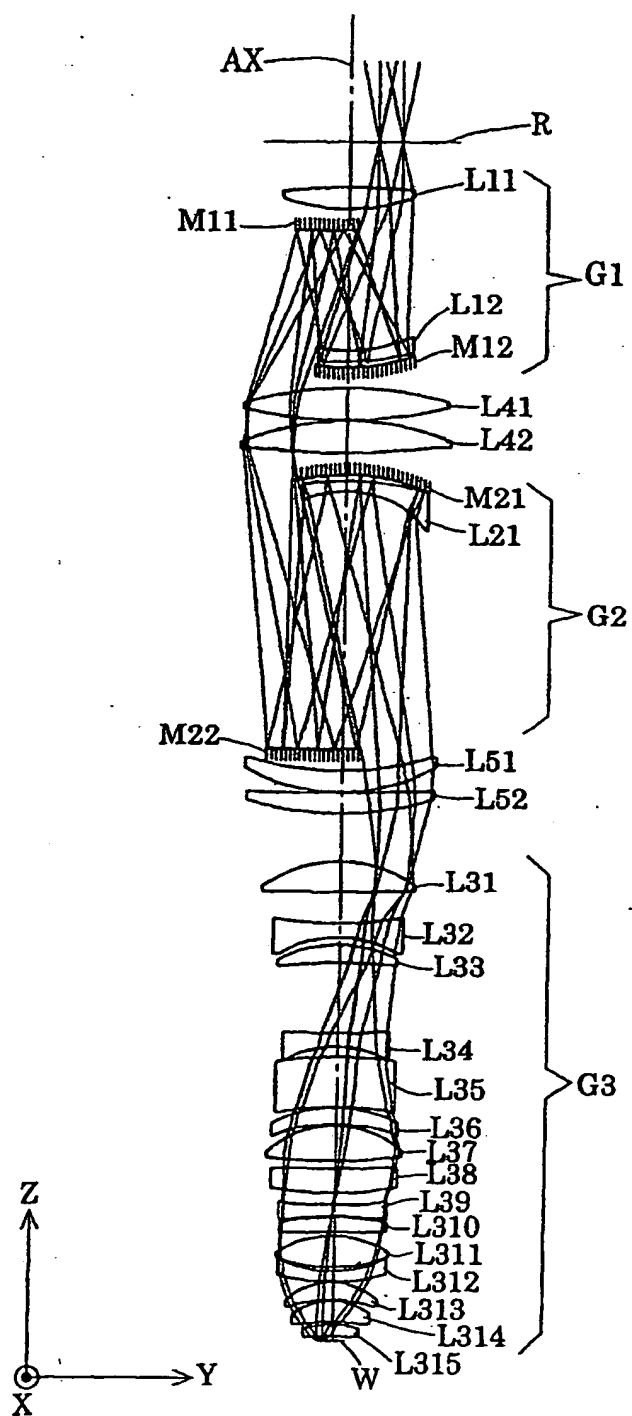


FIG. 24

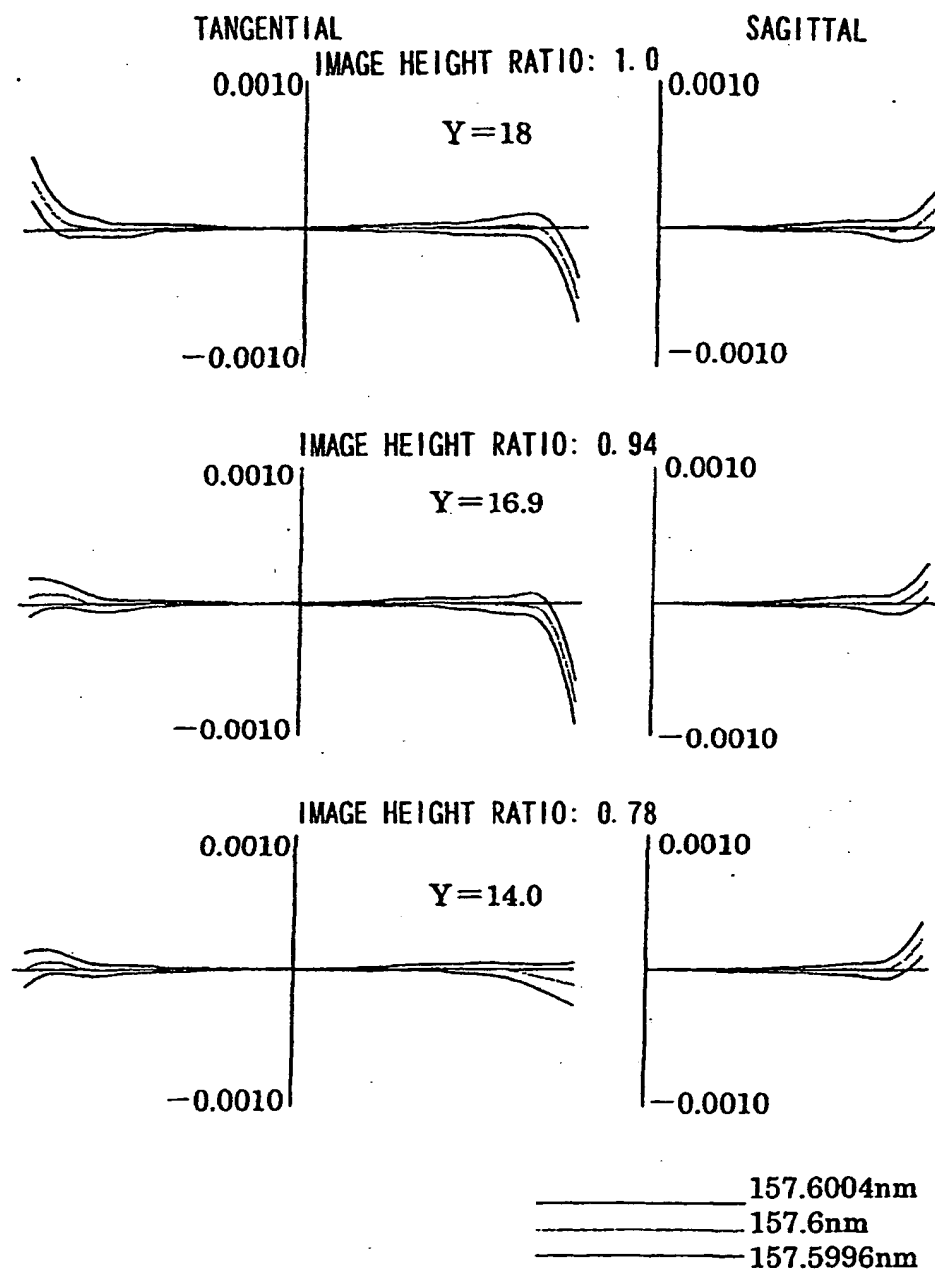


FIG. 25

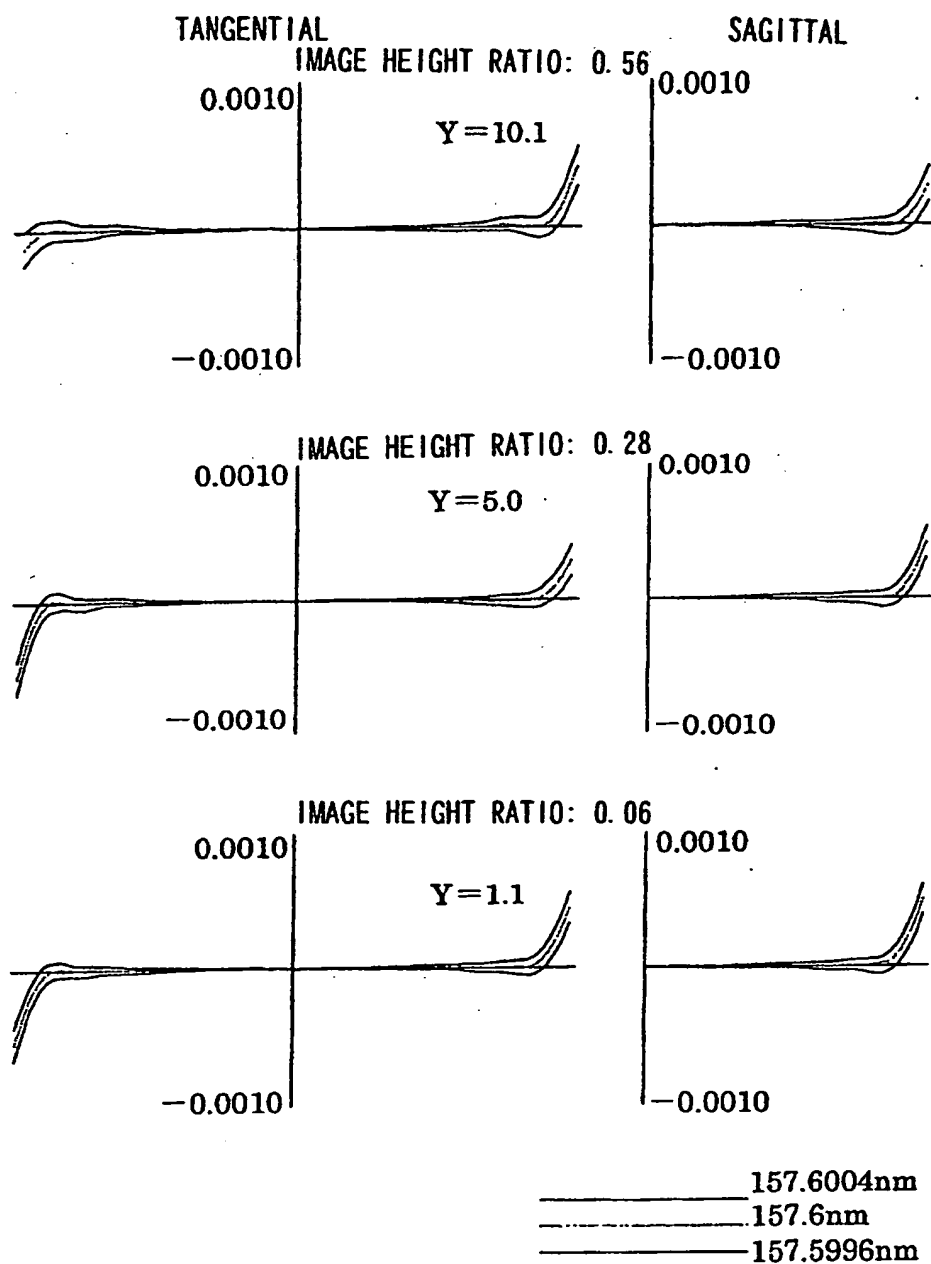


FIG. 26

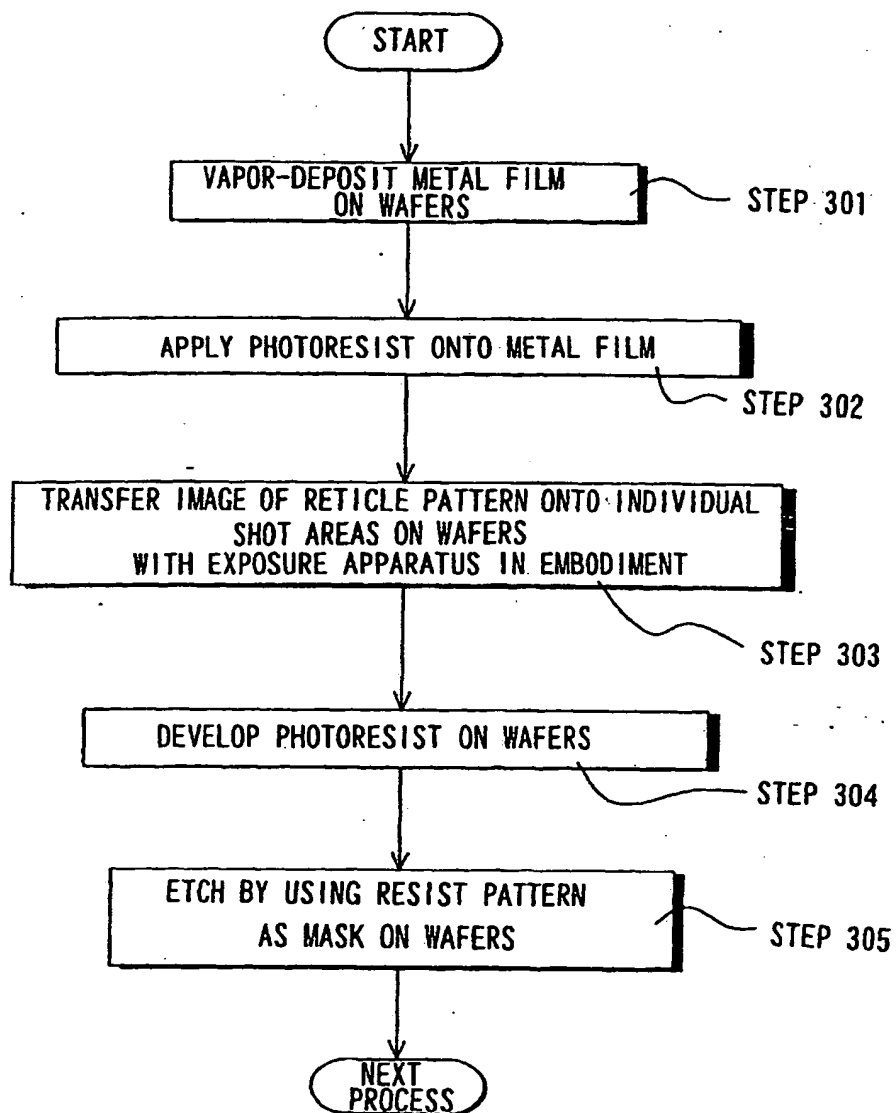
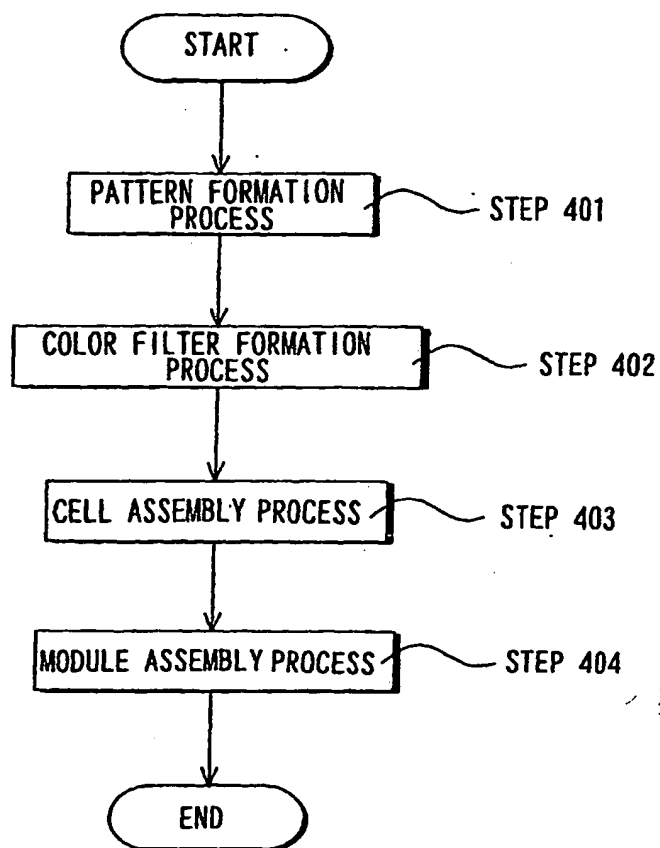


FIG. 27



INTERNATIONAL SEARCH REPORT

International application No.

PCT/JP01/09266

A. CLASSIFICATION OF SUBJECT MATTER Int.Cl ⁷ G02B17/08, H01L21/027		
According to International Patent Classification (IPC) or to both national classification and IPC		
B. FIELDS SEARCHED Minimum documentation searched (classification system followed by classification symbols) Int.Cl ⁷ G02B17/08, H01L21/027		
Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched Jitsuyo Shinan Koho 1926-1996 Toroku Jitsuyo Shinan Koho 1994-2001 Kokai Jitsuyo Shinan Koho 1971-2001 Jitsuyo Shinan Toroku Koho 1996-2001		
Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)		
C. DOCUMENTS CONSIDERED TO BE RELEVANT		
Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	US 5515207 A (Nikon Precision Inc.), 07 May, 1996 (07.05.96), Full text; all drawings (Family: none)	1-16
A	US 4861148 A (Matsushita Electric Industrial Co., Ltd.), 29 August, 1989 (29.08.89), Full text; all drawings & JP 63-14113 A, Full text; all drawings & EP 237041 B1 & DE 3787035 G	1-16
Y	JP 6-265789 A (Nikon Corporation), 22 September, 1994 (22.09.94), Full text; all drawings (Family: none)	9, 10 1-8, 11-16
A		
Y	US 5861997 A (Nikon Corporation), 19 January, 1999 (19.01.99), Full text; all drawings & JP 8-62502 A, Full text; all drawings	1-16
<input checked="" type="checkbox"/> Further documents are listed in the continuation of Box C. <input type="checkbox"/> See patent family annex.		
* Special categories of cited documents: "A" document defining the general state of the art which is not considered to be of particular relevance "E" earlier document but published on or after the international filing date "L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) "O" document referring to an oral disclosure, use, exhibition or other means "P" document published prior to the international filing date but later than the priority date claimed "T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention "X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art "&" document member of the same patent family		
Date of the actual completion of the international search 21 December, 2001 (21.12.01)		Date of mailing of the international search report 15 January, 2002 (15.01.02)
Name and mailing address of the ISA/ Japanese Patent Office		Authorized officer
Facsimile No.		Telephone No.

Form PCT/ISA/210 (second sheet) (July 1992)

INTERNATIONAL SEARCH REPORT

International application No.

PCT/JP01/09266

C (Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
Y	EP 779528 A2 (SVG Lithography Systems, Inc.), 18 June, 1997 (18.06.97), Full text; all drawings & JP 9-211332 A, Full text; all drawings & CA 2192604 A & US 5815310 A & KR 97048693 A	1-16
Y A	US 5805334 A (Nikon Corporation), 08 September, 1998 (08.09.98), Full text; all drawings & JP 9-311278 A, Full text; all drawings	9,10 1-8,11-16
Y	JP 10-10430 A (Nikon Corporation), 16 January, 1998 (16.01.98), Full text; all drawings & US 6157498 A	1-16
Y	JP 10-104513 A (Carl Zeiss Stiftung), 24 April, 1998 (24.04.98), Full text; all drawings & EP 833180 A2 & DE 19639586 A1 & KR 99075861 A & US 6169627 B1	1-16
Y	US 6097537 A (Nikon Corporation), 01 August, 2000 (01.08.00), Full text; all drawings & JP 11-295606 A, Full text; all drawings	1-16
Y	JP 2000-98228 A (Nikon Corporation), 07 April, 2000 (07.04.00), Full text; all drawings & US 6213610 B1 & US 20010002155 A1 & US 6302548 B2	1-16
Y	JP 2000-100694 A (Nikon Corporation), 07 April, 2000 (07.04.00), Full text; all drawings & US 6172825 B1	1-16
Y	JP 2000-235144 A (Carl Zeiss Stiftung Trading As Carl Zeiss), 29 August, 2000 (29.08.00), Full text; all drawings & DE 19948240 A1 & EP 1035445 A2 & KR 2000076656 A	1-16
PX PY	EP 1069448 A1 (Nikon Corporation), 17 January, 2001 (17.01.01), Full text; all drawings & JP 2001-27727 A, Full text; all drawings	9,10 1-8,11-16
PX PY	JP 2001-166210 A (Carl Zeiss Stiftung), 22 June, 2001 (22.06.01), Full text; all drawings & EP, 1098215, A1	7-10 1-6,11-16
PX PY	JP 2001-185480 A (Nikon Corporation), 06 July, 2001 (06.07.01), Full text; all drawings (Family: none)	9,10 1-8,11-16

Form PCT/ISA/210 (continuation of second sheet) (July 1992)

INTERNATIONAL SEARCH REPORT

International application No.

PCT/JP01/09266

C (Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT		
Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
PX PY	JP 2001-228401 A (Canon Inc.), 24 August, 2001 (24.08.01), Full text; all drawings (Family: none)	9, 10 1-8, 11-16
Y	WO 00/39623 A1 (Nikon Corporation), 06 July, 2000 (06.07.00), Full text; all drawings & EP 1059550 A1 & KR 2001041257 A	1-16

Form PCT/ISA/210 (continuation of second sheet) (July 1992)

INTERNATIONAL SEARCH REPORT

International application No.

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Box I Observations where certain claims were found unsearchable (Continuation of item 1 of first sheet)

This international search report has not been established in respect of certain claims under Article 17(2)(a) for the following reasons:

1. ☐ Claims Nos.:
because they relate to subject matter not required to be searched by this Authority, namely:

2. ☐ Claims Nos.:
because they relate to parts of the international application that do not comply with the prescribed requirements to such an extent that no meaningful international search can be carried out, specifically:

3. ☐ Claims Nos.:
because they are dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).

Box II Observations where unity of invention is lacking (Continuation of item 2 of first sheet)

This International Searching Authority found multiple inventions in this international application, as follows:

(See extra sheet.)

1. ☐ As all required additional search fees were timely paid by the applicant, this international search report covers all searchable claims.
2. ☒ As all searchable claims could be searched without effort justifying an additional fee, this Authority did not invite payment of any additional fee.
3. ☐ As only some of the required additional search fees were timely paid by the applicant, this international search report covers only those claims for which fees were paid, specifically claims Nos.:

4. ☐ No required additional search fees were timely paid by the applicant. Consequently, this international search report is restricted to the invention first mentioned in the claims; it is covered by claims Nos.:

Remark on Protest ☐ The additional search fees were accompanied by the applicant's protest.
☐ No protest accompanied the payment of additional search fees.

Form PCT/ISA/210 (continuation of first sheet (1)) (July 1992)

INTERNATIONAL SEARCH REPORT

International application No.

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Continuation of Box No.II of continuation of first sheet (1)

1. Claim 1 is an invention relating to a catadioptric system comprising a first image-forming optical system having at least 2 reflecting mirrors and adapted to form a first intermediate image of a first surface on the basis of light from the first surface, a second image-forming optical system having at least 2 reflecting mirrors and adapted to form a second intermediate image of the first surface on the basis of light through the first image-forming optical system, and a dioptric type third image-forming optical system adapted to form the final image of the first surface on a second surface on the basis of light through the second image-forming optical system, wherein all optical components that constitute the first, second and third image-forming optical systems are arranged along a single straight optical axis.

Further, Claims 2 - 6 are inventions dependent on Claim 1.

2. Claim 7 is an invention relating to a catadioptric system comprising a plurality of optical members for forming an intermediate image of the first surface in an optical path between the first and second surfaces twice and forming, for the third time, an intermediate image of the first surface as the final image on the second surface, wherein the plurality of optical members are arranged along a single straight optical axis.

Further, Claim 8 is an invention dependent on Claim 7.

3. Claim 9 is an invention relating to a catadioptric system comprising a plurality of reflecting mirrors arranged along a single straight optical axis, wherein an image of a rectangular region spaced away from the optical axis in a first surface is formed on a second surface.

Further, Claim 10 is an invention dependent on Claim 9.

4. Claim 11 is an invention relating to a catadioptric system comprising a first image-forming optical system having at least a first reflecting mirror and a second reflecting mirror and adapted to form a first intermediate image of a first surface on the basis of light from the first surface, a second image-forming optical system having at least a third reflecting mirror and a fourth reflecting mirror and adapted to form a second intermediate image of the first surface on the basis of light through the first image-forming optical system, and a dioptric type third image-forming optical system adapted to form the final image of the first surface on a second surface on the basis of light through the second image-forming optical system, wherein all optical components that constitute the first, second and third image-forming optical systems are arranged along a single straight optical axis, and at least one negative lens is disposed immediately in front of each of the reflecting surface sides of two of the first, second, third and fourth reflecting mirrors.

Further, Claims 12 - 13 are inventions dependent on Claim 11.

Further, Claim 14 is an invention dependent on any one of Claim 1 - 13.

Further, Claims 15 - 16 are inventions dependent on Claim 14.

However, the technical content itself, wherein in a catadioptric system having a plurality of optical members, the plurality of optical members are arranged along a single straight optical axis, is a technique which has heretofore been known as described, for example, in JP 10-104 513 A (Carl Zeiss Stiftung) 24 April 1998 (24. 04. 98). Therefore, of the groups of inventions, the 3 and the others have no matter in common which is novel as compared with the prior art.

Thus, of the groups of inventions, the 3 and the others have no matter in common which is considered to be a special technical feature in the sense of the second sentence in PCT Rule 13. 2, and of the groups of inventions, the 3 and the others cannot be said to be a group of inventions so linked as to form a single general inventive concept. Therefore, of the groups of inventions, the 3 and the others cannot be said to be in a relationship that satisfies unity.